

PSOC[™] 4 and PSOC[™] 6 MCU CAPSENSE[™] design guide

About this document

Scope and purpose

The CAPSENSE[™] design guide explains how to design capacitive touch sensing applications with the CAPSENSE[™] feature in PSOC[™] 4 and PSOC[™] 6 MCU device families. The CAPSENSE[™] feature offers unprecedented signal-to-noise ratio (SNR), best-in-class liquid tolerance, and a wide variety of sensors such as buttons, sliders, touchpads, and proximity sensors. This design guide explains the CAPSENSE[™] operation, CAPSENSE[™] design tools, performance tuning of the PSOC[™] Creator and ModusToolbox[™] CAPSENSE[™] component and design considerations. This guide also introduces Fifth Generation CAPSENSE[™] technology which has several advantages over the previous generation devices.

Different device families are available with CAPSENSE[™] feature. If you have not chosen a particular device, or are new to capacitive sensing, see the <u>Getting started with CAPSENSE[™]</u> design guide. It helps you understand the advantages of CAPSENSE[™] over mechanical buttons, CAPSENSE[™] technology fundamentals, and to select the right device for your application. It also directs you to the right documentation, kits, or tools to help with your design.

Intended audience

This document is primarily intended for engineers who need to become familiar with the CAPSENSE[™] design principles of PSOC[™] 4 and PSOC[™] 6 MCU devices.



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1 Introduction

1.1 Overview

Capacitive touch sensors are user interface devices that use human body capacitance to detect the presence of a finger on or near a sensor. CAPSENSE[™] solutions bring elegant, reliable, and easy-to-use capacitive touch sensing functionality to your product.

This design guide focuses on the CAPSENSE[™] feature in the PSOC[™] 4 and PSOC[™] 6 MCU families of devices. These are true programmable embedded system-on-chip, integrating configurable analog and digital peripheral functions, memory, radio, and a microcontroller on a single chip. These devices are highly flexible and can implement many functions such as ADC, DAC, and Bluetooth[®] LE in addition to CAPSENSE[™], which accelerates time-to-market, integrates critical system functions, and reduces overall system cost.

This guide assumes that you are familiar with developing applications for PSOC[™] 4 and PSOC[™] 6 MCU using the PSOC[™] Creator integrated design environment (IDE). If you are new to PSOC[™] 4, see AN79953 - Getting started with PSOC[™] 4 or AN91267 - Getting started with PSOC[™] 4 Bluetooth[®] LE. If you are new to PSOC[™] 6 MCU, see AN221774 – Getting started with PSOC[™] 6 MCU and AN210781 - Getting started with PSOC[™] 6 MCU with Bluetooth[®] LE connectivity. If you are new to PSOC[™] Creator, see the PSOC[™] Creator home page.

If you are new to ModusToolbox[™], see ModusToolbox[™] IDE quick start guide.

This design guide helps you understand:

- CAPSENSE[™] technology in PSOC[™] 4 and PSOC[™] 6 MCU
- Design and development tools available for <u>PSOC[™]</u> 4 and PSOC[™] 6 MCU PSOC[™] 6 MCU CAPSENSE[™]
- PSOC[™] 6 MCU CAPSENSE[™] PCB layout guidelines for PSOC[™] 4 and PSOC[™] 6 MCU
- Performance tuning of PSOC[™] 4 and <u>PSOC[™]</u> 6 MCU CAPSENSE[™] component
- Applications using CAPSENSE[™] Plus features such as motor control systems and induction cookers

1.2 CAPSENSE[™] features

CAPSENSE[™] in PSOC[™] 4 and PSOC[™] 6 MCU has the following features:

- Supports self-capacitance (CSD) and mutual-capacitance (CSX) based touch sensing on all CAPSENSE[™]capable GPIO pins¹⁾
- Provides the best-in-class signal-to-noise ratio (SNR), allowing high sensitivity that provides high-range proximity sensing (up to a 30-cm proximity-sensing distance) and liquid-tolerant operation (see Liquid tolerance)
- High-performance sensing across a variety of overlay materials and varied thickness (see CAPSENSE[™] fundamentals, Overlay material, and Overlay thickness)
- SmartSense auto-tuning technology
- Pseudo random sequence (PRS) clock source, supports spread spectrum and programmable resistance switches for lower electromagnetic interference (EMI)
- Low power consumption with as low as 1.71-V operation and as low as 150-nA current consumption in Hibernate mode

The PSOC[™] 4100S Max device introduces the fifth-generation CAPSENSE[™] technology (Ratiometric sensing technology) and has the following additional features when compared to older generations:

• **Improved SNR**: Fifth-generation CAPSENSE[™] technology (Ratiometric sensing technology) significantly improves noise performance compared to previous generation devices

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¹ To achieve the best CAPSENSE[™] performance, follow the recommendations in the Sensor pin selection section



- **Improved refresh rate**: The better sensitivity of multi sense converter (MSC) requires less time to get a similar signal as in previous generations; therefore, it is able to achieve a higher refresh rate. The two independent MSC blocks, which can scan the sensors in parallel improve the refresh rate further especially in use cases where large numbers of sensors need to be scanned
- **Improved CPU bandwidth**: Scan supported in both CPU mode and DMA mode. The CPU mode is a conventional interrupt-driven mode, while the DMA mode is capable of autonomous scanning which reduces the CPU bandwidth requirement to 18% compared to previous generations
- Improved noise immunity: Rail-to-rail swing is used as sense voltage, which provides maximum sense voltage and better immunity. In the fifth-generation CAPSENSE[™] technology, full-wave differential sensing is used for self-capacitance sensing and this cancels out noise induced from the external environment to the sensor routings. This sensing technology is also better immune to power supply (V_{dd}) noise

The PSOC[™] 4000T device is a member of the PSoC[™] 4 MCU family with fifth-generation CAPSENSE[™] and multisense technology. It offers an ultra-low power touch HMI solution, based on an integrated **"Always-On"** sensing technology, improved performance to enable modern sleek user interface solutions with superior liquid tolerance, and robust and reliable touch HMI solutions for harsh environments.

1.3 PSOC[™] 4 and PSOC[™] 6 MCU CAPSENSE[™] Plus features

You can create PSOC[™] 4 CAPSENSE[™] Plus applications that feature capacitive touch sensing and additional system functionality. The key features of these devices, in addition to CAPSENSE[™] are:

- Arm[°]Cortex[°]-M0/M0+ CPU with single cycle multiply delivering up to 43 DMIPS at 48 MHz
- 1.71 V 5.5 V operation over –40 to 85° C ambient
- Up to 128 KB of flash (CM0+ has > 2X code density over 8-bit solutions)
- Up to 16 KB of SRAM
- Up to 94 programmable GPIOs
- Independent center-aligned PWMs with complementary dead-band programmable outputs, synchronized ADC operation (ability to trigger the ADC at a customer-specifiable time in the PWM cycle), and synchronous refresh (ability to synchronize PWM duty cycle changes across all PWMs to avoid anomalous waveforms)
- Comparator-based triggering of PWM Kill signals (to terminate motor-driving when an over-current condition is detected)
- 12-bit 1 Msps ADC including sample-and-hold (S&H) capability with zero-overhead sequencing allowing the entire ADC bandwidth to be used for signal conversion and none used for sequencer overhead
- Opamps with comparator mode and SAR input buffering capability
- Segment LCD direct drive that supports up to four commons
- SPI/UART/I2C serial communication channels
- Bluetooth[®] LE communication compliant with version 4.0 and multiple features of version 4.1
- Programmable logic blocks, each having eight macrocells and a cascadable data path, called universal digital blocks (UDBs) for efficient implementation of programmable peripherals (such as I2S)
- Controller area network (CAN)
- Fully-supported PSOC[™] Creator design entry, development, and debug environment providing:
 - Design entry and build (comprehending analog routing)
 - Components for all fixed-function peripherals and common programmable peripherals
 - Documentation and training modules
- Support for porting builds to MDK Arm[®] environment (previously known as RealView) and others
- Support for Eclipse integrated development environment (IDE) for ModusToolbox™

The main features of PSOC[™] 6 MCU device, in addition to CAPSENSE[™] are:



- Single CPU devices (Arm[®] Cortex[®] M4), dual CPU devices (Arm[®] Cortex[®] M4 and Cortex[®] M0+). Support for inter-processor communication in hardware
- 1.71 V 3.6 V device operating voltage with user selectable core logic operation at either 1.1 V or 0.9 V
- Up to 2 MB of flash memory and up to 1 MB of SRAM
- Up to 78 GPIOs that can be used for analog, digital, CAPSENSE™, or segment LCD functions
- Programmable analog blocks: Two opamps, configurable PGAs, comparators, 12-bit 1 Msps SAR ADC, 12 -bit voltage mode DAC
- Programmable digital blocks, communication interfaces
- 12 UDBs, 32 TCPWMs configurable as 16-bit/32-bit timer, counter, PWM, or quadrature decoder
- Up to 13 serial communication block (SCB) configurable as I2C, SPI, or UART interfaces. See the Device datasheet for more details
- Audio subsystem with one I2S interface and two PDM channels
- SMIF interface with support for execute-in-place from external quad SPI flash memory and on-the-fly encryption and decryption
- Bluetooth[®] Smart connectivity with Bluetooth[®] LE 5.0 (applicable only to PSOC[™] 6 MCU with Bluetooth[®] LE family of devices)

See AN64846 - Getting started with CAPSENSE[™] to select an appropriate CAPSENSE[™] device based on your requirements.

1.4 CAPSENSE[™] design flow

Figure 1 illustrates the product design cycle with capacitive sensing; the information in this guide is highlighted in green. provides links to the supporting documents for each of the numbered tasks in Figure 1.

PSOC[™] 4 and PSOC[™] 6 MCU CAPSENSE[™] design guide



1 Introduction



Figure 1

Table 1 **Supporting documentation**

Steps in flowchart	Supporting documentation		
	Name	Chapter	
1. Understanding	CAPSENSE [™] design guide (This document)	Chapter 2 and Chapter 3	
CAPSENSE™	Getting started with CAPSENSE™	_	
(table continues)			



Steps in flowchart	Supporting documentation		
	Name	Chapter	
2. Specify requirements	Getting started with CAPSENSE™	-	
3. Feasibility study	PSOC [™] 4 datasheet	-	
	PSOC [™] 4 Bluetooth [®] LE datasheet		
	PSOC [™] 6 MCU datasheet		
	AN64846 – Getting started with CAPSENSE [™] design guide	-	
	AN79953 – Getting started with PSOC [™] 4		
	AN91267 – Getting started with PSOC [™] 4 Bluetooth [®] LE		
	AN221774 – Getting started with PSOC [™] 6 MCU		
4. Schematic design	CAPSENSE [™] design guide (This document)	Chapter 7	
5. Layout design	CAPSENSE [™] design guide (This document)	Chapter 7	
6. Component configuration	PSOC [™] CAPSENSE [™] Component datasheet/ middleware document	-	
	CAPSENSE [™] design guide (This document)	Chapter 5	
7. Performance tuning	PSOC [™] CAPSENSE [™] design guide (This document)	Chapter 5	
8. Firmware design	PSOC [™] Component datasheet/middleware document	-	
	PSOC [™] Creator	-	
	Example projects		
	Download ModusToolbox [™] here.		
	See the ModusToolbox™ related documents:		
	ModusToolbox™ release notes		
	ModusToolbox™ user guide		
	ModusToolbox [™] quick start guide		
	ModusToolbox [™] CAPSENSE [™] configurator guide		
	ModusToolbox [™] CAPSENSE [™] tuner guide		
	PSOC [™] Creator to ModusToolbox [™] porting guide		
9. Programming PSOC [™]	PSOC [™] Creator user guide for in-IDE programming	-	
	PSOC [™] Programmer home page and MiniProg3 user guide for standalone programming		
10. Prototype	-	-	
11. Design validation	CAPSENSE [™] design guide (This document)	Chapter 5	
12. Production	_	_	



2 CAPSENSE[™] technology

Capacitive touch sensing technology measures changes in capacitance between a plate (the sensor) and its environment to detect the presence of a finger on or near a touch surface.

2.1 CAPSENSE[™] fundamentals

A typical CAPSENSE[™] sensor consists of a copper pad of proper shape and size etched on the surface of a PCB. A non-conductive overlay serves as the touch surface for the button, as Figure 2 shows.



Figure 2 Capacitive touch sensor

PCB traces and vias connect the sensor pads to PSOC[™] GPIOs that are configured as CAPSENSE[™] sensor pins. As Figure 3 shows, the self-capacitance of each electrode is modeled as C_{SX} and the mutual capacitance between electrodes is modeled as C_{MX} . CAPSENSE[™] circuitry internal to the PSOC[™] converts these capacitance values into equivalent digital counts (see Chapter 3 for details). These digital counts are then processed by the CPU to detect touches.

CAPSENSE[™] also requires external capacitor C_{MOD} or C_{INT} for self-capacitance sensing and mutual-capacitance sensing. For third- and fourth-generation CAPSENSE[™] architecture, a single C_{MOD} capacitor is required for self-capacitance sensing and C_{INTA} and C_{INTB} capacitors for mutual-capacitance sensing. If shield electrode is implemented for liquid tolerance, or for large proximity sensing distance, an additional C_{TANK} capacitor may be required. For Fifth-Generation CAPSENSE[™] architecture, two C_{MOD} capacitors are required for both self-capacitance and mutual-capacitance sensing for each channel. These external capacitors are connected between a dedicated GPIO pin and ground. Table 39 list the recommended values of the external capacitors.





Figure 3 PSOC[™] device, sensors, and external capacitors

The capacitance of the sensor in the absence of a touch is called the parasitic capacitance, *C*_P. *C*_P results from the electric field between the sensor (including the sensor pad, traces, and vias) and other conductors in the system such as the ground planes, traces, and any metal in the product's chassis or enclosure. The GPIO and internal capacitances of PSOC[™] also contribute to the parasitic capacitance. However, these internal capacitances are typically very small compared to the sensor capacitance.

2.1.1 Self-capacitance sensing

Figure 4 shows how a GPIO pin is connected to a sensor pad by traces and vias for self-capacitance sensing. Typically, a ground (GND) hatch surrounds the sensor pad to isolate it from other sensors and traces. Although Figure 4 shows some field lines around the sensor pad, the actual electric field distribution is very complex.





Figure 4 Parasitic capacitance

When a finger is present on the overlay, the conductive nature and large mass of the human body forms a grounded, conductive plane parallel to the sensor pad, as Figure 5 shows.



Figure 5 Finger capacitance

This arrangement forms a parallel plate capacitor. The capacitance between the sensor pad and the finger is shown in Equation 1.

$$C_F = \frac{\epsilon_0 \, \epsilon_r \, A}{d}$$

Equation 1 Finger capacitance

Where:

- ε_0 = Free space permittivity
- ε_r = Relative permittivity of overlay
- A = Area of finger and sensor pad overlap
- d = Thickness of the overlay
- $C_{\rm F}$ = Finger capacitance.



 C_P and C_F are parallel to each other because both represent the capacitance between the sensor pin and ground. Therefore, the total capacitance C_S of the sensor, when the finger is present on the sensor, is the sum of C_P and C_F .

 $C_s = C_P + C_F$

Equation 2 Total sense capacitance when finger is present on sensor

In the absence of touch, C_S is equal to C_P .

PSOC[™] converts the capacitance CS into equivalent digital counts called raw counts. Because a finger touch increases the total capacitance of the sensor pin, an increase in the raw counts indicates a finger touch. Refer to the CSD specification in Device datasheet/Component datasheet/middleware document document to learn about the supported CP range for a given device with which the recommended SNR can be achieved.

2.1.2 Mutual-capacitance sensing

Figure 6 shows the button sensor layout for mutual-capacitance sensing. Mutual-capacitance sensing measures the capacitance between two electrodes, transmit (Tx) electrode and receive (Rx) electrode.

In a mutual-capacitance sensing system, a digital voltage signal switching between VDDIO²⁾ or VDDD³⁾ (if VDDIO is not supported by the device) and GND is applied to the Tx pin and the amount of charge received on the Rx pin is measured. The amount of charge received on the Rx electrode is directly proportional to the mutual-capacitance ($C_{\rm M}$) between the two electrodes.

When a finger is placed between the Tx and Rx electrodes, the mutual-capacitance decreases to C¹_M, as shown in Figure 7. Because of the reduction in the mutual-capacitance, the charge received on the Rx electrode also decreases. The CAPSENSE[™] system measures the amount of charge received on the Rx electrode to detect a touch/no touch condition.

2

³ VDDD is the device power supply for digital section.







Mutual-capacitance sensing





Mutual-capacitance with finger touch

2.2 Capacitive touch sensing method

PSOC[™] uses patented capacitive touch-sensing method CAPSENSE[™] sigma delta (CSD) for self-capacitance sensing and CAPSENSE[™] crosspoint (CSX) for mutual-capacitance scanning. The CSD and CSX touch sensing methods provide the industry's best-in-class Signal-to-noise ratio (SNR). These sensing methods are a combination of hardware and firmware techniques.



2.2.1 CAPSENSE[™] sigma delta (CSD)

Figure 8 shows a simplified block diagram of the CSD method.

In CSD, each GPIO has a switched-capacitance circuit that converts C_s into an equivalent current. An analog MUX (AMUX) selects one of the sensor currents and feeds it into the current to digital converter. The current to digital converter is similar to a delta sigma ADC. The output count of the current to digital converter, known as raw count, is a digital value that is proportional to the self-capacitance between the electrodes.

raw count = $G_{CSD} C_S$

Equation 3 Raw count and sensor capacitance relationship in CSD

Where,

 G_{CSD} = Capacitance to digital conversion gain of CSD

 $C_{\rm S}$ = Self-capacitance of the electrode



Figure 8 Simplified diagram of CSD method

Figure 10 illustrates a plot of raw count over time. When a finger touches the sensor, the C_S increases from C_P to $C_P + C_F$, and the raw count increases. By comparing the change in raw count to a predetermined threshold, logic in firmware decides whether the sensor is active (finger is present).

2.2.2 CAPSENSE[™] crosspoint (CSX)

Figure 9 shows the simplified block diagram of the CSX method.





Figure 9 Simplified diagram of CAPSENSE[™] crosspoint (CSX) method

With CSX, a voltage on the Tx electrode couples charge on to the RX electrode. This charge is proportional to the mutual capacitance between the Tx and Rx electrodes. An analog MUX then selects one of the Rx electrodes and feeds it into the current to digital converter.

The output count of the current to digital converter, *Rawcount_{Counter}*, is a digital value that is proportional to the mutual-capacitance between the Rx and Tx electrodes as shown in Equation 4.

 $Rawcount_{Counter} = G_{CSX} C_M$

Equation 4 Raw count and sensor capacitance relationship in CSX

Where,

 G_{CSX} = Capacitance to digital conversion gain of mutual capacitance method

 $C_{\rm M}$ = Mutual-capacitance between two electrodes

Figure 10 illustrates a plot of raw count over time. When a finger touches the sensor, C_M decreases from C_M to C^1_M (see Figure 7) hence the counter output decreases. The firmware normalizes the raw count such that the raw counts go high when C_M decreases. This maintains the same visual representation of raw count between CSD and CSX methods. By comparing the change in raw count to a predetermined threshold, logic in firmware decides whether the sensor is active (finger is present). The normalized inverted raw count is computed using Equation 15.





Figure 10 Raw count versus time

For an in-depth discussion of the PSOC[™] 4 and PSOC[™] 6 CAPSENSE[™] CSD and CSX blocks, see chapter PSOC[™] 4 and PSOC[™] 6 MCU CAPSENSE[™].

2.3 Signal-to-noise ratio (SNR)

In practice, the raw counts vary due to inherent noise in the system.CAPSENSE[™] noise is the peak-to-peak variation in raw counts in the absence of a touch, as Figure 11 shows.

A well-tuned CAPSENSE[™] system reliably discriminates between the ON and OFF states of the sensors. To achieve good performance, the CAPSENSE[™] signal must be significantly larger than the CAPSENSE[™] noise. SNR is defined as the ratio of CAPSENSE[™] signal to CAPSENSE[™] noise is the most important performance parameter of a CAPSENSE[™] sensor.



In this example, the average level of raw count in the absence of a touch is 5925 counts. When a finger is placed on the sensor, the average raw count increases to 6060 counts, which means the signal is 6060–5925 = 135



counts. The minimum value of the raw count in the OFF state is 5912 and the maximum value is 5938 counts. Therefore, the CAPSENSE[™] noise is 5938 – 5912 = 26 counts. This results in an SNR of 135/26 = 5.2.

The minimum SNR recommended for a CAPSENSE[™] sensor is 5. This 5:1 ratio comes from best practice threshold settings, which enable enough margin between signal and noise in order to provide reliable ON/OFF operation.

2.4 CAPSENSE[™] widgets

CAPSENSE[™] widgets consist of one or more CAPSENSE[™] sensors, which as a unit represent a certain type of user interface. CAPSENSE[™] widgets are broadly classified into four categories – buttons (zero-dimensional), sliders (one-dimensional), touchpads/trackpads (two-dimensional), and proximity sensors (three-dimensional). Figure 12 shows button, slider, and proximity sensor widgets. This section explains the basic concepts of different CAPSENSE[™] widgets. For a detailed explanation of sensor construction, see Sensor construction.



Figure 12 Several types of widgets

2.4.1 Buttons (zero-dimensional)

CAPSENSE[™] buttons replace mechanical buttons in a wide variety of applications such as home appliances, medical devices, white goods, lighting controls, and many other products. It is the simplest type of CAPSENSE[™] widget, consisting of a single sensor. A CAPSENSE[™] button gives one of two possible output states: active (finger is present) or inactive (finger is not present). These two states are also called ON and OFF states, respectively.

For the self-capacitance (CSD) sensing method, a simple CAPSENSE[™] button consists of a circular copper pad connected to a PSOC[™] GPIO with a PCB trace. The CAPSENSE[™] button is surrounded by grounded copper hatch that isolates it from other buttons and traces. A circular gap separates the button pad and the ground hatch. Each button requires one PSOC[™] GPIO. These buttons can be constructed using any conductive material on a non-conductive substrate; for example, indium tin oxide on a glass substrate, or silver ink on a non-conductive film. Even metallic springs can be used as button sensors; see Sensor construction for more details.





Figure 13 Simple CAPSENSE[™] buttons

For the mutual-capacitance (CSX) sensing method, each button requires one GPIO pin configured as Tx electrode and one GPIO pin configured as Rx electrode. The Tx pin and Rx pins can be shared across multiple buttons, with each button being a unique intersection of Rx and Tx like in Figure 14. However, it is recommended to minimize the Rx trace length and shield the Rx trace with ground on both sides, to minimize noise coupling into the Rx.



Figure 14 Simple CAPSENSE[™] buttons for mutual-capacitance sensing method

If the application requires many buttons (for example in a calculator keypad or a QWERTY keyboard), you can arrange the CAPSENSE[™] buttons in a matrix, as Figure 15 shows. This allows a design to have multiple buttons per GPIO. For example, the 16-button design in Figure 15 requires only eight GPIOs.





Figure 15 Matrix buttons based on CSD

A matrix button design has two groups of capacitive sensors: row sensors and column sensors. The matrix button architecture can be used for both self-capacitance (CSD) and mutual-capacitance (CSX) methods.

In CSD mode, each button consists of a row sensor and a column sensor, as Figure 15 shows. When a button is touched, both row and column sensors of that button become active. The CSD-based matrix button should be used only if the user is expected to touch one button at a time. If the user touches more than one diagonally opposite buttons, the finger location cannot be resolved as Figure 16 shows. This effect is called as ghost effect, which is considered an invalid condition.





Figure 16 Ghost effect in matrix button based on CSD

Mutual-capacitance is the recommended sensing method for matrix buttons because this method is not affected from the ghost touch phenomena and provides better SNR for high C_p sensors. This is because it senses mutual-capacitance formed at each intersection rather than sensing rows and columns as shown in Figure 17. Applications that require simultaneous sensing of multiple buttons, such as a keyboard with **Shift**, **Ctrl**, and **Alt** keys can use CSX sensing method or you should design the **Shift**, **Ctrl**, and **Alt** keys as individual CSD buttons.





Figure 17 Matrix button based on CSX

Note: Scanning a matrix keypad using CSX sensing method may require a longer overall scan time than the CSD sensing method. This is because the CSD sensing method scans rows and columns as sensors, while the CSX sensing method scans each intersection as a sensor.

2.4.2 Sliders (one-dimensional)

Sliders are used when the required input is in the form of a gradual increment or decrement. Examples include lighting control (dimmer), volume control, graphic equalizer, and speed control. Currently, the CAPSENSE™ Component in PSOC[™] Creator and ModusToolbox[™] supports only self-capacitance-based sliders. Mutual capacitance-based sliders will be supported in future version of component.

A slider consists of a one-dimensional array of capacitive sensors called segments, which are placed adjacent to one another. Touching one segment also results in partial activation of adjacent segments. The firmware processes the raw counts from the touched segment and the nearby segments to calculate the position of the geometric center of the finger touch, which is known as the **centroid position**.

The actual resolution of the calculated centroid position is much higher than the number of segments in a slider. For example, a slider with five segments can resolve at least 100 physical finger positions. This high resolution gives smooth transitions of the centroid position as the finger glides across a slider.

In a linear slider, the segments are arranged inline, as Figure 18 shows. Each slider segment connects to a PSOC[™] GPIO. A zigzag pattern (double chevron) is recommended for slider segments. This layout ensures that when a segment is touched, the adjacent segments are also partially touched, which aids estimation of the centroid position.





Figure 18 Linear slider

Radial sliders are similar to linear sliders except that radial sliders are continuous. Figure 19 shows a typical radial slider.





2.4.3 Touchpads/Trackpads (two-dimensional)

A touchpad (also known as trackpad) has two linear sliders arranged in an X and Y pattern, enabling it to locate a finger's position in both X and Y dimensions. Figure 20 shows a typical arrangement of a touchpad sensor. Similar to the matrix buttons, touchpads can also be sensed using either CSD or CSX sensing method. CSD-based touchpads suffer from ghost touches, so it supports only single-point touch applications.



CSX touchpads can support multi-point touch applications, but these may need more scanning time compared to CSD touchpad because this method scans each intersection rather than rows and columns.



Figure 20 Touchpad sensor arrangement

See AN234185 PSOC[™] 4 CAPSENSE[™] Touchpad design guide to learn more.

2.4.4 Proximity (three-dimensional)

Proximity sensors detect the presence of a hand in the three-dimensional space around the sensor. However, the actual output of the proximity sensor is an ON/OFF state similar to a CAPSENSE[™] button. Proximity sensing can detect a hand at a distance of several centimeters to tens of centimeters depending on the sensor construction. Self capacitance is the recommended method of sensing for a proximity application.

Proximity sensing requires electric fields that are projected to much larger distances than buttons and sliders. This demands a large sensor area. However, a large sensor area also results in a large parasitic capacitance C_P , and detection becomes more difficult. This requires a sensor with high electric field strength at large distances while also having a small area. Figure 21 shows a proximity sensor using a trace with a thickness of 2-3 mm surrounding the other sensors.



Figure 21 Proximity sensor

You can also implement a proximity sensor by ganging other sensors together. This is accomplished by combining multiple sensor pads into one large sensor using firmware. The disadvantage of this method is high parasitic capacitance. See the Component datasheet/middleware document for details on maximum parasitic capacitance supported by a given device.

See AN92239 proximity sensing with CAPSENSE[™] and the proximity sensing section in Getting started with CAPSENSE[™] design guide to learn more about proximity sensors.



2.5 Liquid tolerance

Capacitive sensing is used in a variety of applications such as home appliances, automotive, and industrial applications. These applications require robust capacitive-sensing operation even in the presence of mist, moisture, water, ice, humidity, or other liquids. In a capacitive-sensing application design, false sensing of touch or proximity detection may happen due to the presence of a film of liquid or liquid droplets on the sensor surface, due to the conductive nature of some liquids. CSD sensing method can compensate for variation in raw count due to these causes and provide a robust, reliable, capacitive sensing application operation.



Figure 22 Liquid-tolerant CAPSENSE[™]-based touch user interface in washing machine

- To compensate for changes in raw count due to mist, moisture, and humidity changes, the CAPSENSE™ sensing method continuously adjusts the baseline of the sensor to prevent false triggers
- To prevent sensor false triggers due to a liquid flow, you should implement a Guard sensor as Figure 23 shows. The Driven shield signal and shield electrode can be used to detect the presence of a streaming liquid and ignore the status or stop the sensing from rest of the sensors as long as the liquid flow is present
- **Note**: the guard sensor itself is just another self-capacitance sensor; even though you could implement it around mutual-capacitance sensors also for liquid flow tolerance. PSOC[™] devices allow implementation of such self-capacitance sensors and mutual-capacitance sensors together in the same design
- To compensate for changes in raw count due to liquid droplets for self-capacitance sensing, you can
 implement a Driven shield signal and shield electrode as Figure 23 shows. When a shield electrode is
 implemented, CAPSENSE™ reliably works and reports the sensor ON/OFF status correctly, even when
 liquid droplets are present on the sensor surface. To prevent sensor false triggers due to liquid droplets
 for mutual-capacitance sensing, you can use both the sensing methods that is, mutual capacitance and
 self-capacitance with Driven shield signal and shield electrode on the same set of sensors as Using
 self-capacitance sensing for liquid tolerance of mutual-capacitance sensors explains

In summary, if your application requires tolerance to liquid droplets, implement a Driven shield signal and shield electrode. If your application requires tolerance to streaming liquids along with liquid droplets, implement a Driven shield signal and shield electrode and a Guard sensor as shown in Figure 23. Follow the schematic and layout guidelines explained in the Layout guidelines for liquid tolerance section to construct the shield electrode and guard sensor respectively.





2.5.1 Liquid tolerance for self capacitance sensing

2.5.1.1 Effect of liquid droplets and liquid stream on a self-capacitance sensor

To understand the effect of liquids on a CAPSENSETM sensor, consider a CAPSENSETM system in which the hatch fill around the sensor is connected to ground, as Figure 24(a) shows. The hatch fill when connected to a GND improves the noise immunity of the sensor. Parasitic capacitance of the sensor is denoted as C_P in Figure 24(b).





Figure 24 Typical CAPSENSE[™] system layout

As shown in Figure 25, when a liquid droplet falls on the sensor surface, due to its conductive nature it provides a strong coupling path for the electric field lines to return to ground; this adds a capacitance C_{LD} in parallel to C_P . This added capacitance draws an additional charge from the AMUX bus as explained in GPIO cell capacitance to current converter resulting in an increase in the sensor raw count. In some cases (such as salty water or water containing minerals), the increase in raw count when a liquid droplet falls on the sensor surface may be equal to the increase in raw count due to a finger touch, as Figure 25 shows. In such a situation, sensor false triggers might occur.





Figure 25 Capacitance added by liquid droplet when the Hatch Fill is connected to GND

$C_{\rm P}$ = Sensor parasitic capacitance

 C_{LD} = Capacitance added by the liquid droplet





Effect of liquid droplet when the Hatch Fill around the sensor is connected to GND

To nullify the effect of capacitance added by the liquid droplet to the CAPSENSE[™] circuitry, you should drive the hatch fill around the sensor with the driven-shield signal.

As Figure 27 shows, when the hatch fill around the sensor is connected to the driven-shield signal and when a liquid droplet falls on the touch interface, the voltage on both sides of the liquid droplet remains at the same potential. Because of this, the capacitance, C_{LD} , added by the liquid droplet does not draw any additional charge from the AMUX bus and hence the effect of capacitance C_{LD} is nullified. Therefore, the increase in raw count when a water droplet falls on the sensor will be very small, as Figure 28 shows.





Figure 27 Capacitance added by liquid droplet droplet when the hatch fill around the sensor is connected to shield

 $C_{\rm S}$ = Sensor parasitic capacitance

 C_{SH} = Capacitance between the sensor and the hatch fill

 C_{HG} = Capacitance between the hatch fill and ground

 C_{LD} = Capacitance added by the liquid droplet



Figure 28 Effect of liquid droplet when the hatch fill around the sensor is connected to the driven-shield



Figure 26 shows how a sensor may false trigger in presence of a liquid, if hatch fill is connected to ground. Note however, that the same is not true for all cases. For example, spring sensors, which are inherently more liquid tolerant than sensors etched on PCB surface. As Figure 29 shows, due to the large airgap between the liquid drop and the hatch fill, the capacitance C_{LD} between the liquid drop and grounded hatch pattern on the PCB would be very low so as not to cause any false triggers. If required, the hatched pattern on the PCB can still be connected to a driven shield electrode to further nullify the effect of C_{LD} and have an improved liquid tolerance.





2.5.1.2 Driven shield signal and shield electrode

The driven-shield signal is a buffered version of the sensor-switching signal, as Figure 30 shows. The drivenshield signal has the same amplitude, frequency, and phase as that of sensor switching signal. When the hatch fill around the sensor is connected to the driven shield signal, it is referred as shield electrode.



Figure 30

Driven shield signal

- To implement liquid-tolerant CAPSENSE[™] designs: Shield electrode helps in making CAPSENSE[™] designs liquid-tolerant as explained above
- To improve proximity sensing distance in presence of floating or grounded conductive objects: A shield electrode, when placed between the proximity sensor and a floating or a grounded conductive object, reduces the effect of these objects on the proximity-sensing distance and helps in achieving large



proximity-sensing distance. See the "Proximity Sensing" section in the Getting started with CAPSENSE™ design guide for more details

• To reduce the parasitic capacitance of the sensor: When a CAPSENSE[™] sensor has a long trace, the CP of the sensor will be very high because of the increased coupling of sensor electric field lines from the sensor trace to the surrounding ground. By implementing a shield electrode, the coupling of electric field lines to ground is reduced, which results in reducing the CP of the sensor

See Layout guidelines for shield electrode for layout guidelines of shield electrode.

2.5.1.3 Guard sensor

When a continuous liquid stream is present on the sensor surface, the liquid stream adds a large capacitance (C_{ST}) to the CAPSENSETM sensor. This capacitance may be several times larger than C_{LD} . Because of this, the effect of the shield electrode is completely masked, and the sensor raw counts will be same as or even higher than a finger touch. In such situations, a guard sensor is useful to prevent sensor false triggers.

A guard sensor is a copper trace that surrounds all the sensors on the PCB, as Figure 31 shows. A guard sensor is similar to a button sensor and is used to detect the presence of streaming liquids. When a guard sensor is triggered, the firmware should disable the scanning of all other sensors except the guard sensor to prevent sensor false triggers.





Figure 31 Measurement with a liquid stream

See Layout guidelines for guard sensor for PCB layout guidelines for implementing a guard sensor.

If there is no space on the PCB for implementing a guard sensor, the guard sensor functionality can be implemented in the firmware. For example, you can use the ON/OFF status of different sensors to detect a liquid stream depending on the use case, such as follows:

• When there is a liquid stream, more than one button sensor will be active at a time. If your design does not require multi-touch sensing, you can detect this and ignore the sensor status of all the button sensors to prevent false triggering



- In a slider, if the slider segments which are turned ON are not adjacent segments, you can reset the slider segments status or ignore the slider centroid value that is calculated
- Likewise, you could create your own custom algorithm to detect the presence of streaming liquids and ignore the sensor status during the time a liquid is present on the touch surface
- **Note**: The sensors are not scanned, or the sensor status is ignored when the guard sensor is triggered; therefore, touch cannot be detected when there is a liquid stream on the touch surface

2.5.2 Liquid tolerance for mutual-capacitance sensing

2.5.2.1 Effect of liquid droplets and liquid stream on a mutual-capacitance sensor

Mutual-capacitance buttons often have a grounded hatch fill around the sensors for improved noise immunity. If a liquid droplet falls over the sensor while covering some part of the grounded hatch, the mutual-capacitance decreases similar to the effect of placing a finger on the sensor. This decrease in mutual-capacitance causes an increase in raw count as explained in CAPSENSE[™] CSX sensing method (third- and fourth- generation) in and as shown in the Figure 32. The amount of increase in the raw count depends on the size and characteristics of the liquid drop.

However, mutual-capacitance increases if the liquid droplet covers just the Tx and Rx electrode and does not spread over the grounded hatch. This causes a decrease in raw count as shown in Figure 32. This decrease in raw count may cause the baseline reset due to Low baseline reset. Once the liquid drop is removed, the raw count would rise while the baseline may remain at the lower value, resulting in a difference signal which may cause the sensor to false trigger.



Figure 32

Effect of liquid droplet on CSX sensor when the Hatch Fill around the sensor is connected to ground


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2.5.2.2 Using self-capacitance sensing for liquid tolerance of mutualcapacitance sensors

CAPSENSE[™] senses the self-capacitance of Tx and Rx nodes of a mutual-capacitance sensor. This ability of scanning the sensor using both CSD and CSX modes could be used to avoid false triggers due to the presence of liquid drops on a mutual capacitance sensor. See the code example PSOC[™] 4 hybrid sensing using CAPSENSE[™] to understand how to sense a mutual-capacitance button with both CSD as well as CSX sensing method.

To achieve liquid tolerance, you need to scan the Rx electrode of the sensor with the CSD sense method. While scanning the Rx electrode as a CSD sensor, ensure that you enable the shield electrode, and connect the Tx pin of the mutual-capacitance sensor to the driven shield signal. You can use the low-level API function CapSense_SetPinState() to connect the Tx pin of the mutual-capacitance sensor to the shield electrode before calling the CapSense_ScanAllWidgets() API function that scans the Rx electrode as a CSD sensor as shown below:

CapSense_SetPinState(CapSense_BUTTON1_WDGT_ID,CapSense_BUTTON1_TX0_ID,CapSense_SHIELD); CapSense_ScanAllWidgets();

From sections 2.5.1 and 2.5.2 you understood the effect of liquid drop on the CSD and CSX button respectively. By utilizing the difference in their response to the liquid drop, you can create a firmware logic to achieve a liquid-tolerant mutual-capacitance sensor. The effect of presence of the liquid drop on the CSD and CSX scan results is summarized in Figure 33.



Figure 33 Effect of water drop on the CSX sensor pattern scanned with CSD and CSX methods

Where Figure 33 shows the effect of the water drop on the CSX sensor pattern surrounded by hatch fill when scanned using this method. The regions in Figure 33 represent the following:



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- **1.** Finger touch
- 2. Liquid droplet on the Tx line and grounded shield hatch
- **3.** Liquid drop present on the Tx and Rx electrodes only
- **4.** Finger touch when a liquid drop is on the Tx and Rx electrodes only
- 5. Liquid drop removed from the Tx and Rx electrodes

The changes in raw count as shown in Figure 33 can be used in the firmware to reset the baseline of the CSX sensor to nullify the effect of liquid drops. The button status should be ON state for Region 1, 4, and OFF state in other regions; additionally, the baseline of the CSX button must be re-initialized in Region 3 and Region 5. The baseline of the sensor could be reset by using the CapSense_InitializeWidgetBaseline() API function as shown below:

CapSense_InitializeWidgetBaseline(CapSense_CSX_BUTTON_WDGT_ID);

See the Component datasheet/middleware document or more details on using this API; see Selecting CAPSENSE™ software parameters to learn about the baseline of the sensor.

2.5.3 Effect of liquid properties on liquid-tolerance performance

In certain applications, the CAPSENSE[™] system has to work in the presence of a variety of liquids such as soap water, sea water, and mineral water. In such applications, it is always recommended to tune the CAPSENSE[™] parameters for sensors by considering the worst-case signal due to liquid droplets. To simulate the worst-case conditions, it is recommended that you test the liquid-tolerance performance of the sensors with salty water by dissolving 40 grams of cooking salt (NaCl) in one liter of water. Tests were done using soapy water; the results show that the effect of soapy water is similar to the effect of salty water. Therefore, if the tuning is done to reject salty water, the CAPSENSE[™] system will work even in the presence of soapy water.

In applications such as induction cooktops, there are chances of hot water spilling on to the CAPSENSE[™] touch surface. To determine the impact of the temperature of a liquid droplet on CAPSENSE[™] performance, droplets of water at different temperatures were poured on a sensor and the corresponding change in raw counts was monitored. Experiment shows that the effect of hot liquid droplets is same as that of the liquid at room temperature as Figure 34 shows. This is because the hot liquid droplet cools down immediately to room temperature when it falls on the touch surface. If hot water continuously falls on the sensor and the temperature of the overlay rises because of the hot water, the increase in raw count due to the increase in temperature is compensated by the Baseline update algorithm, thereby preventing any false triggering of the sensors.



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3 PSOC[™] 4 and PSOC[™] 6 MCU CAPSENSE[™]

This chapter explains how CAPSENSE[™] CSD and CSX (third, fourth, and fifth generations) are implemented in the PSOC[™] 4 and PSOC[™] 6 MCUs. See Capacitive touch sensing method to understand the basic principles of CAPSENSE[™]. A basic knowledge of the PSOC[™] device architecture is a prerequisite for this chapter. If you are new to PSOC[™] 4, see AN79953 - Getting started with PSOC[™] 4 or AN91267 - Getting started with PSOC[™] 4 Bluetooth[®] LE; for PSOC[™] 6 MCU, see AN221774 - Getting started with PSOC[™] 6 MCU.

You can skip this chapter if you are using the automatic tuning feature (SmartSense) of the Component. See the CAPSENSE[™] performance tuning chapter for details.

The PSOC[™] 4 family of devices has three different CAPSENSE[™] architectures. Table 2 explains the differences between the third and fifth-generation CAPSENSE[™] architecture.

3.1 CAPSENSE[™] generations in PSOC[™] 4 and PSOC[™] 6

Table 2 lists the main differences in the CAPSENSE[™] architecture for CSD and CSX.

Feature	Third-generation CAPSENSE [™]	Fourth- generation CAPSENSE™	Fifth- generation CAPSENSE [™]	Improvement impact	Conditions
SNR	5:1	6.5:1	48:1	Higher SNR implies better sensitivity, that is, ability to sense smaller signals.	$V_{DD} = 5 V;$ No firmware filter; $C_p \sim = 33 pF;$ $C_f = 0.1 pF$
Sensing mode	Self-cap and mutual-cap modes	Self-cap, mutual-cap, and ADC modes	Self-cap and mutual-cap modes	-	-
Sensor capacitance parasitic range	5 pF – 45 pF	5 pF – 200 pF	2 pF – 200 pF	Greater C _p range implies higher flexibility in PCB layout routing and ability to sense with very short/ long sensor traces, and for different PCB materials (for example, FFC and so on).	

Table 2Comparison of CAPSENSE™ architecture for CSD and CSX

(table continues...)



Feature	Third-generation CAPSENSE™	Fourth- generation CAPSENSE™	Fifth- generation CAPSENSE™	Improvement impact	Conditions
Typical sense signal needed	100 fF	100 fF	15 fF for CSD-RM 10 fF for CSX-RM	Smaller sense signal required, implying support for thicker overlays, higher proximity range, smaller sensor size, and so on.	V _{DD} = 5 V; No firmware filter; C _p ~= 33 pF; SNR = 5:1;
Noise floor (rms)	-	-	500 aF for CSD-RM 100 aF for CSX-RM	Higher SNR or lower noise floor implies ability to sense smaller signals.	V _{DD} - 5 V; C _p ~= 33 pF; C _M = 5 pF
Overlay thickness supported	Up to 5 mm	Up to 5 mm	Up to 18 mm	Supports designs with thicker overlay.	10 mm CSD button; Acrylic overlay; SNR = 5:1; C _p ~= 22 pF;
Refresh rate	-	22 Hz	242 Hz	Faster refresh rate enables fast gestures and taps detections on applications such as large trackpad and long sliders or large number of button sensors with single device, and so on.	7x5 CSX touchpad; Acrylic overlay 3 mm thickness; SNR = 10:1; Finger Size = 8 mm;
CPU bandwidth requirement	Completely CPU driven. CPU is required for initialization and sequencing the sensors.	40% sequencer ¹⁾ It takes care of initialization, configuration, and scanning of sensors. CPU is needed for sequencing through each sensor.	7% Completely autonomou s.	Reduced CPU usage for sensing frees the CPU to perform other peripheral operations, and act as a central controller in an application.	10x8 CSX touchpad; Scan clock = 1 MHz; No of sub- conversions = 70; Refresh rate = 100 Hz;
Emission control options.	PRS	PRS, SSC	PRS, SSC	-	-



Feature		Third-generation CAPSENSE™	Fourth- generation CAPSENSE™	Fifth- generation CAPSENSE™	Improvement impact	Conditions
Noise immunit y	Sense Voltage (V _{ref})	1.2 V	1.2 V-2.8 V.	Rail to Rail	Higher the sense voltage, higher the noise immunity.	-
	Differenti al Sensing	Mutual-cap sensing	Mutual-cap sensing	Mutual-cap and self-cap sensing	Differential sensing cancels out noise induced from external environment through C _{MOD} .	
	V _{DD} noise impact	Yes	Yes	No	V _{DD} noise has minimal affect on fifth generation CAPSENSE [™] operation.	
Sense clock	Self-Cap	45 kHz – 6 MHz	45 kHz – 6 MHz	45 kHz – 6 MHz	Higher sense clock frequency	_
frequenc y	Mutual- Cap	45 kHz - 300 kHz	45 kHz - 3 MHz	45 kHz – 6 MHz	means faster scan for low C _p sensors. This provides ability to support faster taps or gestures, or for a given refresh rate, ability to implement multiple firmware filters for better immunity.	
Multi-cha support	nnel	No	No	Yes	Provides 'n' times increased speed of scanning for the same number of sensors, if 'n'channels are used.	_
Shield Cp				1.2 nF	_	_



Table 2	(continued)	Comparison of CAPSENSE	[™] architecture for CSD and CSX
Table Z	(continueu)	COMPANSON OF CAPSENSE	architecture for CSD and CSA

Feature	Third-generation CAPSENSE [™]	Fourth- generation CAPSENSE™	Fifth- generation CAPSENSE™	Improvement impact	Conditions
Device family	PSOC [™] 4100/4200 PSOC [™] 4100 M/ 4200 M PSOC [™] 4100 L/4200 L PSOC [™] 4100 BL/ 4200 BL	PSOC [™] 4000 PSOC [™] 4000S PSOC [™] 4100S PSOC [™] 4100S Plus PSOC [™] 6	PSOC [™] 4100 S Max PSOC [™] 4000 T(fifth- generation low-power) PSOC [™] 4100 T Plus (fifth- generation low-power)	-	-

1) The hardware state machine is a logic which controls the CAPSENSE[™] block and sensor scanning.

3.2 Capacitive Sigma-Delta (CSD) sensing method (third and fourth generation)

Figure 35 illustrates the CAPSENSE[™] block that scans CAPSENSE[™] sensors in the CSD sensing mode.





Figure 35 CAPSENSE[™] CSD sensing

As explained in Capacitive touch sensing method, this block works by first converting the sensor capacitance into an equivalent current. An analog multiplexer then selects one of the currents and feeds it into the currentto-digital converter. This current-to-digital converter consists of a sigma-delta converter, which controls the modulation IDAC for a specific period, the total current sourced or sinked by the IDACs is the same as the total current sinked or sourced by the sensor capacitance. The digital count output of the sigma-delta converter is an indicator of the sensor capacitance and is called a raw count. This block can be configured in either IDAC Sourcing mode or IDAC Sinking mode. In the IDAC Sourcing mode, the IDACs source current to AMUXBUS while the GPIO cells sink current from AMUXBUS. In the IDAC Sinking mode, the IDACs sink current from AMUXBUS while the GPIO cells source current to AMUXBUS.

3.2.1 GPIO cell capacitance to current converter

In the CAPSENSE[™] CSD system, the GPIO cells are configured as switched-capacitance circuits that convert sensor capacitances into equivalent currents. Figure 36 shows a simplified diagram of the GPIO cell structure.





Figure 36 GPIO cell structure

PSOC[™] 4 and PSOC[™] 6 devices consist of two AMUX buses: AMUXBUS A is used for CSD sensing and AMUXBUS B is used for CAPSENSE[™] CSD shielding. The GPIO switched-capacitance circuit has two possible configurations: source current to AMUXBUS A or sink current from AMUXBUS A

3.2.2 IDAC sourcing mode

In the IDAC Sourcing mode, the GPIO cell sinks current from the AMUXBUS A through a switched capacitor circuit as Figure 37 shows.





GPIO cell sinking current from AMUXBUS A



Two non-overlapping, out-of-phase clocks of frequency F_{SW} control the switches SW_1 and SW_3 as Figure 38 shows. The continuous switching of SW_1 and SW_3 forms an equivalent resistance R_S , as Figure 37 shows.





If the switches operate at a sufficiently low frequency F_{SW} , such that time $T_{SW}/2$ is sufficient to fully charge the sensor to V_{REF} and fully discharge it to ground, as Figure 38 shows, the value of the equivalent resistance R_S is given by Equation 5.

$$R_S = \frac{1}{C_S F_{SW}}$$

Equation 5 Sensor equivalent resistance

Where,

C_S = Sensor capacitance

 F_{SW} = Frequency of the sense clock

The sigma-delta converter maintains the voltage of AMUXBUS A at a constant V_{REF} (this process is explained in Sigma-delta converter. Figure 39 shows the resulting voltage waveform across C_{S} .



Figure 39



Equation 6 gives the value of average current taken from AMUXBUS A.



$$I_{CS} = C_S F_{SW} V_{REF}$$

Equation 6 Average current sinked from AMUXBUS A to GPIO through CAPSENSE[™] sensor (ICS)

3.2.3 IDAC sinking mode

In the IDAC sinking mode, the GPIO cell sources current to the AMUXBUS A through a switched capacitor circuit as Figure 40 shows. Figure 41 shows the voltage waveform across the sensor capacitance.

Because this mode charges the AMUXBUS A directly through V_{DDD} , it is more susceptible to power supply noise compared to the IDAC sourcing mode. Hence, it is recommended to use this mode with an LDO or a very stable and quiet V_{DDD} .





GPIO cell sourcing current to AMUXBUS A





Voltage across sensor capacitance



Equation 7 provides the value of average current supplied to AMUXBUS A.

 $I_{CS} = C_S F_{SW} \left(V_{DDD} - V_{REF} \right)$

Equation 7 Average current sourced to AMUXBUS A from GPIO through CAPSENSE[™] sensor (ICS)

3.2.4 CAPSENSE[™] clock generator

The CAPSENSETM clock generator block generates the sense clock F_{SW} , and the modulation clock F_{MOD} , from the high-frequency system resource clock (HFCLK) or peripheral clock (PERI) depending on the PSOCTM device family as shown in Figure 35.

3.2.4.1 Sense clock

The sense clock, also referred to as the switching clock, drives the non-overlapping clocks to the GPIO cell switched capacitor circuits for the GPIO cell capacitance to charge converter.

Sense clock can be sourced from three options: direct, 8-bit PRS, and 12-bit PRS. Some PSOC[™] 4 and PSOC[™] 6 MCU parts also support additional spread spectrum clock (SSCx) modes. For more details on the supported modes for PSOC[™] device, see the Component datasheet/middleware document.

Direct clock is a constant frequency sense clock source. When you chose this option, the sensor pin switches with a constant frequency clock with frequency as specified in the CAPSENSE[™] component configuration window.

PRS clock implies that the sense clock is driven from a PRS block, which can generate either 8-bit or 12-bit PRS. Use of the PRS clock spreads the sense clock frequency over a wide frequency range by dividing the input clock using a PRS.

SSCx also spreads the sense clock frequency. It provides better noise immunity and reduces radiated electromagnetic emissions.

See Manually tuning hardware parameters for details on the clock source and frequency selection guidelines.

3.2.4.2 Modulator clock

The modulation clock is used by the Sigma-delta converter. This clock determines the sensor scan time based on Equation 8 and Equation 9.

Sensor scan time = Hardware scan time+ Sensor Initialization time

Equation 8 Sensor scan time

 $(2^{\text{Resolution}} - 1)$

Hardware scan time= $\frac{1}{Modulator Clock Frequency}$

Equation 9 Hardware scan time

Where,

Resolution = Scan resolution

Sensor Initialization time = Time taken by the sensor to write to the internal registers and initiate a scan.



3.2.5 Sigma-delta converter

The sigma-delta converter converts the input current to a corresponding digital count. It consists of a sigmadelta converter and two current sourcing/sinking digital-to-analog converters (IDACs) called modulation IDAC and compensation IDAC as Figure 35 shows.

The sigma-delta converter uses an external integrating capacitor, called modulator capacitor C_{MOD} , as Figure 35 shows. Sigma-delta converter controls the modulation IDAC current by switching it ON or OFF corresponding to the small voltage variations across C_{MOD} to maintain the C_{MOD} voltage at V_{REF} . The recommended value of C_{MOD} is listed in Table 39.

The sigma-delta converter can operate in either IDAC sourcing mode or IDAC sinking mode.

- IDAC sourcing mode: In this mode, the GPIO cell capacitance to charge converter sinks current from C_{MOD} through AMUXBUS A, and the IDACs then source current to AMUXBUS A to balance its voltage
- IDAC sinking mode: In this mode, the GPIO cell capacitance to charge converter sources current from C_{MOD} to AMUXBUS A and the IDACs sink current through AMUXBUS A to balance its voltage

In both the above-mentioned modes, the sigma delta converter can operate in either single IDAC mode or dual IDAC mode:

- In the single IDAC mode, the modulation IDAC is controlled by the sigma-delta converter; the compensation IDAC is always OFF
- In the dual IDAC mode, the modulation IDAC is controlled by the sigma-delta converter; the compensation IDAC is always ON

In the single IDAC mode, if 'N' is the resolution of the sigma-delta converter and I_{MOD} is the value of the modulation IDAC current, the approximate value of raw count in the IDAC Sourcing mode is given by Equation 10.

raw count =
$$\left(2^N - 1\right) \frac{V_{REF} F_{SW}}{I_{MOD}} C_S$$

Equation 10 Single IDAC sourcing raw count

Similarly, the approximate value of raw count in the IDAC sinking mode is given by Equation 11.

raw count =
$$\left(2^N - 1\right) \frac{\left(V_{DD} - V_{REF}\right)F_{SW}}{I_{MOD}} C_S$$

Equation 11 Single IDAC sinking raw count

In both cases, the raw count is proportional to sensor capacitance C_S . The raw count is then processed by the CAPSENSETM CSD Component firmware to detect touches. The hardware parameters such as I_{MOD} , I_{COMP} , and F_{SW} , and the software parameters, should be tuned to optimum values for reliable touch detection. For an indepth discussion of the tuning, see CAPSENSETM performance tuning.

In the dual IDAC mode, the compensation IDAC is always ON. If I_{COMP} is the compensation IDAC current, the equation for the raw count in the IDAC sourcing mode is given by Equation 12.

raw count =
$$\left(2^{N}-1\right) \frac{V_{REF}F_{SW}}{I_{MOD}} C_{S} - \left(2^{N}-1\right) \frac{I_{COMP}}{I_{MOD}}$$

Equation 12 Dual IDAC sourcing raw count

Raw count in the IDAC sinking mode is given by Equation 13.



$$\operatorname{raw \ count} = \left(2^{N} - 1\right) \frac{V_{DD} - V_{REF} F_{SW}}{I_{MOD}} C_{S} - \left(2^{N} - 1\right) \frac{I_{COMP}}{I_{MOD}}$$

Equation 13 Dual IDAC sinking raw count

Note: Raw count values are always positive. It is thus imperative to ensure that I_{COMP} is less than $(V_{DD}-V_{REF})C_S F_{SW}$ for the IDAC sinking mode and I_{COMP} is less than $C_S F_{SW} V_{REF}$ for the IDAC Sourcing mode. Equation 13 does not hold true if $I_{COMP} > V_{REF} C_S F_{SW}$ and Equation 12 does not hold true if $I_{COMP} > (V_{DD} - V_{REF})C_S F_{SW}$; in these cases, raw counts will be zero.

The relation between the parameters shown in the above equation to the CAPSENSE[™] Component parameters is listed in Table 3.

Sl. No.	Parameter	Description	Comments
1	N	Scan resolution	Scan resolution is configurable from 6-bit to 16-bit.
			See Component datasheet/middleware document for details.
2	V _{REF}	N/A	The V _{REF} value is 1.2 V or configurable between 0.6 V to V _{DDA} - 0.6 V depending on the PSOC [™] device family. See Component datasheet/middleware document for details.
3	F _{SW}	Sense clock frequency	Sense clock frequency and sense clock source decide the frequency at which the sensor is switching.
		Sense clock source	See Sense clock for details.
4	/ _{MOD}	Modulator IDAC	I _{MOD} = Modulation IDAC current
5	I _{COMP}	Compensation IDAC	I _{COMP} = Compensation IDAC current
6	V _{DD}	N/A	This parameter is the device supply voltage.
7	Cs	N/A	This parameter is the sensor parasitic capacitance.
8	N/A	Modulator clock frequency	Modulator clock divider does not impact raw count. See the Modulator clock section for more details.

Table 3 Relationship between CAPSENSE[™] raw count and CAPSENSE[™] hardware parameters

3.2.6 Analog multiplexer (AMUX)

The sigma delta converter scans one sensor at a time. An analog multiplexer selects one of the GPIO cells and connects it to the input of the sigma delta converter, as Figure 35 shows. The AMUXBUS A and the GPIO cell switches (see SW3 in Figure 40) forms this analog multiplexer. AMUXBUS A connects to all GPIOs that support CAPSENSETM. See the corresponding Device datasheet for a list of port pins that support CAPSENSETM. AMUXBUS A also connects the integrating capacitor C_{MOD} to the sigma-delta converter circuit. AMUXBUS B is used for shielding and is kept at V_{REF} when shield is enabled.

3.2.7 CAPSENSE[™] CSD shielding

PSOC[™] 4 and PSOC[™] 6 MCU CAPSENSE[™] supports shield electrodes for liquid tolerance and proximity sensing. CAPSENSE[™] has a shielding circuit that drives the shield electrode with a replica of the sensor switching signal to nullify the potential difference between sensors and shield electrode. See Driven-shield signal and shield



electrode Driven-shield signal and shield and Effect of liquid droplets and liquid stream on a self-capacitance sensor for details on how this is useful for liquid tolerance.

In the sensing circuit, the sigma delta converter keeps the AMUXBUS A at V_{REF} (see Sigma-delta converter). The GPIO cells generate the sensor waveforms by switching the sensor between AMUXBUS A and a supply rail (either V_{DD} or ground, depending on the configuration). The shielding circuit works in a similar way; AMUXBUS B is always kept at V_{REF} . The GPIO cell switches the shield between AMUXBUS B and a supply rail (either V_{DDD} or ground, the same configuration as the sensor). This process generates a replica of the sensor switching waveform on the shield electrode.

For a large shield layer with high parasitic capacitance, an external capacitor (Csh tank capacitor) is used to enhance the drive capacity of the shield electrode driver.

3.3 CAPSENSE[™] CSX sensing method (third- and fourth- generation)

Figure 42 illustrates the CSX sensing circuit. The implementation uses the following hardware sub-blocks from CSD HW.

- An 8-bit IDAC and the sigma delta converter
- AMUXBUS A
- CAPSENSE[™] clock generator for Tx clock and modulator clock
- V_{REF} and port pins for Tx and Rx electrodes and external caps
- Two external capacitors (CINTA and CINTB) (see Table 39 for recommended value of these capacitors)

Note: PSOC[™] 4100 does not support the CSX sensing method.



Figure 42 CAPSENSE[™] CSX sensing method configuration

The CSX sensing method measures the mutual-capacitance between the Tx electrode and Rx electrode, as shown in Figure 42. The Tx electrode is excited by a digital waveform (Tx clock), which switches between V_{DDIO} (or V_{DDD} if V_{DDIO} is not available in the given part number) and ground. The Rx electrode is statically connected



to AMUXBUS A. The CSX method requires two external integration capacitors, C_{INTA} and C_{INTB} . The value of these capacitors is listed in Table 39.



Figure 43 CSX sensing waveforms

Figure 43 shows the voltage waveforms on the Tx electrode and C_{INTA} and C_{INTB} capacitors. The sampling – a process of producing a "sample" – is started by the firmware by initializing the voltage on both external capacitors to V_{REF} and performing a series of sub-conversions. A sub-conversion is a capacitance to count conversions performed within a Tx clock cycle. The sum of results of all sub-conversions in a sample is referred to as "raw count".

During a sub-conversion, both SW1 and SW2 switches are operated in phase with the Tx clock. On the rising edge of the Tx clock, SW1 is closed (SW2 is open during this time) and charge flows from the Tx electrode to the Rx electrode. This charge is integrated onto the C_{INTA} capacitor, which increases the voltage on C_{INTA} . The IDAC is configured in sink mode to discharge the C_{INTA} capacitor back to voltage V_{REF} . On the falling edge of the Tx clock, SW2 is closed (SW1 is open during this time) and the charge flows from the Rx electrode to the Tx electrode. This causes the voltage on C_{INTB} to go below V_{REF} . The IDAC is configured in source mode to bring the voltage on C_{INTB} back to V_{REF} .

The charge transferred between Tx and Rx electrodes in both the cycles is proportional to mutual-capacitance, $C_{\rm M}$, between the electrodes. The sigma delta converter controls IDAC for charging or discharging the external capacitors and also it measures the charging and discharging time in terms of modulator clock cycles for a sub-conversion. Multiple sub-conversions are performed during the CSX scanning and the result of each sub-conversion is accumulated to produce "raw count" for a sensor.

The modulator clock is used to measure the time taken to charge/discharge external capacitors within a Tx clock cycle. For this reason, modulator clock frequency must be always greater than Tx clock frequency; higher modulator clock frequency leads to better accuracy. For proper operation, the IDAC current should be set such that the C_{INTA} and C_{INTB} capacitors are charged/discharged within one Tx clock cycle. The CAPSENSETM



Component/middleware provides an option to automatically calibrate the IDAC. It is recommended to enable this option.

 $Rawcount_{Counter} = \frac{2 V_{TX} F_{TX} C_M \text{MaxCount}}{IDAC}$ $MaxCount = \frac{F_{Mod} N_{Sub}}{F_{TX}}$

Equation 14 Raw count relationship for mutual-capacitance sensing

Where,

IDAC = IDAC current

 C_{M} = Mutual-capacitance between Tx and Rx electrodes

 V_{TX} = Amplitude of the Tx signal

 F_{TX} = Tx clock frequency

 F_{Mod} = Modulator clock frequency

 N_{Sub} = Number of sub-conversions

When you place a finger on the CSX button, the mutual-capacitance between Rx and Tx electrodes decreases, which decreases the raw count. This decrease in raw count from the hardware is inverted by the CAPSENSE[™] Component to make it similar to the raw count change in CSD for a finger touch. The final resulting inverted raw count is given by Equation 15.

 $Rawcount_{Component} = MaxCount - Rawcount_{Counter}$

Equation 15 Formula to determine rawcount_{Component}

See CSX sensing method (third- and fourth-generation) for more details of CSX hardware parameters.

3.4 CAPSENSE[™] CSD-RM sensing method (fifth-generation and fifthgeneration low-power)

This section provides an overview of the CSD-RM architecture implemented in the fifth-generation CAPSENSE[™] device (known as multi sense converter (MSC)). The main features include ratiometric sensing, differential mode of operation without the need of reference voltage, use of capacitor DACs (CDAC) instead of current DACs (IDAC), which improves noise performance.







The fifth-generation low power (known as multi-sense low-power or MSCLP) technology has an internal clock removing the dependency on the system resource. Autonomous scanning is now enabled even without the CTRLMUX and DMA. All AMUXBUS CAPSENSE[™] pins support autonomous scanning.





Figure 45 CAPSENSE[™] CSD-RM (fifth-generation low-power)

3.4.1 GPIO cell capacitance to charge converter

Chapter 3.2.1 explains the GPIO cell configuration. In the fifth-generation architecture, the sensor is either interfaced to the AMUX (as before) or a new control MUX matrix, which supports autonomous scanning (limited number of pins supported). The GPIO cells are configured as switched-capacitance circuits that convert sensor capacitance into equivalent charge transfer. Figure 46 shows the GPIO cell structure.





Figure 46 GPIO cell structure (fifth-generation)

In the fifth-generation low-power architecture, the sensor is only interfaced to the AMUX, which now supports autonomous scanning (supports more number of pins than CTRLMUX).





Figure 47 GPIO cell structure (fifth-generation low-power)

Four non-overlapping, out-of-phase clocks of frequency *F*_{SW} control the switches (SW1, SW2, SW3 and SW4) as Figure 48 shows.





Figure 48 Voltage across sensor capacitance

3.4.2 Capacitor DACs (CDACs)

IDACs are replaced by CDACs in the fifth-generation CAPSENSE[™] architecture. It consists of two CDACs, a reference capacitor DAC, and a compensation capacitor DAC. In each sense clock period, the sensor capacitance, as mentioned in GPIO cell capacitance to charge converter, transfers charge to both C_{MOD} s in such a way that it affects the voltage balance between the C_{MOD} s. Both capacitor DACs are switched on to C_{MOD} multiple times during a sense clock period to restore the voltage balance between the C_{MOD} s. The number of cycles required by the reference capacitor DAC to balance the voltage is proportional to the self-capacitance of the sensors.

The fifth-generation low-power CAPSENSE[™] consists of Fine CDAC and Dither CDAC. The Fine Reference CDAC (Cfine) is a programmable CDAC, which is used to achieve finer resolution for the Reference CDAC. The CDAC dither is used to reduce Flat-spots (or dead zones).

3.4.3 CAPSENSE[™] clock generator

This block generates the sense clock F_{SW}, and the modulation clock F_{MOD}, from the high-frequency system resource clock (HFCLK) or peripheral clock (PERI) depending on the PSOC[™] device family.

3.4.3.1 Sense clock

CAPSENSE[™] clock generation is similar to that in the older generation as explained in Chapter 3.2.4.1.



3.4.3.2 Modulator clock

The modulation clock is used by the Ratiometric sensing technology. This clock determines the sensor scan time based on Equation 16 and Equation 17.

Equation 16	Senser seen time
Sensor scan time	= Hardware scan time + Sensor initialization time

Equation 16 Sensor scan time

Hardware scan time	_(Number of subconv ersions)
	Sense clock frequency

Equation 17 Hardware scan time

Where,

Number of subconversions = Total number or sub-conversions in single scan

Subconversion = Capacitance to count conversions performed within a sense clock cycle

Sensor initialization time = Time taken by the sensor to write to the internal registers and initiate a scan

3.4.4 Ratiometric sensing technology

It consists of a ratiometric converter and two CDACs, a reference capacitor DAC, and a compensation capacitor DAC. In each sense clock period, the sensor capacitance, as mentioned in GPIO cell capacitance to charge converter, transfers charge to both $C_{MOD}s$ in such a way that it affects the voltage balance between the $C_{MOD}s$. The ratiometric converter controls the reference CDAC by switching it ON or OFF corresponding to the small voltage variations across two $C_{MOD}s$ to maintain the C_{MOD} voltage at the same level. The number of cycles required by the reference capacitor DAC to balance the voltage between the $C_{MOD}s$ is proportional to the self-capacitance of the sensors.

The compensation capacitor is used to compensate excess mutual-capacitance from the sensor to increase the sensitivity. The number of times it is switched depends on the amount of charge the user application is trying to compensate (remove) from the sensor mutual capacitance.

The ratiometric converter can operate in either the single CDAC mode or dual CDAC mode.

- In the single CDAC mode, the reference CDAC is controlled by the ratiometric converter; the compensation CDAC is always OFF
- In the dual CDAC mode, the reference CDAC is controlled by the ratiometric converter; the compensation CDAC is always ON. The reference CDAC is capable of compensating up to 95%, results in the increased signal as explained in Conversion gain and CAPSENSE[™] signal

In the single CDAC mode, if C_{REF} is the value of the reference CDAC, the approximate raw count value is given by Equation 18.

Rawcount = Maxcount
$$\cdot \frac{C_S}{SnsClk_{Div} \cdot C_{ref}}$$

Equation 18 CSD-RM single CDAC raw count

In the dual CDAC mode, the compensation CDAC is always ON. If C_{COMP} is the compensation CDAC, the raw count equation is given by Equation 19.



3 PSOC[™] **4** and PSOC[™] **6** MCU CAPSENSE[™]

Rawcount = Maxcount
$$\cdot \frac{C_S - 2 \cdot \frac{SnsClk_{Div}}{CompClk_{Div}} \cdot C_{comp}}{SnsClk_{Div} \cdot C_{ref}}$$

Equation 19 CSD-RM dual CDAC raw count

Where,

MaxCount = N_{Sub} .SnsClk_{Div} N_{Sub} = Number of sub-conversions SnsClk_{Div} = Sense clock divider CompClk_{Div} = Compensation CDAC divider C_{s} = Sensor capacitance C_{ref} = Reference capacitance C_{comp} = Compensation capacitance With CIC2 enabled,

MaxCount = Decimation Rate² * K

Equation 20 Max raw count

Where,

Decimation rate =
$$\frac{\text{SnsClk}_{Div} * \text{N}_{sub}}{3}$$

Equation 21 Decimation rate

$K = \frac{\text{No. of CIC2 samples}}{\text{CIC2 Hardware divider}}$		
---	--	--

Equation 22

It is recommended to choose the number of CIC2 samples in such a way that "K" can be set to "1" to get the highest possible raw count.

Table 4CIC2 hardware divider look-up table

Number of CIC2 samples	Recommended CIC2 shift for divider	CIC2 hardware divider
2	1	2
3-4	2	4
5-8	3	8
9-16	4	16
17-32	5	32
33-64	6	64
65-128	7	128
129-256	8	256



Selecting the auto option for CIC2 shift in the CAPSENSE[™] configurator selects hardware shift (hardware divider) as per Table 4.

The decimation rate is the down sampling rate, and when it reaches its maximum of 255, the following condition needs to be ensured to avoid CIC2 accumulator (25-bit) overflow.

 $CIC2_Acc_Size_{Max} \ge TRUNC\left(\frac{N_{sub} * Sns_Clk_Div}{Decimation} - 1\right) * Decimation^2$

Equation 23 CIC2 Accumulator overflow condition

Where,

CIC2_Acc_Size_{Max} - Maximum CIC2 accumulator size

The maximum CIC2 accumulator size for a direct clock is $(2^{25} - 1)$, and for a PRS clock is $(2^{25} - 1)/2$.

As per Equation 18, the output raw count is proportional to the ratio of sensor capacitance to the reference capacitance, and hence the name Ratiometric Sensing.

Noise improvement is one of the main advantages of the fifth-generation over previous generations of CAPSENSETM technology. The dominant noise sources in the fourth-generation are current (I_{MOD}) , reference voltage (V_{REF}) , and clock jitter (F_{SW}) (see Equation 12). These noise sources have been removed in the fifth-generation (see Equation 19). The IDAC has been replaced with CDAC. Since the system is now fully differential, it does not need V_{REF} . The CAPSENSETM architecture is no longer affected by jitter as the scan result is now based on the edges of the clock rather than the duration of the clock. Because of differential architecture, the drift of raw count for a given power-supply ripple is significantly less in the fifth-gen and fifth-gen low-power CAPSENSETM. The user may not need any LDO to design with fifth-gen and fifth-gen low-power CAPSENSETM technology if power supply ripple is within the limits mentioned in the datasheet.

3.4.5 Analog multiplexer (AMUX) and control matrix (CTRLMUX)

Another feature introduced in the Fifth-Generation is the control matrix (CTRLMUX) as shown in Figure 44. The CTRLMUX enables autonomous scanning and provides immunity to on-chip IO noise. The CTRLMUX allows the CAPSENSE[™] IP to directly handle the sensor inputs⁴⁾ (in addition to the traditional GPIO mode), and hence supports autonomous scanning of the sensors without the CPU.

For fifth-generation low-power, as shown in the image Figure 45, the CTRLMUX has been removed. The AMUXBUS is enabled to handle autonomous scanning on all the CAPSENSE[™] pins.

3.4.6 CAPSENSE[™] CSDRM shielding

PSOC[™] 4 CAPSENSE[™] supports shield electrodes for liquid tolerance and proximity sensing. The purpose of the shielding is to remove the parasitic capacitance between the sensor and shield electrodes. See Driven-shield signal and shield electrode and Effect of liquid droplets and liquid stream on a self-capacitance sensor for details on how this is useful for liquid tolerance. The fifth-generation CAPSENSE[™] architecture supports two shield modes – active and passive shielding.

3.4.6.1 Active shielding

In active shielding mode, the shield circuit drives the shield electrode with a replica of the sensor signal using a buffer as shown in Figure 49. This nullifies the potential difference between sensors and the shield electrode.

⁴ Supports limited number of inputs. Refer to the device datasheet for more details.





3.4.6.2 Passive shielding

In the passive shielding mode, there is no buffer used; instead, the shield is switched between V_{DDA} and GND as shown in Figure 50. The switching is controlled in such a way that the net charge between the sensor and the shield is nullified every two sense clocks.



Figure 50 Passive shield signal

Table 5 provides the comparison of the active shielding features versus the passive shielding features.

Table 5Active vs passive shielding

Feature	Active shielding	Passive shielding	Effect
Performance	Higher	Lower	Active shielding is preferred for high- performance applications.
Power impact	Higher	Lower	Passive shielding is preferred for low- power applications.



3.5 CAPSENSE[™] CSX-RM sensing method (fifth-generation and fifthgeneration low-power)

Figure 51 illustrates the CSX-RM sensing circuit. The implementation uses the following hardware subblocks:

- Two 8-bit capacitor DACs and ratiometric converter
- AMUXBUS and CTRLMUX
- CAPSENSE[™] clock generator for Tx clock and modulator clock
- Port pins for Tx and Rx electrodes and external caps
- Two external capacitors (C_{MOD1} and C_{MOD2})





CAPSENSE[™] CSX-RM sensing method configuration (fifth-generation)





Figure 52 CAPSENSE[™] CSX-RM sensing method configuration (fifth-generation low-power)

The CSX-RM sensing method measures the mutual-capacitance between the Tx electrode and Rx electrode, as shown in Figure 51. The Tx electrode is activated by a digital waveform (Tx clock), which switches between V_{DDA} and ground. The Rx electrode is statically connected to AMUXBUS A or CTRLMUX, as applicable. The CSX-RM method requires two external integration capacitors, C_{MOD1} and C_{MOD2} .

The sampling – a process of producing a "sample" – is started by the firmware by initializing the voltage on both external capacitors (C_{MOD}) to $V_{DDA}/2$ and performing a series of sub-conversions. A sub-conversion is a capacitance to count conversions performed within a Tx clock cycle. The sum of results of all sub-conversions in a sample is referred to as "raw count".

On the rising and falling edge of the Tx clock, charge flows from the Tx electrode to the Rx electrode. In such a way that it unbalances the voltage between the external C_{MOD} capacitors. Both capacitor DACs (reference and compensation capacitor DACs) are switched onto C_{MOD} multiple times during a sense clock period to balance the C_{MOD} 's back to their original voltage. Number of cycles required by the reference capacitor DAC to balance is proportional to the mutual-capacitance, C_m , between the electrodes.

The number of times the reference capacitor is switched with respect to the modulator clock is denoted by the Tx clock divider value according to Equation 24.

$$TxClk_{Div} = \frac{F_{Mod}}{F_{Tx}}$$

Equation 24 Tx clock divider

Where, $TxClk_{Div} = Tx clock divider$ $F_{Mod} = Modulator frequency$

infineon

3 PSOC[™] 4 and PSOC[™] 6 MCU CAPSENSE[™]

F_{Tx} = Tx clock frequency

The compensation capacitor is used to compensate excess mutual-capacitance from the sensor to increase the sensitivity. The number of times it is switched depends on the amount of charge the user application is trying to compensate (remove) from the sensor mutual-capacitance. The number of times the compensation capacitor is switched with respect to the modulator clock is denoted by the value of the compensation CDAC divider according to the Equation 21. The CDAC compensation clock divider must be less than or equal to the Tx clock divider.

 $CompClk_{Div} = \frac{F_{MOD}}{F_{comp}}$

Equation 25 Compensation CDAC divider

Where,

*CompClk*_{Div} = Compensation CDAC divider

FM MOD = Modulator frequency

 $F_{\rm comp}$ = Compensation CDAC clock frequency

3.5.1 Ratiometric sensing technology

The ratiometric converter gives an equivalent raw count which is proportional to the sensor mutualcapacitance after each scan. The ratiometric converter can operate in either single CDAC mode or dual CDAC mode.

- In the single CDAC mode, the reference CDAC is controlled by the ratiometric converter; the compensation CDAC is always OFF
- In the dual CDAC mode, the reference CDAC is controlled by the ratiometric converter; the compensation CDAC is always ON. Compensation CDAC is capable of compensating up to 95%, results in increased signal as explained in Conversion gain and CAPSENSE[™] signal

In the single CDAC mode, if C_{ref} is the value of the reference CDAC, the approximate value of raw count is given by Equation 26.

Rawcount = Maxcount
$$\cdot \frac{C_M}{TxClk_{Div} \cdot \left(\frac{C_{ref}}{2}\right)}$$

Equation 26 CSX-RM single CDAC raw count

In the dual CDAC mode, the compensation CDAC is always ON. If C_{comp} is the compensation CDAC, the equation for the raw count is given by Equation 27.

$$\text{Rawcount} = \text{Maxcount} \cdot \frac{C_M - \frac{TxClk_{Div}}{CompClk_{Div}} \cdot C_{comp}}{TxClk_{Div} \cdot \left(\frac{C_{ref}}{2}\right)}$$

Equation 27 CSX-RM dual CDAC raw count

Where,

MaxCount = N_{Sub}.TxClk_{Div} N_{Sub} = Number of sub-conversions SnsClk_{Div} = Sense clock divider CompClk_{Div} = Compensation CDAC divider

Application note



$C_{\rm S}$ = Sensor capacitance
C _{ref} = Reference capacitance
$C_{\rm comp}$ = Compensation capacitance
With CIC2 enabled,

MaxCount = Decimation Rate^{2 * K}

Equation 28 Max raw count

Where,

Decimation rate	_SnsClk _{Div} * N _{sub}
Decimation fate	3

Equation 29 Decimation rate

<i>v</i> _	No. of CIC2 samples
к –	CIC2 Hardware divider

Equation 30

It is recommended to choose the number of CIC2 samples in such a way that "K" can be set to "1" to get the highest possible raw count.

Table 6CIC2 hardware divider look-up table

Number of CIC2 samples	Recommended CIC2 shift for divider	CIC2 hardware divider
2	1	2
3-4	2	4
5-8	3	8
9-16	4	16
17-32	5	32
33-64	6	64
65-128	7	128
129-256	8	256

Selecting the auto option for CIC2 shift in the CAPSENSE[™] configurator selects hardware shift (hardware divider) as per Table 4

The decimation rate is the down sampling rate, and when it reaches its maximum of 255, the following condition needs to be ensured to avoid CIC2 accumulator (25-bit) overflow.

$$CIC2_Acc_Size_{Max} \ge TRUNC\left(\frac{N_{sub} * Sns_Clk_Div}{Decimation} - 1\right) * Decimation^{2}$$

Equation 31 CIC2 Accumulator overflow condition

Where,

 $CIC2_Acc_Size_{Max} - Maximum CIC2 \ accumulator \ size$

The maximum CIC2 accumulator size for a direct clock is $(2^{25} - 1)$, and for a PRS clock is $(2^{25} - 1)/2$.



According to Equation 27, the output raw count is proportional to the ratio of the mutual capacitance of the sensor to the reference capacitance, hence the name ratiometric sensing.

3.6 CAPSENSE[™] multi-phase scanning method

CAPSENSE[™] multi-phase scanning refers to a differential measurement of a target sensor's capacitance relative to other sensors, which is carried out by scanning multiple sensors at once. Typical applications include keypad matrix and touchscreens. This is useful for countering certain types of common-mode noise, like voltage ripples in the VDDA supply, which can turn into finger-injected noise in the system. Refer to Noise in CAPSENSE[™] system for more details.

3.6.1 MPSC-D (Multi-phase self-cap differential)

MPSC-D is a technique for differential measurement of the target sensor capacitance. This is carried out by scanning multiple electrodes simultaneously.

In regular CSD scanning, there are four phases (ph0-ph3), and one electrode is scanned at a time in these phases. MPSC-D also uses four phases of scanning, but in contrast to CSD, multiple electrodes are scanned simultaneously instead of just one. The number of electrodes used for MPSC scanning is called the MPSC-D order and is referred to as 'N_{MPSC-D}' or Multi-phase self order. The minimum supported value of N_{MPSC-D} is 5. In other words MPSC-D is supported on the following:

- Matrix buttons with at least 5 sensors
- Touchpad with at least 5 row and 5 columns
- Slider with at least 5 segments

Compared to a regular CSD scan, this technique allows for a decrease in scanning time with the same signal-tonoise ratio (SNR) or an increase in SNR if the scanning time remains the same. In the best-case scenario, the SNR increases by $\sqrt{N_{MPSC-D}}$ times if the scanning time remains constant.

3.6.2 Advantages

The MPSC-D technique offers several advantages over the regular CSD techniques:

Improved SNR: MPSC-D technique provides a theoretical improvement in SNR by multiple of $\sqrt{N_{MPSC-D}}$, where N_{MPSC-D} is Multi-phase self-order.

Noise Reduction: The MPSC-D technique described above helps in suppressing common mode noise, for example, white noise, LCD noise.

Shield Not Required: There is no need to use a shield in MPSC-D.

3.6.3 Limitations of MPSC-D

Increased power consumption: Enabling MPSC-D mode leads to higher power consumption because it involves simultaneously driving multiple electrodes instead of only one.

Additional computing: Multi-phase scanning techniques employ convolution and deconvolution methods that requires additional computing.

Note: Covering more than 50% of the sensors with a conductive object, may cause improper functioning of the MPSC-D widget.



3.6.4 Implementation of MPSC-D

The MPSC-D feature can be used with any CSD widget that has more than 5 sensing elements; MPSC is not supported for configurations with less than 5 electrodes. For example, to use MPSC-D, a CSD slider widget is added, as shown in the Figure 53, with a number of sensors greater than or equal to five.

CAPSENSE [™] Configurator					- 0
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Basic Advanced Scan Configuration					
			CSD tuning mode:	Manual tuning	
↑ Move up ↓ Move down ★ Delete	•		Low Power tuning mode:	Manual tuning	
Type Name		Sensing Mode	Sensing Element(s)		Finger Capacitar
DinearSlider0		CSD RM	5 Segments		N/A
+					

Figure 53 Adding CSD Slider in CAPSENSE[™] configurator

Each CSD widget with more than 5 sensing elements has a parameter called MPSC self-order. To access this parameter, open the Extra Parameters section in the Widget Details tab of the Advanced section.



Edit View Help			
eneral CSD Settings CSX Settings ISX Settings Widget	Details		
LowPower0	Name	Value	
LowPower0_Sns0	 Widget general parameters 		
LinearSlider0	Diplexing	□ false	
LinearSlider0_Sns0	Maximum position	100	
LinearSlider0_Sns1	Enable multi-frequency scan	false	
LinearSlider0_Sns2	 Widget hardware parameters 		
LinearSlider0_Sns3	Sense clock divider	24	
LinearSlider0_Sns4	Clock source	Direct	
	LFSR range		
	LFSR dither limit (%)	10	
	Clock source auto selection mode	Strong	
	Number of sub-conversions	16	
	Decimation rate mode	Auto	
	Decimation rate	Auto	
	CIC2 accumulator shift	Auto	
	MAX raw count	0	
	Row MAX raw count	0	
	Enable coarse initialization bypass	☐ false	
	Multi-phase self order	5	
	 Capacitive DAC parameters 		
	Reference CDAC mode	Auto	
	Reference CDAC value	Auto-calibrated	
	Reference CDAC boost	Disable	
	Fine CDAC mode	Auto	
	Fine CDAC value	Auto-calibrated	
	Compensation CDAC mode	Auto	
	Compensation CDAC divider mode		
	Compensation CDAC divider	Auto-calibrated	
		'	

Figure 54 Enabling MPSC-D in configuration

The number of electrodes involved during scanning defines the multi-phase selforder. The default value of multi-phase selforder is 1, which means MPSC-D is disabled. The multi-phase self-order can be set equal to the number of sensing elements. For example, if there are 5 sensing elements, the multi-phase self-order will be 5.

With multi-phase self-order set to the number of sensing elements of widget, the MPSC-D will be enabled by the system.

The table below presents a comparative analysis of power consumption, computation time, and Signal-to-Noise Ratio (SNR) for the CY8CPROTO-040T kit configured with a slider widget of 5 sensors with MPSC enabled and disabled.

Configuration used for the measurement:

- Source clock = IMO 46 MHz
- FMOD = 46 MHz
- Tx Clock divider = 24
- NSUB = 16

Table 7 Effect of MPSC on System Performance

Parameters	With MPSC	Without MPSC
SNR	67.49	37.76
Power consumption (μA)	151	120
Computation time (µs)	94	53



3.7 Advantages of fifth generation and fifth generation low-power

See AN234231 - Achieving lowest-power capacitive sensing with PSOC[™] 4000T for detailed information on autonomous scanning and the CIC2 filter.

3.7.1 Autonomous scanning

In previous generation CAPSENSE[™] technology, after each scan, CPU is interrupted to configure the next sensor. Autonomous scanning mode in the fifth-generation CAPSENSE[™] technology avoids the CPU intervention for scanning every subsequent sensor. This significantly reduces the CPU bandwidth required for scanning widgets with large number of sensors. Autonomous scanning requires features such as CTRLMUX and DMA. Since the number of pins supported with CTRLMUX is limited, the number of pins supporting autonomous scanning is also limited. See the Configuring autonomous scan section for more details.

In fifth-generation low-power CAPSENSE[™], autonomous scanning is supported inherently, and requires neither CPU intervention nor CTRLMUX and DMA. All CAPSENSE[™] pins support this scanning mode, via the AMUXBUS, compared to the limited number of pins, which were supported by the CTRLMUX in the fifth-generation CAPSENSE[™] technology.

3.7.2 Usage of multiple channels

The PSOC[™] 4100S Max device supports two fifth-generation CAPSENSE[™] blocks – MSC0 and MSC1. Each block has the same functionality and performance as explained in the CAPSENSE[™] CSD-RM sensing method (fifth-generation and fifth-generation low-power) and CAPSENSE[™] CSX-RM sensing method (fifth-generation and fifth-generation low-power) sections. Each instance can be considered as a channel and multiple instances imply multiple channels. Multi-channel behavior can be supported by multiple instances in a single chip and/or having multiple chips. The operation of the channels is synchronized and operate in lockstep when scanning the sensors hooked in to the channels. Lockstep guarantees clock synchronization and avoids any cross-channel noise due to un-synchronized sense clocks.

See Multi-channel scanning section for more details.

3.7.3 CIC2

The multi-sense low-power (MSCLP) CAPSENSE[™] device has a built-in cascaded integrator-comb 2 (CIC2) digital filter, which improves the effective resolution, and thereby the SNR, for a given scan period. The CIC2 filter is a 2nd order digital low-pass (decimation) filter used to filter delta-sigma converters. Figure 55 shows the representation of a CIC2 filter made up of a cascade of two integrators and two comb filters.

The CIC2 filter receives the output of the MSCLP analog front end, which is a delta-sigma converter. This converter generates a bitstream of 1s and 0s representing its input, and moves the quantization noise to high frequencies. This high-frequency noise is filtered out by a digital low-pass filter; the downsampler converts the input to a single digital word representing the measured signal. This combination of a low-pass filter (A0, A1) and a downsampler (D0, D1) is known as a decimator (CIC2 filter) as shown in Figure 55.





Figure 55 CIC2 filter block diagram

The raw count gets accumulated at the end of each valid sample.

A minimum of two valid CIC2 samples are required for proper CIC2 filtering. Considering two valid samples, calculate the decimation (down sampling) rate using the following equation:

5)
Decimation Rate(N) =
$$\frac{\text{SnsClk}_{Div} * N_{sub}}{3}$$

Equation 32 Decimation rate

Configure the CIC2 Shift parameter as "Auto" in the CAPSENSE[™] configurator. This automatically selects the appropriate hardware shift (hardware divider).

Calculate the max raw count, when CIC2 is enabled, using the following equation:

 $Rawcount_{max}$ = Decimation Rate²

Equation 33 Max rawcount equation

 ⁵ When the decimation rate reaches its maximum of 255, the user needs to ensure that the below conditions are met to avoid the CIC2 accumulator (25-bit) overflow.
 For Direct clock: (2²⁵-1) >= TRUNC((Nsub*Sns_Clk_Div)/Decimation-1)*Decimation²
 For PRS clock: (2²⁵-1)/2 >= TRUNC((Nsub*Sns_Clk_Div)/Decimation-1)*Decimation²



4 CAPSENSE[™] design and development tools

4 CAPSENSE[™] design and development tools

This section introduces the available software tools, such as PSOC[™] Creator and ModusToolbox[™], to develop your CAPSENSE[™] application. For more details, see the user manual of the respective IDE. Table 8 shows the supported devices and the CAPSENSE[™] component/middleware version in PSOC[™] Creator and ModusToolbox[™].

Table 8Tools and supported devices

Devices	Software tool	CAPSENSE [™] library
PSOC [™] 4000S, PSOC [™] 4100S, PSOC [™] 4100S Plus, PSOC [™] 4100S Plus 256K, PSOC [™] 4500S	ModusToolbox™, PSOC™ Creator	CAPSENSE [™] middleware, CAPSENSE [™] component
PSOC [™] 4000T, PSOC [™] 4100T Plus, PSOC [™] 4100S Max, All PSOC [™] 6 devices	ModusToolbox™	CAPSENSE [™] middleware
All other PSOC [™] 4 devices	PSOC [™] Creator	CAPSENSE [™] component

4.1 PSOC[™] Creator

PSOC[™] Creator is a state-of-the-art, easy-to-use IDE. It offers a unique combination of hardware configuration and software development based on classical schematic entry. You can develop applications in a drag-and-drop design environment using a library of Components. For details, see the PSOC[™] Creator home page.

4.1.1 CAPSENSE[™] component

PSOC[™] Creator provides a CAPSENSE[™] component, which is used to create a capacitive touch system in PSOC[™] by simply configuring this Component. The CAPSENSE[™] component also provides an application programming interface (API) to simplify firmware development. Some PSOC[™] 4 Bluetooth[°] LE and PSOC[™] 6 MCU devices also support a CAPSENSE[™] Gesture Component (see the corresponding Device datasheet to see if your device supports this Component).




Figure 56 PSOC[™] Creator component placement

Each CAPSENSE[™] component has an associated datasheet that explains details about the Component. To open the Component datasheet, right-click the Component and select **Open Datasheet**.

The CAPSENSE[™] component also has a Tuner GUI, called the Tuner GUI, to help with the tuning process.

4.1.2 CapSense_ADC component

The CapSense_ADC⁶⁾ component is only applicable for the PSOC[™] 4S-Series, PSOC[™] 4100S Plus, PSOC[™] 4100PS, and PSOC[™] 6 MCU devices. This component should be used when both CAPSENSE[™] and ADC operations are required. This component allows using the CAPSENSE[™] block for ADC operation and touch functionality in a time-multiplexed manner.

4.1.3 Tuner GUI

Tuner helper is included with the CAPSENSE[™] component and assists in tuning CAPSENSE[™] parameters and monitoring sensor data such as raw count, baseline, and difference count. Refer the Component datasheet/ middleware document for the detailed procedure on how to use Tuner GUI.

4.1.4 Example projects

You can use the CAPSENSE[™] example projects provided in PSOC[™] Creator to learn schematic entry and firmware development. To find a CAPSENSE[™] example project, go to the PSOC[™] Creator home page, click **Find Code**

⁶ CapSense_ADC is not supported in devices with fifth-generation CAPSENSE[™] block.



Example ..., and select the appropriate architecture, as Figure 57 shows. You can also filter for a project by writing partial or complete project name in the **Filter by** field.





4.2 ModusToolbox™

ModusToolbox[™] software suite is used for the development of PSOC[™] 6 and PSOC[™] 4⁷ based CAPSENSE[™] applications. You can download ModusToolbox[™] from here. Before you start working with this software, it is recommended that you go through the Quick start guide and user guide. ModusToolbox[™] software trainings can be found here. If you have ModusToolbox[™] IDE installed in your system, you can create a CAPSENSE[™] application for the devices supported in ModusToolbox[™].

4.2.1 CAPSENSE[™] middleware

ModusToolbox[™] provides a CAPSENSE[™] middleware, which can be used to create a capacitive touch system in PSOC[™] by simply configuring parameters in the CAPSENSE[™] configuration tool. The middleware also provides an application programming interface (APIs) to simplify firmware development. See the CAPSENSE[™] middleware library for more details.

4.2.2 CAPSENSE[™] configurator

The CAPSENSE[™] configurator tool in ModusToolbox[™] is similar to that in PSOC[™] Creator, which is used to configure the CAPSENSE[™] hardware and software parameters. For more details on configuring CAPSENSE[™] in ModusToolbox[™], see the ModusToolbox[™] CAPSENSE[™] configurator guide and CAPSENSE[™] middleware library. Figure 58 shows how to open the CAPSENSE[™] configuration tool in ModusToolbox[™]. Alternatively, it can also be

⁷ See Table 8 for supported PSOC[™] 4 devices in ModusToolbox[™].



opened from the **Quick panel** in the ModusToolbox[™]. For simplicity of documentation, this design guide shows selecting the CAPSENSE[™] parameter in PSOC[™] Creator CAPSENSE[™] component.

mtw - Hello_World/main.c - Eclipse IDE for ModusToolbo	x [™] 32
File Edit Source Refactor Navigate Search Project	Run Window Help
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 TARGET_APP_CY8CKIT-041S-MAX Config GeneratedSource design.modus.lock design.modus.lock deps doss TOOLCHAIN_ARM TOOLCHAIN_ARM 	 File Name: main.c Description: This is the source code for the PSoC 4 MCU Hello World Example Optimize the source code of the PSoC 4 MCU Hello World Example Copyright 2020-2023, Cypress Semiconductor Corporation (an Infineon company) or an affiliate of Cypress Semiconductor Corporation (an Infineon company) or an affiliate of Cypress Semiconductor Corporation (an Infineon company) or This software, including source code, documentation and related
> 🤛 TOOLCHAIN_IAR > 🖻 cybsp_doc.h > 🗟 cybsp_hw_config.h	<pre>* materials ("Software") is owned by Cypress Semiconductor Corporation * or one of its affiliates ("Cypress") and is protected by and subject to * worldwide netter protection (United States and foreign).</pre>
> 🖻 cybsp_types.h	Device Configurator – 🗆 🗙
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Quick Panel In Variables & Expressions Seakpoints	Peripherals Pins Analog-Routing System Peripheral-Clocks DMA Enter filter text
Eclipse IDE for	Resource Name(s) Personality ~ Y Peripheral Documentation
ModusToolbox™	Serial Communication Block (SCB) 0 scb_0 ⑦ CapSense Middleware Open CapSense Middleware Documentation
	Serial Communication Block (SCB) 1 scb_1 ⑦ Configuration Help Open MSC Driver Documentation
- Start	Serial Communication Block (SCB) 2 CYBSP_UART UART-1.0 V External Tools
New Application	Serial Communication Block (SCB) 3 scb_3 CapSense Configurator Launch CapSense Configurator
Import Existing Application In-Place	Serial Communication Block (SCB) 4 scb_4
Search Online for Code Examples	V Digital
Search Online for Libraries and BSPs	> Timer, Counter, and PWM (TCPWM) 0
P Training Material	V System
Refresh Quick Panel	✓ ✓ CASSEnse CASSEnse CapSense 1.0
Refresti Quick Panel	MSC 0 CYBSP_MSC0 MSC-1.1
 Hello_World (APP_CY8CKIT-041S-MAX) 	MSC-1 CYBSP_MSC1 MSC-1.1
Suild Application	CD Direct Drive 0 Icd_0_drive_0
Clean Application	Watchdog Counters (WDC) wcc_0_wdc_0
	Watchelon Timer (WDT) sres 0 with 0
	Capserise (CrbsP_capserise) - Parameters Code Preview
	Ready

Figure 58 CAPSENSE[™] configurator tool in ModusToolbox[™]

4.2.3 CSDADC middleware

This CSDADC middleware⁸⁾ should be used when both the CAPSENSE[™] and ADC operations are required. This middleware allows using the CAPSENSE[™] hardware block for ADC operation and touch functionality in a timemultiplexed manner. It could be used for all three sensing modes that is, CSD, ADC, and CSX. See the CSDADC middleware library documentation for more details.

4.2.4 CSDIDAC middleware

The CSDIDAC middleware allows you to use the CAPSENSE[™] IDAC in a standalone mode. You can use this middleware if you are not using CAPSENSE[™] middleware or if you are using only one IDAC for CAPSENSE[™]. See the CSDADC middleware library documentation.

4.2.5 CAPSENSE[™] tuner

ModusToolbox[™] also supports a GUI tool that can be used for tuning CAPSENSE[™] parameters. This tool can be opened from the Device configurator by selecting Launch CAPSENSE[™] tuner as shown in Figure 58. See the CAPSENSE[™] tuner guide documentation.

4.2.6 Example projects

To quickly start the CAPSENSE[™] system design, start with the example projects provided in ModusToolbox[™]. You can find a CAPSENSE[™] example project by navigating to **File > New > ModusToolbox Application**. Choose the

⁸ CapSense_ADC is not supported in devices with the fifth-generation CAPSENSE[™] block.



appropriate Board Support Package with a device. Figure 59 shows creating a CAPSENSE[™] CSD Button example starter code in ModusToolbox[™] from the list of available code examples.

Project Creator ettings <u>H</u> elp					- 0
Application(s) Root Path:	C:/mtw				Browse
Target IDE:	Eclipse IDE for ModusToolbo	X TM			~
Enter filter text				Browse for Application	This code example demonstrates how to manually
CAPSENSE liqu	juid tolerant proximity uid-tolerant hybrid scan ulti-frequency Scan beline scan and process primity caetures	New Application Name	New BSP Name		tune a self capacitance-based button widget in PSoC [™] 4 devices using the Multi Sense Converter (MSO CSD-RM sensing technique and CAPSENSE [™] Tuner GUI. For more details, see the <u>README on GitHub</u> .
MSC CAPSENS MSC CAPSENS MSC CAPSENS MSC CAPSENS MSC CAPSENS	SE CSD Button Tuning SE CSD Slider Tuning SE CSD Touchpad Tuning SE CSX Button Tuning SE Liquid tolerant touchpad uch CSX Touchpad Tuning INSE low-power	MSC_CAPSENSE_CSD	APP_CY8CKIT-041S-MAX		
ummary: SP: CY8CKIT-041S-MAX emplate Application(s): MS pplication(s) Root Path: C; ress "Create" to create the		ning			
					< <u>B</u> ack <u>Create</u> Close

Figure 59 Creating CAPSENSE[™] CSD Button example project in ModusToolbox[™]

4.3 Hardware kits

Table 9 lists the development kits that support evaluation of PSOC[™] 4 and PSOC[™] 6 CAPSENSE[™].

Table 9PSOC[™] 4 and PSOC[™] 6 CAPSENSE[™] development kits

Development kit	Supported CAPSENSE [™] features
PSOC [™] 4000 pioneer kit (CY8CKIT-040)	A 5x6 CAPSENSE [™] touchpad and a wire proximity sensor
PSOC [™] 4 S-series pioneer kit (CY8CKIT-041)	Two self- or mutual-capacitive sensing buttons A 7×7 self- or mutual-capacitive sensing touchpad
PSOC [™] 4 S-series prototyping kit (CY8CKIT-145)	Three self- or mutual-capacitive sensing buttons A five-segment self- or mutual-capacitive sensing linear slider
PSOC [™] 4100S Plus prototyping kit (CY8CKIT-149)	Three self- or mutual-capacitive sensing buttons A six-segment self- or mutual-capacitive sensing linear slider

(table continues...)



Table 9 (continued) PSOC[™] 4 and PSOC[™] 6 CAPSENSE[™] development kits **Development kit** Supported CAPSENSE[™] features PSOC[™] 4100S Max pioneer kit (CY8CKIT041S-Max) Two self- or mutual-capacitive sensing buttons An eight-segment self- or mutual-capacitive sensing linear slider A 10x16 self or mutual-capacitive sensing touchpad A proximity sensor loop PSOC[™] 4000T kit (CY8CKIT-040T) One CAPSENSE[™] button A 4x5 self- or mutual-capacitive sensing touchpad A proximity sensor loop PSOC[™] 4000T prototyping kit (CY8CPROTO-040T) One self-capacitive sensing button One mutual-capacitive sensing button A proximity sensor loop A five-segment self- or mutual-capacitive sensing linear slider PSOC[™] 4100T Plus prototyping kit One self-capacitive sensing button (CY8CPROTO-041TP) One mutual-capacitive sensing button A proximity sensor loop A 4x5 self- or mutual-capacitive sensing touchpad PSOC[™] 4 pioneer kit (CY8CKIT042) A five-segment linear slider PSOC[™] 4 Bluetooth[®] LE pioneer Kit (CY8CKIT-042-A five-segment linear slider and a wire proximity sensor BLE) PSOC[™] 4200-M pioneer kit (CY8CKIT-044) A five-element gesture detection and two proximity wire sensors PSOC[™] 4200-L pioneer kit (CY8CKIT-046) A five-element gesture detection, two proximity wire sensors, and an eight-element radial slider No onboard CAPSENSE[™] sensors. The kit can be used to PSOC[™] 4100PS prototyping kit (CY8CKIT-147) connect external sensors to any I/O pin. CAPSENSE[™] proximity shield A four-element gesture detection and one proximity loop sensor (CY8CKIT-024) A two-element flexible PCB and 12-element flexible PCB CAPSENSE[™] liquid level sensing shield (CY8CKIT-022) PSOC[™] 4 processor module (CY8CKIT038), with A five-segment linear slider and two buttons PSOC[™] development kit (CY8CKIT001) A 10-segment slider, five buttons and a 4 x 4 matrix button CAPSENSE[™] expansion board kit with LED indication. (CY8CKIT-031), to be used with CY8CKIT038 and **CY8CKIT-001** CAPSENSE[™] performance tuning in CY8CKIT-038 MiniProg3 program and debug kit (CY8CKIT-002)

(table continues...)



Table 9(continued) PSOC[™] 4 and PSOC[™] 6 CAPSENSE[™] development kits

Development kit	Supported CAPSENSE™ featuresA 5-segment CAPSENSE™ slider, two CAPSENSE™ buttons, one CAPSENSE™ proximity sensing header, a proximity sensor.	
PSOC [™] 6 Wi-Fi BT pioneer kit (CY8CKIT-062-WiFi-BT pioneer kit) and PSOC [™] 6 Bluetooth [®] LE pioneer kit (CY8CKIT062-BLE pioneer kit)		
PSOC [™] 6 Wi-Fi BT prototyping kit (CY8CPROTO-063-4343W)	A 5-segment CAPSENSE™ slider and two mutual-cap CAPSENSE™ buttons	



5 CAPSENSE[™] performance tuning

After you have completed the sensor layout (see PCB layout guidelines), the next step is to implement the firmware and tune the CAPSENSE[™] parameters for the sensor to achieve optimum performance. The CAPSENSE[™] sensing method is a combination of hardware and firmware techniques. Therefore, it has several hardware and firmware parameters required for proper operation. These parameters should be tuned to optimum values for reliable touch detection and fast response. Most of the capacitive touch solutions in the market must be manually tuned. A unique feature called SmartSense (also known as Auto-tuning) is available for PSOC[™] 4 and PSOC[™] 6 CAPSENSE[™]. SmartSense is a firmware algorithm that automatically sets all parameters to optimum values.

5.1 Selecting between SmartSense and manual tuning

SmartSense auto-tuning reduces design cycle time and provides stable performance across PCB variations, but requires additional RAM and CPU resources, as indicated in the Component datasheet/middleware document or ModusToolbox[™] CAPSENSE[™] configurator guide, to allow runtime tuning of CAPSENSE[™] parameters. SmartSense is recommended mainly for conventional CAPSENSE[™] applications involving simple button and slider widgets, and is currently supported only for Self-capacitance sensing and not Mutual-capacitance sensing.

On the other hand, manual tuning requires effort to tune optimum CAPSENSE[™] parameters, but allows strict control over characteristics of capacitive sensing system, such as response time and power consumption. It also allows use of CAPSENSE[™] beyond the conventional button and slider applications such as proximity and liquid-level-sensing.

SmartSense is the recommended tuning method for all the conventional CAPSENSE[™] applications. You should use SmartSense auto-tuning if your design meets the following requirements:

- The design is for conventional user-interface application like buttons, sliders, and touchpad
- The parasitic capacitance (C_P) of the sensors is within SmartSense-supported range as mentioned in the "SmartSense operating conditions" section in Component datasheet/middleware document or ModusToolbox[™] CAPSENSE[™] configurator guide
- The sensor scan time chosen by SmartSense meets the response time/power requirements of the end system
- SmartSense auto-tuning meets the RAM/flash requirements of the design

For all other applications, use Manual tuning. In such cases, you can also use SmartSense as an initial step to find the optimum hardware parameters such as Sense Clock frequency, and then change the tuning mode to manual tuning for further tuning of the CAPSENSE[™] parameters. See Using SmartSense to determine hardware parameters.

Note: Manual tuning requires I^2C or UART communication with a host PC.

5.2 SmartSense

5.2.1 Overview

The CAPSENSE[™] algorithm is a combination of hardware and firmware blocks inside PSOC[™]. Therefore, it has several hardware and firmware parameters required for proper operation. These parameters need to be tuned to optimum values for reliable touch detection and fast response.

SmartSense is a CAPSENSE[™] tuning method that automatically sets sensing parameters for optimal performance, based on user-specified finger capacitance values, and continuously compensates for system, manufacturing, and environmental changes.



Note: SmartSense currently supports widgets with **CSD (Self-cap)** Sensing mode only. **CSX (Mutual-cap)** widgets must be tuned manually.

Some advantages of SmartSense, as opposed to manual tuning are:

• **Reduced design cycle time:** The design flow for capacitive touch applications involves tuning all of the sensors. This step can be time consuming if there are many sensors in your design. In addition, you must repeat the tuning when there is a change in the design, PCB layout, or mechanical design. Auto-tuning solves these problems by setting all of the parameters automatically. Figure 60 shows the design flow for a typical CAPSENSE[™] application with and without SmartSense



Figure 60

- Design flow with and without SmartSense
- Performance is independent of PCB variations: The parasitic capacitance, C_P, of individual sensors can vary due to process variations in PCB manufacturing, or vendor-to-vendor variation in a multi-sourced supply chain. If there is significant variation in C_P across product batches, the CAPSENSE[™] parameters must be re-tuned for each batch. SmartSense sets parameters for each device automatically, hence taking care of variations in C_P
- Ease of use: SmartSense is faster and easier to use because only a basic knowledge of CAPSENSE[™] is needed

Note that SmartSense can be used in multiple ways:

- SmartSense (Full auto-tune) This is the quickest way to tune. This method calibrates CAPSENSE[™] hardware and software parameters automatically at runtime. This is the recommended method for most designs
- 2. SmartSense (Hardware parameters only) This method auto-tunes all hardware parameters of CAPSENSE[™], but allows to set user-defined threshold values (see Table 15). This method consumes less



flash/RAM resources than SmartSense (Full Auto-Tune). Also, this method avoids the extra processing needed for automatic threshold calculation and hence allows lower power consumption for a given scan rate. Use this method for low-power or noisy designs or in cases with constrained memory requirements

3. SmartSense for initial tuning – You may also use SmartSense for initial tuning, to quickly find the best settings for a CAPSENSE[™] board and then change to manual tuning. This method is useful for cases with strict requirements on response time or power consumption. This is a quick method to find the best settings, instead of starting manual tuning from scratch. Refer to the section Using SmartSense to determine hardware parameters for more details

4. Table 10 CAPSENSE[™] parameters auto-tuned in SmartSense

Parameter	Full auto-tune mode	Hardware parameters only mode		
Scan resolution	Calculated once on CAPSENSE [™] initialization.			
Compensation IDAC				
Modulator IDAC				
Sense clock frequency				
Modulator clock frequency				
Finger threshold	Calculated once on CAPSENSE [™]	Manual selection (see Table 15).		
Noise threshold	initialization based on the selected finger capacitance and updated			
Hysteresis	after each sensor scan.			
Negative noise threshold				
Low baseline reset				

5.2.2 SmartSense full auto-tune

In SmartSense Full Auto-tune mode, the only parameter that needs to be tuned by the user is the Finger Capacitance parameter. The Finger Capacitance parameter (C_F) indicates the minimum value of finger capacitance that should be detected as a valid touch by the CAPSENSETM Component. Whenever the actual C_F that is added when the finger touches the button sensor is greater than the value specified for the Finger Capacitance parameter in the Component configuration window, the sensor status will change to '1'; however, if the actual C_F added by the finger touch is less than the value specified in the Component configuration window, the sensor status will remain '0'. The way of tuning the finger capacitance is different for button and slider widgets.

Note: Even for SmartSense auto-tuning, the CAPSENSE[™] Component allows manual configuration of some general parameters like enable/disable of compensation IDAC, filters, shield such as liquid-tolerance-related parameters and modulator clock. These can be left at their default values for most cases or configured based on the respective sections in this guide.

5.2.2.1 Tuning button widgets

This section explains how to choose the finger capacitance value for the button widget. You may perform only a coarse tuning of the Finger capacitance parameter for a working design, or you may choose to fine-tune the Finger capacitance value. Coarse-tuning will satisfy the requirements of most designs, but fine-tuning will allow you to choose the most efficient CAPSENSE[™] parameters (that is, minimum sensor scan time) using SmartSense.

If you do not know the value of C_F (C_F can be estimated based on Equation 1), set the Finger capacitance as follows:



- **1.** Start by specifying the highest value for finger capacitance (from the available options in the list) and check the SNR and button status when the button is touched. Use the Tuner GUI to find the SNR
- 2. Decrease the finger capacitance parameter value until the button status changes to '1' on touch and SNR>5. Figure 61 shows the detailed steps to find the right value for the Finger capacitance parameter in your design

Enable filters if the SNR of one or more sensors is less than 5:1 when the set finger capacitance is already at the least finger capacitance supported in the Component. You can also enable filters if externally induced noise is causing a decrease in SNR. See Table 11 to choose the right filter in this case. There are various types of filters available in the CAPSENSE[™] Component such as Median Filter, IIR filter, and Average Filter; you can enable more than one filter to reduce the noise in the raw count according to the requirement.

If you choose to use an IIR filter, begin by selecting a filter with a higher value of the filter coefficient and keep decreasing it until you achieve an SNR greater than or equal to 5:1. Using filters will affect the response time. You must properly select the filter coefficient such that the response time and SNR requirement are satisfied.

If the SNR is still less than 5:1 even when the smallest allowed value of finger capacitance and proper filter is chosen, see PCB layout, Manual tuning, or Tuning debug FAQs for more details on debugging the issue.







Using SmartSense auto-tuning based CAPSENSE[™] project in PSOC[™] Creator



Filter Description **Mathematical description** Application y[i] = median(x[i], x[i-1], x[i-2])Median Nonlinear filter that takes the Eliminates noise spikes three most recent samples from motors and and computes the median switching power value. supplies **Eliminates periodic** Finite impulse response filter $\mathbf{y}\left[i\right] = \frac{1}{4} \times \left(x[i] + x[i-1]\right)$ Average (no feedback) with equally noise (for example, weighted coefficients. It takes from power supplies) +x[i-2]+x[i-3])the four most recent samples and computes their average. First Order Eliminates high Infinite impulse response filter $y[i] = \frac{1}{K} \times \{N \times x[i]\}$ IIR (feedback) with a step frequency noise. response similar to an RC low $+ (K - N) \times y[i - 1]$ pass filter, thereby passing the low-frequency signals (finger touch responses). K value is fixed to 256. N is the IIR filter raw count coefficient. A lower N value results in lower noise, but slows down the response. Hardware Enables the hardware IIR filter Eliminates high-RawCount = IIR (see the equation on the right) frequency noise. for regular widgets (except $\frac{1}{2^{iirRCcoef}}RawCount_{New} + \begin{pmatrix} 1 & - \end{pmatrix}$ Proximity and Low Power). iirRCcoef – IIR filter raw count $\frac{1}{2^{\text{iirRCcoef}}}$ RawCount_{Previous} coefficient; valid range: 0 to 8. A low coefficient means lower filtering, while a higher coefficient means a higher response time. Note: There is no filtering for coefficient value "0".

Table 11 Raw data noise filters in CAPSENSE[™] component

5.2.2.2 Tuning slider widgets

For sliders, set finger capacitance to the highest value initially. Slide your finger on the slider. If at any position on the slider, at least one slider segment status is ON and has an SNR >5:1, and at least two slider segments report a "difference count" that is, a "sensor signal" value greater than 0, use this finger capacitance value. Otherwise, decrease the finger capacitance value until the above condition holds true. Figure 62 shows how to tune the finger capacitance for slider widget.

If these conditions are not met even after setting minimum allowed Finger Capacitance, use Manual tuning or revise the hardware according to Slider design considerations or see Tuning debug FAQs. Figure 62 explains the process of setting finger capacitance value for sliders.



Note: It is recommended to use the compensation IDAC because it allows a higher variation in the parasitic capacitance of the slider segment with respect to the slider segment that has the maximum C_P.



Figure 62 Setting finger capacitance value for ssliders

* To review slider design, see the Slider design section in the Design considerations chapter.

** To do manual tuning, see the Manual tuning section in the CAPSENSE[™] performance tuning chapter.

5.2.2.3 Tuning proximity widgets

See AN92239 Proximity sensing with CAPSENSE[™] and the "Proximity sensing" section in Getting started with CAPSENSE[™] design guide.

5.2.3 SmartSense hardware parameters-only mode

See Table 15 for the recommended values for thresholds when the CSD tuning method is SmartSense (Hardware parameters only).



5.2.4 SmartSense for initial tuning

See Using SmartSense to determine hardware parameters for more details.

5.3 Manual tuning

5.3.1 Overview

SmartSense technology allows a device to calibrate itself for optimal performance and complete the entire tuning process automatically. This technology will meet the needs of most designs, but in cases where SmartSense does not work or there are specific SNR or power requirements, the CAPSENSE™ parameters can be adjusted to meet system requirements. This can be achieved by manual tuning.

Some advantages of manual tuning, as opposed to SmartSense auto-tuning are:

- Strict control over parameter settings: SmartSense sets all the parameters automatically. However, there may be situations where you need to have strict control over the parameters. For example, use manual tuning if you need to strictly control the time PSOC[™] takes to scan a group of sensors or strictly control the sense clock frequency of each sensor (this can be done to reduce EMI in systems)
- Supports higher parasitic capacitances: If the parasitic capacitance is higher than the value supported by SmartSense, you should use manual tuning. See the Component datasheet/middleware document for more details on the supported range of parasitic capacitance by SmartSense

The manual tuning process can be summarized in the following three steps and is shown in Figure 63.

Set initial values of Selecting CAPSENSE[™] hardware parameters using SmartSense (see Using SmartSense to determine hardware parameters) or determine the values manually.

Tune CAPSENSE[™] component hardware parameters to ensure that Signal-to-noise is greater than 5:1 with a signal of at least 50 counts while meeting the system timing requirements.

Set optimum values of Selecting CAPSENSE[™] software parameters.

The following sections describe the fundamentals of manual tuning and the above three steps in detail. Knowledge of the CAPSENSE[™] architecture in PSOC[™] is a prerequisite for these sections. See Capacitive touch sensing method and CAPSENSE[™] generations in PSOC[™] 4 and PSOC[™] 6. The main difference in CAPSENSE[™] architecture across different generations are listed in Table 2.

Depending upon the sensing method selected, the manual tuning procedure will differ. See CSD sensing method (third- and fourth-generation), CSX sensing method (third- and fourth-generation) chapter for their respective manual tuning procedures. You can skip these sections if you are not planning to use manual tuning in your design. Figure 63 shows a general manual tuning procedure.





Figure 63 Manual tuning process overview

* To review the hardware design, see the Sensor construction and PCB layout guidelines sections in the Design considerations chapter.

5.3.2 CSD sensing method (third- and fourth-generation)

This section explains the basics of manual tuning using CSD sensing method. It also explains the hardware and software parameters that influence CSD sensing method and procedure of manual tuning for button, slider, touchpad and proximity widgets.



5.3.2.1 Basics

5.3.2.1.1 Conversion gain and CAPSENSE[™] signal

Conversion gain will influence how much signal the system sees for a finger touch on the sensor. If there is more gain, the signal is higher, and a higher signal means a higher achievable Signal-to-noise ratio (SNR).

Note: An increased gain may result in an increase in both signal and noise. However, if required, you can use firmware filters to decrease noise. For details on available firmware filters, see Table 11.

Conversion gain in single IDAC mode

In the single IDAC mode, the raw count is directly proportional to the sensor capacitance.

rawcount = $G_{CSD} C_S$

Equation 34 Raw count relationship to sensor capacitance

Where,

C_S = sensor capacitance

 $C_{\rm S} = C_{\rm P}$ if there is no finger present on sensor

 $C_{\rm S} = (C_{\rm P} + C_{\rm F})$ when there is a finger present on the sensor

G_{CSD} = Capacitance to digital conversion gain of CAPSENSE[™] CSD

The approximate value of this conversion gain using the IDAC sourcing mode, according to Equation 10 and Equation 34 is:

$$G_{CSD} = \left(2^N - 1\right) \frac{V_{REF} F_{SW}}{I_{MOD}}$$

Equation 35 Capacitance to digital converter gain

$$G_{CSD} = \left(2^N - 1\right) \frac{(V_{DD} - V_{REF})F_{SW}}{I_{MOD}}$$

Equation 36 Capacitance to digital converter gain (sinking IDAC mode)

Where,

 V_{REF} = Comparator reference voltage. Refer Table 2.

 F_{SW} = Sense clock frequency

 I_{MOD} = Modulator IDAC current

N = Resolution of the sigma to delta converter.

The tunable parameters of the conversion gain are V_{REF} , F_{SW} , I_{MOD} , and N. Figure 64 illustrates a plot of raw count versus sensor capacitance.





Figure 64 Raw count versus sensor capacitance

The change in raw counts when a finger is placed on the sensor is called CAPSENSE[™] signal. Figure 65 shows how the value of the signal changes with respect to the conversion gain.





Signal values for different conversion gains



Figure 65 shows three plots corresponding to three conversion gain values G_{CSD3} , G_{CSD2} , and G_{CSD1} . An increase in the conversion gain results in higher signal value. However, this increase in the conversion gain also moves the raw count corresponding to C_P (that is, Baseline) towards the maximum value of raw count (2^N-1). For very high gain values, the raw count saturates as the plot of G_{CSD3} shows. Therefore, you should tune the conversion gain to get a good signal value while avoiding saturation of raw count. Tune the CSD parameters such that when there is no finger on the sensor, that is when $C_S = C_P$, the raw count = 85% of (2^N-1) as Figure 66 shows. This ensures maximum gain, with enough margin for the raw count to grow because of environmental changes, and not saturate on finger touches.



Figure 66

Recommended tuning

Conversion gain in dual IDAC mode

The equation for raw count in the dual IDAC mode, according to Equation 34 and Equation 12 is:

rawcount =
$$G_{CSD}C_S - \left(2^N - 1\right) \frac{I_{COMP}}{I_{MOD}}$$

Equation 37 Dual IDAC mode raw counts

Where,

*I*_{COMP} = Compensation IDAC current

 G_{CSD} is given by Equation 9 for sourcing IDAC mode and Equation 36 for sinking IDAC mode.

In both single IDAC and dual IDAC mode, tune the CSD parameters, so that when there is no finger on the sensor, that is when $C_S =$, C_P the raw count = 85% of (2N-1), as Figure 67 shows, to ensure high conversion gain, to avoid Flat-spots, and to avoid raw count saturation due to environmental changes.





Figure 67 Recommended tuning in dual IDAC mode

As Figure 67 shows, the 85% requirement restricts to a fixed gain in single-IDAC mode, while in dual-IDAC mode, gain can be increased by moving the C_S axis intercept to the right (by increasing I_{COMP}) and correspondingly decreasing the modulator IDAC (I_{MOD}) to still achieve raw count = 85% of (2^N-1) for $C_S = C_P$. Using dual IDAC mode this way brings the following changes to the Raw Count versus C_P graph:

1. Use of compensation IDAC introduces a non-zero intercept on the C_S axis as given in .

$$C_{S} \text{axis intercept} = \left(\frac{I_{COMP}}{V_{REF}F_{SW}}\right)$$

Equation 38

C_S axis intercept with regards to I_{COMP}

The value of I_{MOD} in the dual IDAC mode is half compared to the value of I_{MOD} in the single IDAC mode (all other parameters remaining the same), so the gain G_{CSD} in the dual IDAC mode is double the gain in the single IDAC mode according to dual IDAC mode. Thus, the signal in the dual IDAC mode is double the signal in the single IDAC mode for a given resolution N.

While manually tuning a sensor, keep dual IDAC mode and Equation 26 as well as the following points in mind:

- **1.** Higher gain leads to increased sensitivity and better overall system performance. However, do not set the gain such that raw counts saturate, as the plot of gain G_{CSD3} shows in Figure 65. It is recommended to set the gain in such a way that the raw count corresponding to C_P is 85 percent of the maximum raw count for both the single IDAC and dual IDAC mode. The sense clock frequency (F_{SW}) should be set carefully; higher the frequency, higher the gain, but the frequency needs to be low enough to fully charge and discharge the sensor as Equation 26 indicates
- 2. Enabling the Compensation IDAC plays a huge role in increasing the gain; it will double the gain if set as recommended above. Always enable the Compensation IDAC when it is not being used for general-purpose applications



- **3.** Lower the modulation IDAC current, higher the gain. Adjust your IDAC to achieve the highest gain, but make sure that the raw counts corresponding to C_P have enough margin for environmental changes such as temperature shifts, as indicated in Figure 66 and Figure 67
- **4.** Increasing the number of bits of resolution used for scanning increases gain. An increase in resolution by one bit will double the gain of the system, but also double the scan time according to Equation 8. A balance of scan time and gain needs to be achieved using resolution

5.3.2.1.2 Flat-spots

Ideally, raw counts should have a linear relationship with sensor capacitance as Figure 64 and Figure 67 show. However, in practice, sigma delta modulators have non-sensitivity zones, also called flat-spots or dead-zones – for a range of sensor capacitance values, the sigma delta modulator may produce the same raw count value as Figure 68 shows. This range is known as a dead-zone or a flat-spot.



Figure 68 Flat-spots in raw counts versus sensor capacitance when direct clock is used

In the case of CAPSENSE[™] CSD, these flat spots occur near 25, 50, and 75 percent of the maximum raw count value (that is, near 25%, 50%, and 75% of 2^N-1, where N = Scan resolution). These flat spots are prominent when direct clock is used as Sense clock source. Flat-spots do not occur if PRS is used as the Sense Clock source (see also section Using SmartSense to determine hardware parameters.

For almost all systems, we recommend using PRS as the Sense Clock source because it limits the impact of flat spots and also provides EMI/EMC benefits as indicated in Sense clock. If your system requires a direct clock, ensure that you use auto-calibration or avoid this raw count range when using manual calibration.

Flat-spots reduction techniques

1. Calibrate rawcount to 85%

In the case of CAPSENSE[™] CSD, these flat-spots occur near 25, 50, and 75 percent of the maximum raw count value (that is, near 25%, 50%, and 75% of 2N-1, where 'N' is the scan resolution). Setting calibration to 85% decreases the width of flat-spots significantly.

2. Use PRS clock

These flat-spots are prominent when direct clock is used as the Sense clock source. Flat-spots do not occur if PRS is used as the Sense Clock source (refer to the Using SmartSense to determine hardware



parameters section). For almost all systems, we recommend using PRS as the Sense Clock source because it limits the impact of flat-spots and also provides EMI/EMC benefits as indicated in Sense clock source. If your system requires a direct clock, ensure that you use auto-calibration or avoid this raw count range when using manual calibration.

5.3.2.2 Selecting CAPSENSE[™] hardware parameters

CAPSENSE[™] hardware parameters govern the conversion gain and CAPSENSE[™] signal. Table 12 lists the CAPSENSE[™] hardware parameters that apply to CSD sensing method. The following subsection gives guidance on how to adjust these parameters to achieve optimal performance for CAPSENSE[™] CSD system.

For simplicity of documentation, this design guide shows selecting the CAPSENSE[™] parameters in PSOC[™] Creator. You can use the same procedure to set the parameters in ModusToolbox[™]. However, in ModusToolbox[™], you set the Sense clock and Modulator clock using divider values while in the PSOC[™] Creator you specify the frequency value directly in the configurator. For more details on configuring CAPSENSE[™], see the Component datasheet/middleware document.

Sl. No.	CAPSENSE [™] parameter in PSOC [™] Creator	CAPSENSE [™] parameter in ModusToolbox [™]	
1	Sense cock frequency	Sense clock divider	
2	Sense clock source	Sense clock source	
3	Modulator clock frequency	Modulator clock divider	
4	Modulator IDAC	Modulator IDAC	
5	Compensation IDAC	Compensation IDAC	
6	Scan resolution	Scan resolution	

Table 12	CAPSENSE [™] component hardware parameters
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5.3.2.2.1 Using SmartSense to determine hardware parameters

Parameters listed in Table 12 are CAPSENSE[™] hardware parameters. Tuning these parameters manually for optimal value is a time-consuming task. You can use SmartSense to determine these hardware parameters and take it as an initial value for manual tuning. You can fine-tune these values to further optimize the scan time, SNR, power consumption, or improving EMI/EMC capability of the CAPSENSE[™] system.

Set the tuning mode to SmartSense and configure default values for parameters other than finger capacitance. See the SmartSense section for the tuning procedure and use the Tuner GUI to read back all the hardware parameters set by SmartSense. See the Component datasheet/middleware document for more details on how to use the Tuner GUI.

Figure 69 shows the best hardware parameter values in the Tuner GUI that are tuned by SmartSense for a specific hardware to sense a minimum finger capacitance of 0.1 pF.





Figure 69 Read-back hardware parameter values in Tuner GUI

5.3.2.2.2 Manually tuning hardware parameters

Sense clock parameters

There are two parameters that are related to Sense clock: Sense clock source and Sense clock frequency.

Sense clock source

Select "Auto" to let the Component automatically choose the best sense clock source from Direct, PRSx, and SSCx for each widget. If not selecting Auto, then select the clock source based on the following:

- Use pseudo random sequence (PRSx) modes to remove flat-spots
- Use spread spectrum clock (SSCx) modes for reducing EMI/EMC noise at a particular frequency. This feature is available in the PSOC[™] 4 S-Series, PSOC[™] 4100S Plus, PSOC[™] 4100PS, and PSOC[™] 6 family of devices. In this case, the frequency of the sense clock is spread over a predetermined range
- Use the direct clock for absolute capacitance measurement

When selecting PRSx as the sense clock source, ensure that the sequence completes within one conversion cycle; not letting the sequence complete may cause high noise in raw count, that is, $T_{PRS} << T_{SCAN}$. For PRS clock, use the following equations to calculate one PRS sequence completion cycle and scan time.



$$T_{SCAN} = \frac{2^N - 1}{F_{MOD}}$$
, where N is the Scan resolution

Equation 39 Sensor scan time

$$T_{PRS} = \frac{2^{N_PRS} - 1}{F_{SW}}$$
, where N_PRS is either 8 or 12

Equation 40 PRS sequence period

See the Component datasheet/middleware document for more details on the rules and recommendations for SSCx selection.

Sense clock frequency

The sense clock frequency should be selected so that the sensor will charge and discharge completely in each sense clock period as Figure 39 shows.

This requires that the maximum sense clock frequency be chosen per Equation 41.

$$F_{SW}(\text{maximum}) = \frac{1}{10R_{SeriesTotal}C_{H}}$$

Equation 41 Sense clock maximum frequency

$$R_{SeriesTotal} = R_{EXT} + R_{GPIO}$$

Equation 42 Total series resistance

Here, C_P is the sensor parasitic capacitance, and $R_{SeriesTotal}$ is the total series-resistance, including the 500 Ω resistance of the internal switches, the recommended external series resistance of 560 Ω (connected on PCB trace connecting sensor pad to the device pin), and trace resistance if using highly resistive materials (example ITO or conductive ink);that is, a total of 1.06 k Ω plus the trace resistance.

The value for CP can be estimated using the CSD Built-in-Self-test API; GetSensorCapacitance(). See the Component datasheet/middleware document for details.

Equation 35 shows that it is best to use the maximum clock frequency to have a good gain; however, you should ensure that the sensor capacitor fully charges and discharges as shown in Figure 39.

Generally, the C_P of the shield electrode will be higher compared to sensor C_P . For good liquid tolerance, the shield signal should satisfy the condition mentioned in Shield electrode tuning theory. If it is not satisfied, reduce the sense clock frequency further to satisfy the condition.

Modulator clock frequency

The modulator clock governs the conversion time for capacitance-to-digital conversion, also called the "sensor scan time" (see Equation 8).

A lower modulator clock frequency implies the following:

Longer conversion time (see Equation 26 and Equation 24)

- Lower peak-to-peak noise on raw count because of longer integration time of the sigma-delta converter
- Wider Flat-spots



Select the highest frequency for the shortest conversion time and narrower flat spots for most cases. Use slower modulator clock to reduce peak-to-peak noise in raw counts if required.

Modulation and compensation IDACs

CSD supports two IDACs: Modulation IDAC and Compensation IDAC that charge C_{MOD} as Figure 35 shows. These govern the Conversion gain in dual IDAC mode for capacitance-to-digital conversion. The CAPSENSE[™] Component allows the following configurations of the IDACs:

- Enabling or disabling of Compensation IDAC
- Enabling or disabling of Auto-calibration for the IDACs
- DAC code selection for Modulator and Compensation IDACs if auto-calibration is disabled

Compensation IDAC

Enabling the compensation IDAC is called "dual IDAC" mode, and results in increased signal as explained in Conversion gain in dual IDAC mode. Enable the compensation IDAC for most cases. Disable the compensation IDAC only if you want to free the IDAC for other general-purpose analog functions.

Auto-calibration

This feature enables the firmware to automatically calibrate the IDAC to achieve the required calibration target of 85%. It is recommended to enable auto-calibration for most cases. Enabling this feature will result in the following:

- Fixed raw count calibration to 85% of maximum raw count even with part-to-part C_P variation
- Avoids Flat-spots
- Automatically selects the optimum gain

If your design environment includes large temperature variation, you may find that the 85% IDAC calibration level is too high, and that the raw counts saturate easily over large changes in temperature, leading to lower SNR. If this is the case, you can adjust the calibration level lower by using CapSense_CSDCalibrateWidget() in your firmware.

For proper functioning of CAPSENSE^M under diverse environmental conditions, it is recommended to avoid very low or high IDAC codes. For a 7-bit IDAC, it is recommended to use IDAC codes between 18-110 from the possible 0 to 127 range. You can use CAPSENSE^M tuner to confirm that the auto-calibrated IDAC values fall in this recommended range. If the IDAC values are out of the recommended range, based on Equation 34, Equation 35 and Equation 37, you may change the V_{Ref} or F_{SW} to get the IDAC code in proper range.

Disable IDAC auto-calibration if a change in C_P needs to be detected by measuring the raw count level at reset, for example:

- Detecting large variations in sensor C_P across boards or layout problems
- Detecting finger touch at reset
- Advanced CAPSENSE™ methods like liquid-level sensing, for example, to have different raw count level for different liquid levels at reset

Selecting DAC codes

This is not the recommended approach. However, this could be used only If you want to disable autocalibration for any reason. To get the IDAC code, you may first configure CAPSENSE[™] Component with autocalibration enabled and all other hardware parameters the same as required for final tuning and read back the calibrated IDAC values using Tuner GUI. Then, re-configure the CAPSENSE[™] Component to disable autocalibration and use the obtained IDAC codes as fixed DAC codes read-back from the Tuner GUI.



Scan resolution

It governs the sensor scan time per Equation 39 and the conversion gain per Equation 34, Equation 35, and Equation 37. Scan resolution needs to be selected to maintain a balance between the signal and scan time. Higher scan resolution implies the following:

- Longer scan time per Equation 39
- Higher SNR on raw counts (increase in resolution increases the signal at a disproportionate rate to noise)

In general, it is recommended to tune the resolution to achieve as high SNR as possible; however if the system is constrained on power consumption and/or response time, set the lowest resolution to achieve at-least 5:1 SNR in the end system.

Note: You should tune the scan resolution for less than 10:1 SNR only if you have scan time or power number constraints.

5.3.2.2.3 Tuning shield electrode

The shield related parameters need to be additionally configured or tuned differently when you enable the Shield electrode in the CSD sensing method for liquid tolerance or reducing the C_p of the sensor.

Shield electrode tuning theory

Ideally, the shield waveform should be exactly the same as that of the sensor as explained in Driven shield signal and shield electrode. However, in practical applications, the shield waveform may have a higher settling time and an overshoot error. Observe the sensor and shield waveform in the oscilloscope; an example waveform is shown in Driven shield signal and shield electrode. The shield waveform should settle to the sensor voltage within 90% of ON time of the sense clock waveform and the overshoot error of the shield signal with respect to V_{REF} should be less than 10%.

If these conditions are not satisfied, you will observe a change in raw count of the sensors when touching the shield hatch; in addition, if inactive sensors are connected to shield as mentioned in Inactive sensor connection, touching one sensor can cause change in raw count on other sensors, which indicates that there is cross talk if the shield electrode is not tuned properly.

In SmartSense, the sense clock frequency is automatically set. Check if these conditions are satisfied. If not satisfied, switch to Manual tuning and set the Sense clock frequency manually so that these conditions are satisfied. You can also tune the Shield SW resistance parameter to reduce the overshoot error.





Figure 70 Properly tuned shield waveform

Tuning shield-related parameters

Enable shield tank capacitor

Enabling a shield tank capacitor increases the drive strength of the shield thus allowing the shield signal to settle to the sensor voltage faster as required. It is recommended to use the shield tank capacitor for PSOC[™] 4A-S and PSOC[™] 6 MCU family of devices. For PSOC[™] 4A, PSOC[™] 4A-L, and PSOC[™] 4A-M family of devices, the shield tank capacitor does not prove very advantageous because it doubles the shield series resistance. It is recommended to keep this option disabled for these device families.

Shield electrode delay

For proper operation of the shield electrode, the shield signal should match the sensor signal in phase. Due to the difference in trace lengths of the sensor and shield electrodes, the shield waveform may arrive earlier to the sensor waveform. You can use an oscilloscope to view both sensor and shield signals to verify this condition. If they are not aligned, use this option to add delay to the shield signal to align the two signals. Available delays vary depending on the device selected.

Shield SW resistance

This parameter controls the shield signal rise and fall times to reduce EMI. This parameter is valid only for PSOC[™] 4 S-Series, PSOC[™] 4100S Plus, PSOC[™] 4100PS, and PSOC[™] 6 MCU family of devices. The default value of shield switch resistance is Medium. Table 13 shows the effect of the Shield SW resistance value. You should select this value based on the application requirement; in addition, ensure that it satisfies the conditions in Shield electrode tuning theory.



Lower switch resistance	Higher switch resistance	
Large overshoot error	Smaller overshoot error	
Higher electromagnetic emission	Lower electromagnetic emission	
Faster settling time that is, higher maximum sense clock frequency	Slower settling time that is, lower maximum sense clock frequency	

Table 13 Shield SW resistance selection guidelines

Number of shield electrodes

This parameter specifies the number of shield electrodes required in the design. Most designs work with one dedicated shield electrode; however, some designs require multiple dedicated shield electrodes for ease of PCB layout routing or to minimize the PCB real estate used for the shield layer. See Layout guidelines for shield electrode.

Inactive sensor connection

When the shield electrode is enabled for liquid-tolerant designs, or if you want to use shield to reduce the sensor parasitic capacitance, this option should be specified as "Shield"; otherwise, select "Ground".

However, there is a risk of higher radiated emission due to inactive sensors getting connected to Shield. In such situations, use the CAPSENSE[™] API to manually control inactive sensor connections. Instead of connecting all unused sensors to the shield, connect only the opposing inactive sensors or inactive sensors closer to the sensor being scanned to shield for reducing the radiated emission.

5.3.2.3 Selecting CAPSENSE[™] software parameters

CAPSENSE[™] software parameters govern the sensor status based on the raw count of a sensor. Table 14 provides a list of CAPSENSE[™] software parameters. These parameters apply to both CSD and CSX sensing methods. This section defines these parameters with the help of Baseline, and provides guidance on how to adjust these parameters for optimal performance of your design. Table 15 shows the recommended values for the software threshold parameter and they are applicable for most of the designs. However, if there are any external noise present in the end system, you must modify these thresholds accordingly to avoid any sensor false trigger.

Table 14CAPSENSE™ component widget threshold parameters

Sl. No.	o. CAPSENSE [™] component parameter name in PSOC [™] Creator/ModusToolbox [™]		
1.	Finger threshold		
2.	Noise threshold		
3.	Hysteresis		
4.	ON debounce		
5.	Sensor auto-reset		
6.	Low baseline reset		
7.	Negative noise threshold		



Table 15	Recommended values for the	hreshold parameters		
Sl. No.	CAPSENSE [™] threshold parameter	Recommended value		
1.	Finger threshold	80 percent of signal		
2.	Noise threshold	40 percent of signal		
3.	Hysteresis	10 percent of signal		
4.	ON debounce	3		
5.	Low baseline reset	30		
6.	Negative noise threshold	40 percent of signal		

Baseline 5.3.2.3.1

After tuning the CAPSENSE[™] Component for a given C_P, the raw count value of a sensor may vary gradually due to changes in the environment such as temperature and humidity. Therefore, the CAPSENSE[™] Component creates a new count value known as baseline by low-pass filtering the raw counts. Baseline keeps track of, and compensates for, the gradual changes in raw count. The baseline is less sensitive to sudden changes in the raw count caused by a touch. Therefore, the baseline value provides a reference level for computing signal.

Figure 71 shows the concept of raw count, baseline, and signal.



Figure 71 Raw count, baseline, and signal

Baseline update algorithm 5.3.2.3.2

To properly tune the CAPSENSE[™] software, that is, the threshold parameters, it is important to understand how baseline is calculated and how the threshold parameters affect the baseline update.



Baseline is a low-pass-filtered version of raw counts. As Figure 72 shows, baseline is updated by low-pass-filtering raw counts if the current raw count is within a range of (*Baseline* – Negative noise threshold) to (*Baseline* + Noise threshold). If the current raw count is higher than baseline by a value greater than noise threshold, baseline remains at a constant value equal to prior baseline value.



Figure 72 Baseline update algorithm

If the current raw count is below baseline minus negative noise threshold, baseline again remains constant at a value equal to prior baseline value for Low baseline reset number of sensor scans. If the raw count continuously remains lower than baseline minus noise threshold for low baseline reset number of scans, the baseline is reset to the current raw count value and starts getting updated again, as Figure 73 shows.



Figure 73 Low baseline reset

5.3.2.3.3 Finger threshold

The finger threshold parameter is used along with the hysteresis parameter to determine the sensor state, as Equation 43 shows.

Sensor state = { ON if (Signal \geq Finger Threshold + Hysteresis) OFF if (Signal \leq Finger Threshold - Hysteresis) }

Equation 43 Sensor state

Note: Signal in the above equation refers to the difference: raw count – baseline, when the sensor is touched, as Figure 71 shows.



It is recommended to set finger threshold to 80 percent of the signal. This setting allows enough margin to reliably detect sensor ON/OFF status over signal variations across multiple PCBs.

5.3.2.3.4 Hysteresis

The hysteresis parameter is used along with the finger threshold parameter to determine the sensor state, as Equation 43 and Figure 74 show. Hysteresis provides immunity against noisy transitions of sensor state. The hysteresis parameter setting must be lower than the finger threshold parameter setting. It is recommended to set hysteresis to 10 percent of the signal.



Figure 74

Hysteresis

5.3.2.3.5 Noise threshold

For single-sensor widgets, such as buttons and proximity sensors, the noise threshold parameter sets the raw count limit above which the baseline is not updated, as Figure 72 shows. In other words, the baseline remains constant as long as the raw count is above *baseline* + *noise threshold*. This prevents the baseline from following raw counts during a finger touch.

The noise threshold value should always be lower than the *finger threshold – hysteresis*. It is recommended to set noise threshold to 40 percent of the signal.

If the noise threshold is set to a low value, the baseline will remain constant if raw counts suddenly increase by a small amount, say because of small shifts in power supply or shifts in ground voltage because of high GPIO sink current and so on.

On the other hand, if the noise threshold is set to a value close to *finger threshold – hysteresis*, the baseline may keep updating even when the sensor is touched. This will lead to reduced signal

Note: (signal = raw count – baseline) and the sensor state may not be reported as ON.

5.3.2.3.6 Negative noise threshold

The negative noise threshold parameter sets the raw count limit below which the baseline is not updated for the number of samples specified by the low baseline reset parameter as Figure 73 shows.

Negative noise threshold ensures that the baseline does not fall low because of any high amplitude repeated negative noise spikes on raw count caused by different noise sources such as electrostatic discharge (ESD) events.

It is recommended to set the negative noise threshold parameter value to be equal to the noise threshold parameter value.



5.3.2.3.7 Low baseline reset

This parameter is used along with the negative noise threshold parameter. It counts the number of abnormally low raw counts required to reset the baseline as Figure 73 shows.

If a finger is placed on the sensor during device startup, the baseline is initialized to the high raw count value at startup. When the finger is removed, raw counts fall to a lower value. In this case, the baseline should track the low raw counts. The Low Baseline Reset parameter helps to handle this event. It resets the baseline to the low raw count value when the number of low samples reaches the low baseline reset number.

Note: In this case, when the finger is removed from the sensor, the sensor will not respond to finger touches for a low baseline reset time given by Equation 44.

Low Baseline Reset Time = $\frac{Low Baseline Re set parameter value}{Scan rate}$

Equation 44 Low baseline reset time

The low baseline reset parameter should be set to meet following conditions:

- Low baseline reset time is greater than the time for which negative noise (due to noise sources such as ESD events) is expected to last
- Low baseline reset time is lower than the time in which a sensor is expected to start responding again after the finger kept on sensor during device startup is removed from the sensor

The low baseline reset parameter is generally set to a value of 30.

5.3.2.3.8 Debounce

This parameter selects the number of consecutive CAPSENSE[™] scans during which a sensor must be active to generate an ON state from the component. Debounce ensures that high-frequency, high-amplitude noise does not cause false detection.

```
\begin{array}{l} \text{Sensor state} = \{ ON \ if \ (Signal \geq Finger \ Threshold \ + \ Hysteresis) \ for \ scans \geq debounce \\ OFF \ if \ (Signal \leq Finger \ Threshold \ - \ Hysteresis) \\ OFF \ if \ (Signal \geq Finger \ Threshold \ + \ Hysteresis) \ for \ scans \ < debounce \\ \end{array}
```

Equation 45 Sensor state with debounce

The Debounce parameter impacts the response time of a CAPSENSE[™] system. The time it takes for a sensor to report ON after the raw counts value have increased above finger threshold + hysteresis because of finger presence, is given by Equation 46.

```
Sensor response time = \frac{Debounce}{Scan Rate}
```

Equation 46 Relationship between debounce and sensor response time

The Debounce parameter is generally set to a value of '3' for reliable sensor status detection. It can be raised or lowered based on the noise aspects of the end user system.

5.3.2.3.9 Sensor auto reset

Enabling the Sensor Auto Reset parameter causes the baseline to always update regardless of whether the signal is above or below the noise threshold.



When auto reset is disabled, the baseline only updates if the current raw count is within a range of (*Baseline – Negative Noise Threshold*) to (*Baseline + Noise Threshold*) as Figure 72 shows and the Baseline update algorithm describes. However, when Auto Reset is enabled, baseline is always updated if the current raw count is higher than (*Baseline – Negative Noise Threshold*) as Figure 75 shows.



Figure 75 Baseline update with sensor auto reset enabled

Because the baseline is always updated when sensor auto reset is enabled, this setting limits the maximum time duration for which the sensor will be reported as pressed. However, enabling this parameter prevents the sensors from permanently turning on if the raw count suddenly rises without anything touching the sensor. This sudden rise can be caused by a large power supply voltage fluctuation, a high-energy RF noise source, or a very quick temperature change.

Enable this option if you have a problem with sensors permanently turning on when the raw count suddenly rises without anything touching the sensor.

5.3.2.3.10 Multi-frequency scan

Enabling multi-frequency scan, the CAPSENSE[™] component performs a sensor scan with three different sense clock frequencies and obtains corresponding difference count. The median of the sensor difference-count is selected for further processing. Use this feature for robust operation in the presence of external noise at a certain sensor scan frequency. This option is not available in SmartSense Full Autotune mode. See the code example CE227719 CAPSENSE[™] with multi-frequency scan.

5.3.2.4 Button widget tuning

Figure 76 illustrates an overview of the CSD button tuning procedure.





Figure 76 CSD button widget tuning flowchart

Attention: For fifth-generation CAPSENSE[™], change number of sub-conversions (N_{Sub}) instead of resolution.



To review the hardware design, see the Sensor construction and PCB layout guidelines sections in the Design considerations chapter. Also, see the Tuning debug FAQs section for guidelines on advanced debug.

As explained in Chapter 5.1, Manual tuning requires effort to tune optimum CAPSENSE[™] parameters, but allows strict control over characteristics of capacitive sensing system, such as response time and power consumption. The button is tuned for reliable touch detection to avoid false triggers in noisy environment.

The CE230926 PSOC[™] 4: CAPSENSE[™] CSD button tuning explains tuning of self-capacitance based button widgets in the Eclipse IDE for ModusToolbox[™] using the CAPSENSE[™] Tuner GUI. For details on the Component and all related parameters, see the Component datasheet.

5.3.2.5 Slider widget tuning

A slider has many segments, each of which is connected to the CAPSENSETM input pins of the PSOCTM device. Unlike the simple on/off operation of a button widget sensor, slider widget sensors work together to track the location of a finger or other conductive object. Because of this, the slider layout design should ensure that the C_P of all the segments in a slider remain as close as possible. Keeping similar C_P values between sensors will help minimize the tuning effort and ensure an even response across the entire slider. See Slider design for details on slider layout design guidelines to avoid nonlinearity in the centroid, ensure that the signal from all the slider segments is equal, as Figure 77 shows, when a finger is placed at the center of the slider segment. If the signal of the slider segments is different, then the centroid will be nonlinear, as Figure 78 shows.

Note:

In PSOC™ Creator and in ModusToolbox™, a centroid of 0xFFFF and 0x0000 is reported respectively when a finger is not detected on the slider, or when none of the slider segments report a difference count value greater than the Finger Threshold parameter.



Figure 77 Response of centroid versus finger location when signals of all slider elements are equal

Note: Signal = Raw Count – Baseline





Figure 78

Response of centroid versus finger location when the signal of all slider elements are different

A linear response for the reported finger position (that is, the Centroid position) versus the actual finger position on a slider requires that the slider design is such that whenever a finger is placed anywhere between the middle of the segment SLDn and middle of segment SLDn-1, other than the exact middle of slider segments, exactly two sensors report a valid signal ⁹. If a finger is placed at the exact middle of any slider segment, the adjacent sensors should report a difference count = noise threshold. These conditions are required since the centroid position calculation is based on the closest segment to the finger and two neighboring segments as shown in Equation 47.

centroid position =
$$\left(\frac{S_{x+1} - S_{x-1}}{S_{x+1} + S_{x-1}} + x\right) \times \frac{\text{Resolution}}{(n-1)}$$

Equation 47 Centroid algorithm used by CAPSENSE[™] component in PSOC[™]

Where,

Resolution = API resolution set in the CAPSENSE $^{\text{\tiny M}}$ Component Customizer

n = Number of sensor elements in the CAPSENSE[™] Component Customizer

x = Index of element which gives maximum signal

 s_i = Different counts (with subtracted noise threshold value) of the slider segment

Figure 79 shows an overview of the CSD slider tuning procedure.

⁹ Here, a valid signal means that the difference count of the given slider segment is greater than or equal to the noise threshold value.





Figure 79CSD slider widget tuning flowchart

Attention: For fifth-generation CAPSENSE[™], change number of sub-conversions (N_{Sub}) instead of resolution.


The upper crossover point (UCP) and lower crossover point (LCP) are obtained as shown inFigure 80. Refer to CE229521 – PSOC[™] 4 CAPSENSE[™] CSD Slider tuning which demonstrates how to manually tune a self-capacitance based Slider widget on PSOC[™] Creator and CE230493 – PSOC[™] 4: CAPSENSE[™] CSD Slider tuning on Eclipse IDE for ModusToolbox[™].



Figure 80 Difference count (delta) vs finger position

5.3.2.6 Touchpad widget tuning

Please refer to AN234185 PSoC[™] 4 CAPSENSE[™] Touchpad design guide for touchpad tuning guidelines.

5.3.2.7 Proximity widget tuning

For tuning a proximity sensor, see AN92239 - Proximity sensing with CAPSENSE[™].

5.3.3 CSX sensing method (third- and fourth-generation)

This chapter explains the basics of manual tuning using the CSX sensing method. It also explains the hardware parameters that influence a manual tuning procedure.

5.3.3.1 Basics

5.3.3.1.1 Conversion gain and CAPSENSE[™] signal

In a mutual-capacitance sensing system, the *Rawcount*_{counter} is directly proportional to the mutual-capacitance between the Tx and Rx electrodes, as Equation 48 shows.

 $Rawcount_{Counter} = G_{CSX}C_M$

Equation 48 Raw count relationship to sensor capacitance

Where,

 G_{CSX} = Capacitance to digital conversion gain of CAPSENSETM CSX

 $C_{\rm M}$ = Mutual-capacitance between the Tx and Rx electrodes.



Figure 82 shows the relationship between raw count and mutual capacitance of the CSX sensor. The tunable parameters of the conversion gain in Equation 49 are F_{TX} , N_{MOD} , F_{MOD} and IDAC. The approximate value of this conversion gain is:

 $G_{CSX} = \frac{2 \ V_{TX} F_{TX} \ MaxCount}{IDAC}$

Equation 49 Capacitance to digital converter gain

MaxCount = $\frac{F_{Mod} N_{Sub}}{F_{TX}}$

Equation 50 MaxCount equation

Where,

V_{TX} = Voltage at the Tx node of the sensor as shown in Figure 81

 $V_{TX} = V_{ON} - V_{OFF}$

The value of V_{TX} is always V_{DDIO} or V_{DDD} (if V_{DDIO} is not available) if the Tx clock frequency can completely charge and discharge the Tx electrode. F_{TX} is the Tx clock frequency, I_{DAC} is the current drawn for charging and discharging the C_{INT} capacitors, and N_{sub} is the number of sub-conversions.



Figure 81 Voltage at Tx node of the CSX sensor

Note: The raw count observed from the Component is given by Equation 51. See CAPSENSE[™] CSX sensing method (third- and fourth- generation) for more details on Rawcount_{component}.

 $Rawcount_{Component} = MaxCount - Rawcount_{counter}$

Equation 51 Rawcount_{Component}





Figure 82 Raw count vs Sensor mutual-capacitance

5.3.3.2 Selecting CAPSENSE[™] hardware parameters

CAPSENSE[™] hardware parameters govern the conversion gain and. Table 16 lists the CAPSENSE[™] hardware parameters that apply to the CSX sensing method. Table 16 also shows the mapping of each parameter in the PSOC[™]Creator CAPSENSE[™] component to the one in the ModusToolbox[™] middleware. For simplicity of documentation, this design guide shows selecting the CAPSENSE[™] parameter using the CAPSENSE[™] configurator in PSOC[™] Creator. The same procedure could be followed in configuring CAPSENSE[™] in ModusToolbox[™]. However, in ModusToolbox[™], you set the Tx clock and Modulator clock using divider values. On the other hand, in PSOC[™] Creator, you specify the frequency value directly in the configurator. See Component datasheet/middleware document.

	5 .	•		
Sl #	CAPSENSE [™] parameter in PSOC [™] Creator	CAPSENSE [™] parameter in ModusToolbox [™]		
1	Modulator clock frequency	Modulator clock divider		
2	Tx clock source	Tx clock source		
3	Tx clock frequency	Tx clock divider		
4	IDAC	IDAC		
5	Number of sub-conversions	Number of sub-conversions		

Table 16	CAPSENSE[™] signal	component hardware	parameters

5.3.3.2.1 Tx clock parameters

There are two parameters that are related to the Tx clock: Sense clock source and Sense clock frequency.

Tx clock source

Select "Auto" to let the Component automatically choose the best Tx clock source between Direct and Spread spectrum clock (SSCx) for each widget. If not selecting Auto, select the clock source based on the following:

- Direct Clock signal with a fixed clock frequency. Use this option for most cases
- Spread spectrum clock (SSCx) If you chose this option, the Tx clock signal frequency is dynamically spread over a predetermined range. Use this option for reduced EMI interference and avoiding Flat-spots



However, when selecting SSCx clock, you need to select the Tx clock frequency, Modulator clock frequency, and number of sub conversion such that the conditions mentioned in Component datasheet/ModusToolbox[™] CAPSENSE[™] configurator guide for SSCx clock source selection are satisfied.

Tx clock frequency

The Tx clock frequency determines the duration of each sub-conversion as explained in the CAPSENSE[™] CSX sensing method (third- and fourth- generation) Chapter. The Tx clock signal must completely charge and discharge the sensor parasitic capacitance; it can be verified by checking the signal in an oscilloscope, or it can be set using the Equation 52. In addition, you should ensure that the auto-calibrated IDAC code lies in the midrange (for example, 30-90) for the selected . If the auto-calibrated IDAC code lies out of the recommended range, tune such that it IDAC falls in the recommended range and satisfies Equation 52.

$$F_{TX} < \frac{1}{10 \, R_{SeriesTx} C_{PTx}}$$

Equation 52 Condition for selecting Tx clock frequency

To minimize the scan time, as Equation 53 shows, it is recommended to use the maximum Tx clock frequency available in the component drop-down list that satisfies the criteria.

$$T_{CSX} = \frac{N_{Sub}}{F_{Tx}}$$

Equation 53 Scan time of CSX sensor

Where, N_{Sub} = Number of sub-conversions.

Additionally, if you are using the SSCx clock source, ensure that you select the Tx clock frequency that meets the conditions mentioned in Component datasheet/middleware document/ModusToolbox[™] CAPSENSE[™] configurator guide in addition to these conditions.

The maximum value of FTX depends on the selected device. For the PSOC[™] 4 S-Series, PSOC[™] 4100S Plus, PSOC[™] 4100PS, and PSOC[™] 6 MCU family of devices, the maximum FTX is 3000 kHz and for other devices it is 300 kHz.

5.3.3.2.2 Modulator clock frequency

It is best to choose the highest allowed clock frequency for the given device because a higher modulator clock frequency leads to a higher sensitivity/signal, increased accuracy, and lower noise for a given C_M to digital count conversion as Equation 40 and Equation 41 indicate. Also, a higher value of F_{mod}/F_{tx} ensures lower width of Flatspots in C_M to raw count conversion.

5.3.3.2.3 IDAC

It is recommended to enable IDAC auto-calibration. It is best to avoid very high and very low IDAC codes. The recommended IDAC code range is between 30-90. If the IDAC values are away from the recommended range, tune the Tx clock frequency to adjust the IDAC level. If the IDAC is failing to calibrate properly, it may be due to low $C_{\rm M}$ in the design. Refer to the section I am observing a low CM for my CSX button for mitigating impact of low $C_{\rm M}$ in the design.



5.3.3.2.4 Number of sub-conversions

The number of sub-conversions decides the sensitivity of the sensor and sensor scan time. From Equation 14 for a fixed modulator clock and Tx clock, increasing the number of sub-conversions (N_{Sub}) increases the signal and SNR. However, increasing the number of sub-conversions also increases the scan time of the sensor per Equation 54.

Scan time = $\frac{N_{Sub}}{F_{Tx}}$

Equation 54 CSX scan time

Initially, set the value to a low number (for example, 20), and use the Tuner GUI to find the SNR of the sensor. If the SNR is not > 5:1 with the selected N_{Sub} , try to increase the N_{Sub} in steps such that the SNR requirement is met.

5.3.3.3 Selecting CAPSENSE[™] software parameters

CAPSENSE[™] software parameters for mutual-capacitance are the same as that for self-capacitance; therefore, these parameters could be selected as mentioned in the section Selecting CAPSENSE[™] software parametersSelecting CAPSENSE[™] software parameters.

5.3.3.4 Button widget tuning

Figure 83 illustrates an overview of the CSX button tuning procedure.





Figure 83 CSX button widget tuning example

* To review the hardware design, see the Sensor construction and PCB layout guidelines sections in the Design considerations chapter. Also, see the Tuning debug FAQs section for guidelines on advanced debug



The CE230660 PSOC[™] 4: CAPSENSE[™] CSX button tuning explains tuning of mutual-capacitance based button widgets in the Eclipse IDE for ModusToolbox[™] and CE228931 – PSOC[™] 4 CAPSENSE[™] CSX button tuning in PSOC[™] Creator using the CAPSENSE[™] tuner. For details on the Component and all related parameters, see the Component datasheet.

5.3.3.5 Touchpad widget tuning

Please refer to AN234185 PSoC[™] 4 CAPSENSE[™] Touchpad design guide for touchpad tuning guidelines.

5.3.4 CSD-RM sensing method (fifth-generation and fifth-generation lowpower)

This chapter explains the basics of manual tuning using CSD-RM sensing method (Fifth-Generation and Fifth-Generation Low-Power). It also explains the hardware and software parameters that influence the CSD-RM sensing method and the procedure of manual tuning for button, slider, touchpad and proximity widgets.

5.3.4.1 Basics

5.3.4.1.1 Conversion gain and CAPSENSE[™] signal

Conversion gain will influence how much signal the system sees for a finger touch on the sensor. If there is more gain, the signal is higher, and a higher signal means a higher achievable Signal-to-noise ratio (SNR).

Note: An increased gain may result in an increase in both signal and noise. However, if required, you can use firmware filters to decrease noise. For details on available firmware filters, see Table 11.

Conversion gain in single CDAC

In the single CDAC mode, the raw count is directly proportional to the sensor capacitance.

raw count =
$$G_{CSD} C_S$$

Equation 55 Raw count relationship to sensor capacitance

Where,

C_S = Sensor capacitance

 $C_{\rm S}$ = $C_{\rm P}$ if there is no finger present on sensor

 $C_{\rm S} = (C_{\rm P} + C_{\rm F})$ when there is a finger present on the sensor

 G_{CSD} = Capacitance to digital conversion gain of CAPSENSETM CSD. The approximate value of this conversion gain according to Equation 18 and Equation 55 is shown using Equation 56.

$$G_{CSD} = MaxCount \frac{1}{SnsClk_{Div} \cdot C_{ref}}$$

Equation 56 Capacitance to digital converter gain

Where,

The equation for raw count in the single CDAC mode, according to Equation 56 and Equation 55 is shown in Equation 57.



raw count =
$$N_{Sub} \frac{C_S}{C_{ref}}$$

Equation 57 Single CDAC mode raw counts

Where,

 N_{Sub} = Number of sub-conversions $SnsClk_{Div}$ = sense clock divider C_S = Sensor capacitance C_{ref} = Reference capacitance C_{ref} = Re $fCDACCode \times C_{lsb}$ RefCDACCode = Reference CDAC value C_{lsb} = 8.86fF

The tunable parameters of the conversion gain are C_{ref} , $SnsClk_{Div}$, and N_{Sub} . Figure 84 shows a plot of raw count versus sensor capacitance.



Figure 84 Raw count versus sensor capacitance

The change in raw counts when a finger is placed on the sensor is called CAPSENSE[™] signal. Figure 85 shows how the value of the signal changes with respect to the conversion gain.





Figure 85 Signal values for different conversion gains

Figure 85 shows three plots corresponding to three conversion gain values G_{CSD3} , G_{CSD2} , and G_{CSD1} . An increase in the conversion gain results in higher signal value. However, this increase in the conversion gain also moves the raw count corresponding to C_P (that is, Baseline) towards the maximum value of raw count (Maxcount). For very high gain values, the raw count saturates as the plot of G_{CSD3} shows. Therefore, tune the conversion gain to get a good signal value while avoiding saturation of raw count. Tune the CSD-RM parameters such that when there is no finger on the sensor, that is when $C_S = C_P$, the raw count = 85% of Maxcount as Figure 86 shows. This ensures maximum gain, with enough margin for the raw count to grow because of environmental changes, and not saturate on finger touches.





Figure 86 Recommended tuning

Conversion gain in dual CDAC mode

The equation for raw count in the dual CDAC mode, according to Equation 19 and Equation 55 is shown in Equation 58.

$$2 \times C_{comp}$$
 $C_{CSD} C_S - Maxcount \times \frac{2 \times C_{comp}}{C_{ref}CompCLK_{div}}$ Equation 58 Dual CDAC mode raw countsWhere,Maxcount = $N_{Sub} * SnsClk_{Div}$ SnsClk_{Div} = Sense clock divider $N_{Sub} * SnsClk_{Div}$ SnsClk_Div = Sense clock divider $N_{Sub} = Number of sub-conversions $C_{ref} = Reference capacitance $C_{comp} = Compensation capacitance $C_{omp}CLK_{Div} = CDAC compensation divider $C_{s} = Sensor capacitance $C_{ref} = RefCDACCode * C_{lsb}$ RefCDACCode * C_{lsb} RefCDACCode * C_{lsb} RefCDACCode * C_{lsb} RefCDACCode = Reference CDAC valueCompCDACCode = Compensation CDAC value $C_{lsb} = 8.86fF$ G_{CSD} is given by Equation 56.$$$$$



In both single CDAC and dual CDAC mode, tune the CSD-RM parameters, so that when there is no finger on the sensor, that is when $C_S = C_P$, the raw count = 85% of Maxcount, as Figure 87 shows, to ensure high conversion gain, to avoid Flat-spots, and to avoid raw count saturation due to environmental changes.



Figure 87 Recommended tuning in dual CDAC mode

As Figure 87 shows, the 85% requirement restricts to a fixed gain in single-CDAC mode, while in dual-CDAC mode, gain can be increased by moving the C_S axis intercept to the right (by increasing *CompClk*_{DIV}) and correspondingly decreasing the modulator CDAC switching (*SnsClk*_{DIV}) to still achieve raw count = 85% of Maxcount for $C_S = C_P$. Using dual CDAC mode this way brings the following changes to the Raw Count versus C_P graph:

• Use of compensation CDAC introduces a non-zero intercept on the C_S axis as shown in Equation 59

$$C_S \text{ axis intercept } = \left(\frac{2 \times C_{comp} SnsClk_{Div}}{CompClk_{Div}}\right)$$

Equation 59

C_S axis intercept with regards to C_{comp}

• The value of C_{ref} in the dual CDAC mode is half compared to the value of C_{ref} in the single CDAC mode (all other parameters remaining the same), so the gain G_{CSD} in the dual CDAC mode is double the gain in the single CDAC mode according to Equation 35. Thus, the signal in the dual CDAC mode is double the signal in the single CDAC mode for a given number of sub-conversions (N_{sub}).

While manually tuning a sensor, refer Equation 35, Equation 37 and the following points:

- 1. Higher gain leads to increased sensitivity and better overall system performance. However, do not set the gain such that raw counts saturate, as the plot of gain G_{CSD3} shows in Figure 65. It is recommended to set the gain in such a way that the raw count corresponding to C_P is 85 percent of the maximum raw count for both the single CDAC and dual CDAC mode
- 2. The sense clock frequency (F_{SW}) should be set carefully; higher the frequency, higher the C_S sampling rate which allows for more F_{SW} periods and better noise averaging, but the frequency needs to be low enough to fully charge and discharge the sensor as Equation 41 indicates
- **3.** Enabling the compensation CDAC (baseline compensation) plays a huge role In increasing the gain; it will double the gain if set as recommended in Conversion gain in dual CDAC mode. Always enable Compensation CDAC, make sure the calibrated C_{ref} is in valid range when enabling Compensation CDAC



- **4.** Lower the reference CDAC, higher the gain. Adjust your CDAC to achieve the highest gain, but make sure that the raw counts corresponding to C_P have enough margin for environmental changes such as temperature shifts, as indicated in Figure 66 and Figure 67
- 5. Increasing the number of sub-conversions used for scanning increases gain. An increase in number of sub-conversions also increases the scan time according to Equation 8. A balance of scan time and gain need to be achieved using number of sub-conversions (N_{sub})

5.3.4.1.2 Flat-spots

Ideally, raw counts should have a linear relationship with sensor capacitance as Figure 64 and Figure 67 show. However, in practice, RM converter has non-sensitivity zones, also called flat-spots or dead-zones – for a range of sensor capacitance values, the RM converter may produce the same raw count value as Figure 88 shows. This range is known as a dead-zone or a flat-spot.

Equation 60 shows the flat-spots relation to different CAPSENSE[™] hardware parameters.

Flatspots Width $\alpha \frac{C_s^2}{C_{MOD}} \cdot \frac{F_{SW}}{F_{MOD} \cdot Bal\%}$

Equation 60 Flat-spots width

Where,

C_S = Sensor capacitance

 C_{MOD} = Modulator capacitor

 F_{SW} = Frequency of the sense clock

 F_{MOD} = Modulator clock frequency

Bal% = Rawcount calibration percentage





Flat-spots in raw counts versus sensor capacitance when direct clock is used

Flat-spots reduction techniques

1. Set rawcount calibration to 85%



As per Equation 60, flat-spots width is inversely proportional to calibration level. Setting calibration to 85% decrease the width of flat-spots significantly.

2. Enable dithering

An additional Dither CDAC is available in Fifth-Generation CAPSENSE™ architecture, which adds white noise that moves the conversion point around the flat-spots region.

3. Enable PRS clock

These flat-spots are prominent when direct clock is used as Sense clock source. Flat-spots are reduced if PRS is used as the sense clock source (see also section Using SmartSense to determine hardware parameters). PRS clock can results in a slight reduction of signal or sensitivity at higher rawcount calibration. Recommended to set the rawcount calibration to 65% when PRS is used as clock source.

4. Use larger C_{MOD}

The flat-spots width is inversely proportional to the C_{MOD} used. Fifth-Generation architecture supports C_{MOD} upto 10 nF and typical value is 2.2 nF. And increasing C_{MOD} have the adverse effect of increasing the noise, initialization time and minimum signal required to detect.

5. Increase sense clock divider

Increasing sense clock divider decreases flat-spots width but increases the scan time. If the flat-spot is detected, increase the Sense clock divider such that the scan time requirement is met.

Table 17 lists different the flat-spots reduction techniques in recommended priority and other considerations.

S. No	Flat-spots reduction techniques	Recommendation	Additional benefits	Disadvantage
1	Set rawcount calibration to 85%.	High	Improves sensitivity	-
2	Enable dithering	High	-	-
3	Enable PRS clock	Low	Improves EMI/EMC radiation	Needs to set rawcount calibration to 65%. Decreases sensitivity.
4	Increase C _{MOD}	Low	-	Increases noise
5	Increase sense clock divider	Low	-	Increases scan time and power consumption

 Table 17
 Flat-spots reduction techniques

5.3.4.2 Selecting CAPSENSE[™] hardware parameters

CAPSENSE[™] hardware parameters govern the conversion gain and CAPSENSE[™] signal. Table 18 lists the CAPSENSE[™] hardware parameters that apply to CSD-RM sensing method. The following subsections provide guidance on how to adjust these parameters to achieve optimal performance for CAPSENSE[™] CSD-RM system.

Table 18CAPSENSE™ component hardware parameters

S. No CAPSENSE [™] parameter in ModusToolBox [™]		
1	Scan mode	
2	Scan connection method	
3	Number of Init sub-conversions	
(table contin	ues)	



Table 18 (continued) CAPSENSE [™] component hardware parameters					
S. No	CAPSENSE [™] parameter in ModusToolBox [™]				
4	Sense clock divider				
5	Sense clock source				
6	Modulator clock divider				
7	Reference CDAC value				
8	CDAC compensation divider				
9	Compensation CDAC value				
10	Fine CDAC value				
11	Number of sub-conversions				
12	Enable CDAC dither				

5.3.4.2.1 show selecting the CAPSENSE[™] parameters in Eclipse IDE for ModusToolbox[™]. For more details on configuring CAPSENSE[™], see the Component datasheet/middleware document.

5.3.4.2.1 Manually tuning hardware parameters

Scan mode

Scan mode can be set as CS-DMA or Interrupt Driven mode. For autonomous scanning select DMA mode and for legacy interrupt based scanning select Interrupt Driven mode.

In Fifth-Generation Low-Power CAPSENSE[™], autonomous scanning is supported inherently and does not need CPU intervention, and does not require CTRLMUX and DMA.

Sensor connection method

Autonomous scanning is only available in CTRLMUX method, but the numbers of supported pins are limited in this method (see the Device datasheet for supported pins). Additionally provides better immunity to on-chip IO noise. Choose AMUXBUS method to support more number of pins in Interrupt Driven mode.

In Fifth-Generation Low-Power CAPSENSE[™], all CAPSENSE[™] pins support autonomous scanning mode, via the AMUXBUS, compared to the limited number of pins which were supported by the CTRLMUX in the Fifth-Generation CAPSENSE[™] technology.

Modulator clock frequency

The modulator clock governs the conversion time for capacitance-to-digital conversion, also called the "sensor scan time" (see Equation 8).

A lower modulator clock frequency implies the following:

- Longer conversion time
- Lower peak-to-peak noise on raw count because of longer integration time of the ratiometric converter
- Wider Flat-spots

Select the highest frequency for the shortest conversion time and narrower flat-spots for most cases. Use slower modulator clock to reduce peak-to-peak noise in raw counts if required.



Based on the required Modulator clock frequency (F_{MOD}), calculate the modulator clock divider using Equation 61.

Modulator clock divider = $\frac{F_{Clock}}{F_{MOD}}$

Equation 61 Modulator clock divider

Where,

*F*_{Clock} = Clock frequency connected to CAPSENSE[™] block

Initialization sub-conversions

As part of initialization, C_{MOD1} and C_{MOD2} need to be charged to the required voltage (VDDA/2). There are three phases in initialization – C_{MOD} initialization, C_{MOD} short and initialization sub-conversions. During C_{MOD} initialization phase, C_{MOD1} is pulled to GND and C_{MOD2} is pulled to VDDA. During C_{MOD} short phase both capacitors are tied together so the charge is shared to produce a voltage close to VDDA/2 on both. After these two phases the scanning is started, but rawcount is discarded for the configured number of init subconversions.

The number of init sub-conversions should be selected based on Equation 62.

Number of init subconversions = ceiling
$$\left(\frac{C_{MOD} \times V_{OS}}{VDDA \times C_S \times (1 - Base \%) \times (\frac{1}{Bal\%} - 1)}\right) + 1$$

or
Number of init subconversions = ceiling $\left(\frac{C_{MOD} \times V_{OS}}{VDDA \times SnClkDiv \times C_{ref} \times (1 - Bal\%)}\right) + 1$

Equation 62 Number of init sub-conversions

Where,

 C_{MOD} = Modulator capacitor V_{OS} = Comparator offset voltage (3 mV)Note:Use Vos=4 mV for Automotive grade (E-grade) devices

 $C_{\rm S} = {\rm Sensor \ capacitance}$ Base% = Baseline compensation percentage
Bal% = Rawcount calibration percentage $SnsClk_{\rm Div} = {\rm sense \ clock \ divider}$ $C_{\rm ref} = {\rm Reference \ capacitance}$ $C_{\rm ref} = {\rm RefCDACCode} * C_{\rm lsb}$ RefCDACCode = Reference CDAC value $C_{\rm lsb} = 8.86 \ {\rm fF}$ Note: In the case of CSD, it is recommended not to check the "Enable coarse initialization bypass"
parameter by default. If power requirements are not met, try enabling it but check supply rejection.

Sense clock parameters

There are two parameters that are related to Sense clock: Sense clock source and Sense clock divider.



Sense clock source

Select "Auto" to let the Component automatically choose the best Sense clock source from Direct, PRSx, and SSCx for each widget. If not selecting Auto, select the clock source based on the following:

- Use SSCx (spread spectrum clock) modes for reducing EMI/EMC noise at a particular frequency. This feature is available in PSOC[™] 4S-Series, PSOC[™] 4100S Plus, PSOC[™] 4100PS, PSOC[™] 4100S Max, PSOC[™] 4000T, PSOC[™] 4100T Plus and PSOC[™] 6 family of devices. In this case, the frequency of the sense clock is spread over a predetermined range
- Use Direct clock for absolute capacitance measurement
- Use PRSx (pseudo random sequence) modes to remove flat-spots and improve EMI/EMC radiation. In 5th Generation CAPSENSE[™], PRS clock results in a slight reduction in signal/sensitivity at higher rawcount calibration percent, hence 65% rawcount calibration is recommended when PRS clock is used

When selecting SSCx, you need to select the Sense clock frequency, Modulator clock frequency, and number of sub-conversion such that the conditions mentioned in ModusToolbox[™] CAPSENSE[™] configurator guide for SSCx clock source selection are satisfied.

PRS/SSC can be used to reduce the emissions, but it will increase power consumption as it needs high Nsubs. It is recommended to set Nsubs as 1024(or multiples of 1024) to obtain the maximum spread. If Nsubs are lesser than 1024 or non-multiples of 1024, the performance will be non-optimal.

Sense clock divider

The sense clock divider should be selected so that the sensor will charge and discharge completely in each sense clock period.

This is verified by observing the charging and discharging waveforms of the sensor using an oscilloscope and an active probe. The sensors should be probed close to the electrode and not at the sense pins or the series resistor.

Note: Fifth-Generation CSD-RM charging and discharging happen twice in a single clock period.

Refer to Figure 89 and Figure 90 for waveforms observed on the sensor/shield. Figure 89 shows proper charging when the sense clock frequency is correctly tuned. The pulse width is at least 5Tau, that is, the voltage is reaching at least 99.3% of the required voltage at the end of each phase. Figure 90 shows incomplete settling (charging/discharging). If the charging is incomplete, increase the sense clock divider.





Figure 89

Proper charge cycle of a sensor





Figure 90 Improper charge cycle of a sensor

Note: The sense clock divider should be **divisible by 4**. This ensures that all four scan phases have equal durations.

Repeat this process for all the sensors and the shield. Each sensor may require a different sense clock divider value to charge/discharge completely. But all the sensors that are in the same scan slot need to have the same sense clock source, sense clock divider, and number of sub-conversions. Therefore, take the largest sense clock divider in a given scan slot and apply it to all the other sensors that share that slot. Take this into consideration that a higher sense clock divider increases current consumption as there are longer charging and discharging cycles. Generally, the *C*_P of the shield electrode will be higher compared to the sensor *C*_P.

For good liquid tolerance, the shield signal should satisfy the condition mentioned in the Tuning shield electrode chapter. If it is not satisfied, reduce the sense clock frequency further to satisfy the condition.

Sense clock divider = $\frac{F_{MOD}}{F_{SW}}$

Equation 63 Sense clock divider



Equation 56 shows that it is best to use the maximum clock frequency to achieve higher gain; however, you should ensure that the sensor capacitor fully charges and discharges as shown in Figure 48.

Number of sub-conversions

The number of sub-conversions decides the sensitivity of the sensor and sensor scan time. From Equation 19 for a fixed modulator clock and Sense clock, increasing the number of sub-conversions (N_{Sub}) increases the signal and SNR. However, increasing the number of sub-conversions also increases the scan time of the sensor per Equation 64.

Scan time = $\frac{N_{Sub}}{F_{SW}}$

Equation 64 CSD-RM scan time

Initially, set the value to a low number, and use the Tuner GUI to find the SNR of the sensor. If the SNR is not > 5:1 with the selected, try to increase the in steps such that the SNR requirement is met.

Note: Number of sub-conversions should be greater than or equal to 8 to allow the CDAC dithering to function optimally. When using PRS/SSC it should be multiples of 1024 for optimal performance.

Capacitive DACs

Fifth-Generation CAPSENSETM supports three CDACs: Reference CDAC (C_{ref}), Fine CDAC (Cfine), and Compensation CDAC (C_{comp}) that balance C_{MOD} 's, as Figure 44 shows. These govern the Conversion gain and CAPSENSETM signal for capacitance-to-digital conversion. CAPSENSETM allows the following configurations of the CDACs:

- Enabling or disabling of Compensation CDACs
- Enabling or disabling of Auto-calibration for the CDACs
- Compensation CDAC divider and DAC codes for Reference and Compensation CDACs can be set manually if auto-calibration is disabled

Table 19 is applicable only for fifth-generation low-power which showcases different numbers of valid CDAC combinations that can be set in the CAPSENSE[™] configurator.

Sr. no.	C _{ref}	C _{fine}	C _{comp}
1	Auto	Auto	Auto
2	Auto	Auto	Disabled
3	Auto	Disabled	Auto
4	Auto	Disabled	Disabled
5	Value	Value	Auto
6	Value	Value	Value
7	Value	Value	Disabled
8	Value	Disabled	Auto
9	Value	Disabled	Value

Table 19Valid CDAC configurations

(table continues...)



Table 19 (continued) Valid CDAC configurations				
Sr. no.	C _{ref}	C _{fine}	C _{comp}	
10	Value	Disabled	Disabled	
11	Disabled	Auto	Auto	
12	Disabled	Auto	Disabled	
13	Disabled	Value	Auto	
14	Disabled	Value	Value	
15	Disabled	Value	Disabled	

Note: It is recommended to always enable auto-calibration for the CDACs. This will ensure optimal tuning.

 C_{ref} boost parameter can be used to adjust the sensitivity of reference CAPDAC, which can be used only with combinations 1 and 3, where Compensation CDAC (C_{comp}) and reference CAPDAC are set to "Auto".

Capacitive DACs scaling

CDACs have some inherent tolerance which could lead to variation in the Signal observed across units. To aid in minimizing this variation, MSCLP devices have CDAC trim codes in SFLASH (read-only). This code is used to scale the Reference CDAC and Fine CDAC parameters, which compensates for variations in the CDAC and brings down the overall signal variation across units

Note: This feature is currently applicable to the PSOC[™] 4100T Plus device only.

The effective parasitic capacitance (Cp) of the sensor mainly depends on Csensor & Cpin,

- Csensor: capacitance of the sensor electrode & traces excluding the device pin
- Cpin: Capacitance of the device pin

Note: The measured Cp in capacitance for $PSOC^{m}$ 4100T Plus is ~2.77 pF.

When the effective Cp measured out of BIST is very small (<4pF), the Cpin capacitance becomes a significant contributor to the Cp and has an impact on signal variation.

To mitigate this issue, the middleware reads and utilizes the trim codes stored in the device SFLASH memory to scale the CDAC values; specifically Reference CDAC (Cref) and Fine CDAC (Cfine).

CDAC scaling is appliable only in the following scenarios,

- Sensor Cp is less than 4pF
- Widget type is CSD (regular and low power)
- Reference CDAC and Fine CADC are set to 'Manual' mode

Note: If sensor Cp is more than 4pF configure CDAC tuning mode as 'Auto'.

Tuning recommendation

For a step-by-step guide on the tuning procedure, please refer to Stage 3 of the code example Readme for CE238886 – PSOC[™] 4: MSCLP low-power self-capacitance button.



Reference CDAC (Cref)

The reference CDAC is used to compensate for the charge transferred by the sensor self-capacitance (C_S) from the C_{MOD} . The number of times it is switched depends on the self-capacitance of the sensor. In the case of a finger placed over the sensor, additional reference CDAC switching is required to compensate.

C_{ref} is calculated using the following equation:

 $C_{\rm ref}$ = Reference capacitance = RefCDACCode * $C_{\rm lsb}$

Where,

RefCDACCode = Reference CDAC value

 $C_{lsb} = 8.86 \text{ fF}$

*C*_{ref} should satisfy the below criteria:

RefCDACCode > 6

If the auto-calibrated RefCDACCode is less than 6, then enable fine CDAC.

The following options can be used to increase the RefCDACCode,

- Decrease the sense clock divider. Note that the pulse width of the sense clock should be long enough to allow the sensor capacitance to charge and discharge completely. This decreased sense clock can be accommodated by decreasing series resistance or decreasing shield Cp
- Disable compensation

Fine Reference CDAC (Cfine)

The fifth-generation low-power CAPSENSE[™] consists of a Fine CDAC, which is a programmable CDAC used to achieve a finer resolution for the Reference CDAC. Hence, enabling Cfine along with Cref increases the accuracy. It is recommended to always enable auto-calibration for Fine CDAC to ensure optimal performance.

 C_{fine} = Fine Reference CDAC = FineCDACCode * C_{lsb} FineCDACCode = Fine CDAC value C_{lsb} = 2.2 nF

Compensation CDAC (Ccomp)

Enabling the compensation CDAC is called "dual CDAC" mode, and results in increased signal as explained in Conversion gain and CAPSENSE[™] signal. Enable the compensation CDAC for most cases.

The compensation capacitor is used to compensate excess self-capacitance from the sensor to increase the sensitivity. The number of times it is switched depends on the amount of charge the user application is trying to compensate (remove) from the sensor self-capacitance.

Compensation CDAC divider

The number of times the compensation capacitor is switched in a single sense clock is denoted by K_{comp} . Select CDAC compensation divider based on Equation 65 such that below criteria is satisfied.

- **1.** CDAC compensation divider >= 4
- **2.** K_{comp} should be a whole number

CDAC compensation divider = $\frac{Sense \ clock \ divider}{K_{comp}}$

Equation 65

CDAC compensation divider

Application note



Auto-calibration

The auto-calibration feature enables the firmware to automatically calibrate the CDAC to achieve the required calibration target of 85%. It is recommended to enable auto-calibration for most cases. Enabling this feature will result in the following:

- Default calibration is set to 85% of maximum raw count even with part-to-part CP variation
 - *Note:* If the raw counts are saturating at 85%, the calibration percentage can be reduced further to avoid saturation.
- Decrease the effect of Flat-spots

If your design environment includes large temperature variation, you may find that the 85% CDAC calibration level is too high, and that the raw counts saturate easily over large changes in temperature, leading to lower SNR. In this case, adjust the calibration level lower by using Cy_CapSense_CalibrateAllSlots() in your firmware.

For proper functioning of CAPSENSETM under diverse environmental conditions, it is recommended to avoid very low or high CDAC codes. For an 8-bit CDAC, it is recommended to use CDAC codes between 6-200 from the possible 0 to 255 range. You can use CAPSENSETM tuner to confirm that the auto-calibrated CDAC values fall in this recommended range. If the CDAC values are out of the recommended range, based on Equation 55, Equation 56, and Equation 58, you may change the Calibration level or F_{mod} or F_{SW} to get the CDAC code in proper range.

Selecting CDAC codes

This is not the recommended approach. However, this approach could be used only if you want to disable autocalibration for any reason. To get the CDAC code, you may first configure CAPSENSE[™] Component with autocalibration enabled and all other hardware parameters the same as required for final tuning and read back the calibrated CDAC values using Tuner GUI. Then, re-configure the CAPSENSE[™] Component to disable autocalibration and use the obtained CDAC codes as fixed DAC codes read-back from the Tuner GUI.

CDAC dither

As the input capacitance is swept, the raw count should increase linearly with capacitance. There are regions where the raw count does not change linearly with input capacitance, and these are called flat-spots. See section Flat-spots for more details. Dithering helps to reduce flat-spots. This is done using a dither CDAC. The dither CDAC adds white noise that moves the conversion point around the flat region.

It is recommended to always enable CDAC dither scale in auto-calibrated mode to ensure optimal performance. In case it is required to set the CDAC dither scale manually, see the following table for general recommended values.

Table 20	Dither scale recommendation for CSD sensors
----------	---

Parasitic Capacitance (C _p)	Scale		
2 pF <= C _p < 3 pF	3		
3 pF <= C _p < 5 pF	2		
5 pF <= C _p < 10 pF	1		
C _p >= 10 pF	0		

For details on setting dither related parameters, refer to the Readme of code example PSOC[™] 4: MSCLP CAPSENSE[™] low power (section '**Stage 2: Measure sensor capacitance to set CDAC Dither parameter**')



5.3.4.2.2 Tuning shield electrode

The shield related parameters need to be additionally configured or tuned differently when you enable the Shield electrode in the CSD-RM sensing method for liquid tolerance or reducing the C_p of the sensor.

Shield electrode tuning theory

Ideally, the shield waveform should be exactly the same as that of the sensor as explained in CAPSENSE[™] CSDRM shielding. However, in practical applications, the shield waveform may have a higher settling time. Observe the sensor and shield waveform in the oscilloscope; an example waveform is shown in Figure 91 and Figure 92. The shield waveform should settle to the sensor voltage within 90% of ON time of the sense clock waveform and the overshoot error of the shield signal with respect to VREF should be less than 10%.

If these conditions are not satisfied, you will observe a change in raw count of the sensors when touching the shield hatch; in addition, if inactive sensors are connected to shield as mentioned in Inactive sensor connection, touching one sensor can cause change in raw count on other sensors, which indicates that there is cross talk if the shield electrode is not tuned properly.

Note: The sense clock divider should be **divisible by 4**. This ensures that all four scan phases have equal durations.

Keep in mind that the higher sense clock divider increases current consumption as there is longer charging and discharging cycles. Generally, the C_P of the shield electrode will be higher compared to the sensor C_P . For good liquid tolerance, approximate maximum shield frequency (F_{Shield}) ensures correct charging and discharging of the shield waveform. If it is not satisfied, reduce the sense clock frequency further to satisfy the condition.

In SmartSense, the sense clock frequency is automatically set. Check if these conditions are satisfied. If not satisfied, switch to Manual tuning and set the sense clock frequency manually so that these conditions are satisfied.











Figure 92 Properly tuned shield waveform (passive shielding)

Tuning shield-related parameters

Inactive sensor connection

When the shield electrode is enabled for liquid-tolerant designs, or if you want to use shield to reduce the sensor parasitic capacitance, this option should be specified as "Shield"; otherwise, select "Ground".

However, there is a risk of higher radiated emission due to inactive sensors getting connected to Shield. In such situations, use the CAPSENSE[™] API to manually control inactive sensor connections. Instead of connecting all unused sensors to the shield, connect only the opposing inactive sensors or inactive sensors closer to the sensor being scanned to shield for reducing the radiated emission.

Number of shield electrodes (total shield count)

This parameter specifies the number of shield electrodes required in the design. Most designs work with one dedicated shield electrode; however, some designs require multiple dedicated shield electrodes for ease of PCB layout routing or to minimize the PCB real estate used for the shield layer. See Layout guidelines for shield electrode Layout guidelines for shield.

Shield mode

The Fifth-Generation CAPSENSE[™] architecture supports two shield modes – active and passive shielding. See CAPSENSE[™] CSDRM shielding section to decide which mode is best suited for your application.



5.3.4.2.3 Selecting CAPSENSE[™] software parameters

CAPSENSE[™] software parameters in Fifth-Generation are the same as that for Fourth-Generation; therefore, these parameters could be selected as mentioned in Selecting CAPSENSE[™] software parameters section.

5.3.4.2.4 Configuring autonomous scan

Autonomous scanning improves CPU offloading by removing the requirement of CPU intervention in between sensor scans. Figure 93 shows the waveform of scanning all slots, which shows the CAPSENSE[™] CPU bandwidth requirement for autonomous scanning and interrupt driven scanning. In autonomous scan once the CPU initiates a command to scan all slots, there is no CPU interrupt raised by CAPSENSE[™] until all the slots are scanned. But in interrupt driven scan, after each slot scan, a CPU interrupt is raised to configure the next slot sensors.





Figure 93 Autonomous Scanning versus Interrupt Driven Scanning

In fifth-generation CAPSENSE[™], autonomous scanning is only available when Scan mode is set as Chained Scanning – DMA (CS-DMA) in the CAPSENSE[™] configurator as shown in Figure 94. And sensor connection method is only available as CTRLMUX. This limits the number of available CAPSENSE[™] sensors. In Interrupt driven mode, sensor connection can be configured as either AMUXBUS or CTRLMUX. Through AMUXBUS any GPIO pin can be configured as a CAPSENSE[™] sensor,but CPU interrupts need to be serviced to read the scan result and configure the next sensor.



Basic Advanced Scan Config	uration				
General CSD Settings CSX	Settings Widget Details				
Scan settings	INT driven		Regular widget raw count filter type		
Scan mode:	CS-DMA		Enable IIR filter (First order)		
Sensor connection method:	CTRLMUX		IIR filter raw count coefficient: 128		
Modulator clock divider:	100 ry: 480		Enable median filter (3-sample)		
Actual modulator clock frequence			Enable average filter (4-sample)		
Enable sensor auto-reset			Baseline IIR filter settings		
Enable self-test library			Regular widget baseline coefficient: 1		
Enable multi-frequency scan					

Figure 94 CAPSENSE[™] configurator settings for scan mode

In fifth-generation low-power CAPSENSE[™] regular widgets are scanned autonomously by default. CPU can remain in deep sleep mode while the scanning happens. An interrupt can wake the CPU to process the data, after all the slots are scanned Low power widgets are scanned using the low-power always-on-sense (LP-AoS) mode as explained in LP-AoS mode.

Autonomous scanning

Autonomous scanning mode in Fifth-Generation CAPSENSE[™] technology avoids the CPU intervention for scanning every next sensor. This significantly reduces the CPU bandwidth required for scanning widgets withlarge number of sensors. Based on the CAPSENSE[™] generation there are the following methods of autonomous scanning - Chained scanning – DMA mode and LP-AoS mode.

Chained scanning – DMA mode

In the chained scanning - DMA mode, DMA handles the configuration of each sensor, thereby avoiding the requirement of CPU intervention after each sensor scan completion. Each channel of MSC block requires four channels of DMA to be configured in the device configurator as shown in Figure 95.



Peripherals Pins Analog-Routing	System Peripheri	MSC 0 (CYBSP_MSC0) - Parameters		ළ ව
Enter filter text 🖉 🌹 🎚	• • * • •	Enter filter text		2 🖸 🖻 🖽
lesource	Name(s)	Name	Value	7
Analog Programmable Analog 12-bit SAR ADC 0	pass 0 sar 0	Peripheral Documentation Onfiguration Help	Open	MSC Documentation
Communication Digital	pass_0_sar_0	Inputs Clock Signal DMA connections	в	16 bit Divider 0 clk (CYBSP_MSC_CLK_DIV) [SHARED]
 ✓ System ✓ CapSense 	msc_0_msc_superblock_0	Write DMAC Channel Trigger Output	8	DMAC Channel 0 tr_out [USED]
MSC 0	CYBSP_MSC0	Chain Write DMAC Channel Trigger Input	P	DMAC Channel 1 tr_in [USED]
MSC 1	CYBSP_MSC1	Read DMAC Channel Trigger Output	8	DMAC Channel 3 tr_out [USED]
Watchdog Counters (WDC)	wco_0_wdc_0	Chain Read DMAC Channel Trigger Input	P	DMAC Channel 2 tr_in [USED]
Watchdog Timer (WDT)	srss_0_wdt_0	Sensors		0.470 L 0.6750
Notice List	0 Tasks 🚺 0 Infos	MSC 0 (CYBSP_MSC0) - Parameters Code Preview		Ø (
Fix Description				Location

Figure 95 DMA configuration for MSC channels

Figure 96 illustrates the flow of CS-DMA based scanning mode.

1. Write DMA channel

Write DMA is configured to transfer scan configuration of a sensor to MSC block. Source address to the corresponding sensor's scan configuration is received from Chain Write DMA channel

- Chain Write DMA channel
 When the MSC block completes scanning of current sensor, it will trigger the DMA to transfer the source address of next sensor's or first sensor's (if it is a new scan) scan configuration to the Write DMA channel
- Read DMA channel
 Read DMA channel transfer the scan result (rawcount) to destination location of corresponding sensor
- **4.** Chain Read DMA channel

Once the current sensor scan is completed by MSC block, Chain Read DMA is triggered to transfer the destination location (address) of current sensor scan result (rawcount) to the Read DMA channel





Figure 96 CS-DMA scanning flow

LP-AoS mode

The fifth-generation CAPSENSE[™] (MSCLP) performs autonomous sensing using the LP-AoS hardware mode. Using this mode, multiple sensors (a frame) can be scanned without the intervention of the CPU. To enable this, the MSCLP block has an internal 1-KB SRAM. The middleware writes the configuration of multiple sensors to be scanned to the internal SRAM. Then, the MSCLP autonomously reads each sensor configuration, initiates scanning, and saves the result to the SRAM for the middleware to read and process after full-frame scanning is completed.

The device can be kept in any device power modes such as active, sleep, or deep sleep while MSCLP is scanning multiple sensors. MSCLP has all the system resources such as high-frequency clock and reference generator internal to the MSCLP hardware to enable scanning in device low-power state (i.e., deep sleep).



Wake-on-Touch (WoT)

LP-AoS has the additional capability of scanning the same frame periodically and processing the result to detect touch. Therefore, the CPU is not required to process or initiate scanning; this allows the PSOC[™] device to be kept in deep sleep for a longer time and to have the sensor touch detection as a wakeup interrupt. This is known as Wake-on-Touch. With this approach, the application can get the lowest power consumption with touch-sensing capability. Note that WoT is only supported for Low-Power Widgets. See section Low-power widget tuning for details on Low-Power Widgets.





5.3.4.2.5 Multi-channel scanning

Multi-channel design uses both the instances of CAPSENSE[™] MSC0 and MSC1, leading to simultaneous operation and reduction in scan time. Multi-channel scanning is in lock step thereby avoiding any cross-channel noise coupling. Scan synchronization is required to have the scanning in lock step. Fifth-Generation CAPSENSE[™] technology has built in ability for multi-channel synchronization and CPU is not required for this.

Multi-channel operation is an added advantage to support applications such as large touchpad, which require many sensor pins for interfacing. For example, a 6x8 touchpad can be configured as shown in Figure 98. In this figure, the sensors shown in blue color is scanned by channel 0 (MSC0) and green color is scanned by channel 1 (MSC1).





Figure 98 Scanning 6x8 CSD touchpad using multi-channel

In this case, channel 0 and channel 1 can scan one of its sensors at the same time. To avoid any cross-talk noise, sensors to be scanned together should be selected such that the physical distance between the two sensor is as maximum as possible, and should avoid combining row and column sensors.

In the above example, the recommended scan configuration is as shown in Table 21. All the sensors that belong to same slot is scanned together.

Slot #	Channel 0 sensor	Channel 1 sensor	
Slot 0	Col 0	Col 4s	
Slot 1	Col 1	Col 5	
Slot 2	Col 2	Col 6	
Slot 3	Col 3	Col 7	
Slot 4	Row 0	Row 3	
Slot 5	Row 1	Row 4	
Slot 6	Row 2	Row 5	

Table 21Channel scan configuration



5.3.4.2.6 Button widget tuning

Button widget tuning section provides high-level steps for tuning CSD button. The CE231078 PSOC[™] 4: MSC CAPSENSE[™] CSD Button Tuning explains tuning of self capacitance-based button widgets in the Eclipse IDE for ModusToolbox[™]. For details on the Component and all related parameters, see the Component datasheet.

5.3.4.2.7 Slider widget tuning

Slider widget tuning section provides high-level steps for tuning CSD slider. The CE232776 PSOC[™] 4: MSC CAPSENSE[™] CSD slider tuning explains tuning of self-capacitance-based slider widgets in the Eclipse IDE for ModusToolbox[™]. For details on the Component and all related parameters, see the Component datasheet.

5.3.4.2.8 Touchpad widget tuning

Refer to the AN234185 PSOC[™] 4 CAPSENSE[™] Touchpad design guide for touchpad hardware and firmware design guidelines, along with tuning guidelines. The CE235338 PSOC[™] 4: MSCLP self-capacitance touchpad tuning code example explains the tuning of self-capacitance-based touchpad widgets in the Eclipse IDE for ModusToolbox[™].

For details on the PSOC[™] Creator based CAPSENSE[™] Component and all related parameters, see the Component datasheet.

5.3.4.2.9 Proximity widget example

For tuning a proximity sensor, see AN92239 - Proximity sensing with CAPSENSE™.

5.3.4.2.10 Low-power widget tuning

The CE235111 – PSOC[™] 4: MSCLP CAPSENSE[™] low power CSD Button Tuning explains the tuning of a low-power widget in the Eclipse IDE for ModusToolbox[™].

5.3.5 CSX-RM sensing method (fifth-generation and fifth-generation lowpower)

This section explains the basics of manual tuning using the CSX-RM sensing method for the fifth-generation and fifth-generation low-power devices. It also explains the hardware parameters that influence the manual tuning procedure.

5.3.5.1 Basics

5.3.5.1.1 Conversion gain and CAPSENSE[™] signal

Conversion gain influences how much signal count the system observes for a finger touch on the sensor. If there is more gain, the signal is higher, and a higher signal means a higher achievable Signal-to-noise ratio (SNR). Note that an increased gain may result in an increase in both signal and noise. However, if required, you can use firmware filters to decrease noise. For details on available firmware filters, see Table 11.

Conversion gain in single CDAC

In a mutual-capacitance sensing system, the rawcount counter is directly proportional to the mutualcapacitance between the Tx and Rx electrodes, as Equation 66 shows.



 $Rawcount_{counter} = G_{CSX}C_M$

Equation 66 Raw count relationship to sensor capacitance

Where,

G_{CSX} = Capacitance to digital conversion gain of CAPSENSE[™] CSX

 $C_{\rm M}$ = Mutual-capacitance between the Tx and Rx electrodes

Equation 38 shows the relationship between raw count and mutual-capacitance of the CSX sensor. The tunable parameters of the conversion gain in Equation 67 are C_{ref} , $TxClk_{Div}$ and N_{Sub} .

The approximate value of this conversion gain is:

$$G_{CSX} = MaxCount \frac{2}{C_{ref}TxClk_{Div}}$$

Equation 67 Capacitance to digital converter gain

Where, MaxCount = $N_{Sub} * TxClk_{Div}$

The equation for raw count in the single CDAC mode, according to Equation 66 and Equation 67 is shown in Equation 68.

$$Rawcount_{Counter} = N_{Sub} \frac{2 \times C_M}{C_{ref}}$$

Equation 68 Single CDAC mode raw counts

Where,

 N_{Sub} = Number of sub-conversions $TxClk_{Div}$ = Tx clock divider C_{M} = Sensor mutual-capacitance RefCDACCode = Reference CDAC value C_{Isb} = 8.86 fF

The tunable parameters of the conversion gain are C_{ref} , $TxClk_{Div}$, and N_{Sub} .



Figure 99

Voltage at Tx node of the CSX sensor

Note: The raw count observed from the Component is given by Equation 69. See CAPSENSE[™] CSX-RM sensing method (fifth-generation and fifth-generation low-power) for more details on Rawcount_{component}.



 $Rawcount_{Component} = MaxCount - Rawcount_{Counter}$

Equation 69 Rawcount_{component}



Figure 100 Raw count vs sensor mutual-capacitance

Conversion gain in dual CDAC mode

The equation for raw count in the dual CDAC mode, according to Equation 27 and Equation 66 is shown in Equation 70.

$$rawcount = G_{CSX}C_M - Maxcount \frac{2 \times C_{comp}}{C_{ref}CompCLK_{div}}$$

Equation 70 Dual CDAC mode raw counts

Where, Maxcount = $N_{Sub} * SnsClk_{Div}$ $SnsClk_{Div}$ = Sense clock divider N_{Sub} = Number of sub-conversions C_{ref} = Reference capacitance = RefCDACCode* C_{lsb} C_{comp} = Compensation capacitance = CompCDACCode* C_{lsb} $CompCLK_{Div}$ = CDAC compensation divider C_{M} = Sensor mutual-capacitance RefCDACCode = Reference CDAC value CompCDACCode = Compensation CDAC value C_{lsb} = 8.86 fF G_{CSX} is given by Equation 67

5.3.5.2 Selecting CAPSENSE[™] hardware parameters

CAPSENSE[™] hardware parameters govern the conversion gain and CAPSENSE[™] signal. Table 22 lists the CAPSENSE[™] hardware parameters that apply to the CSX-RM sensing method for the fifth-generation devices.



Table 22 CAPSENSE [™] component hardware parameters		
S. No	CAPSENSE™ parameter in ModusToolBox™	
1	Tx clock divider	
2	Tx clock source	
3	Modulator clock divider	
4	Reference CDAC value	
5	CDAC compensation divider	
6	Compensation CDAC value	
7	Fine CDAC value	
8	Number of sub-conversions	
9	Enable CDAC dither	

5.3.5.2.1 Scan mode

Scan mode can be set as CS-DMA or Interrupt Driven mode. For autonomous scanning select DMA mode and for legacy interrupt based scanning select Interrupt Driven mode.

In fifth-generation low-power CAPSENSE[™], autonomous scanning is supported inherently and does not need CPU intervention, and does not require CTRLMUX and DMA.

5.3.5.2.2 Sensor connection method

Autonomous scanning is only available in the CTRLMUX method, but the number of supported pins are limited in this method (see the Device datasheet for supported pins). Additionally, this method provides better immunity to on-chip I/O noise. Choose the AMUXBUS method to support more number of pins in the Interrupt Driven mode.

In the CTRLMUX connection method for CSX sensors, choose the inactive sensor connection as VDDA/2 and ensure to add empty scan slots before the first sensor scan for initializing the voltages on Rx lines to VDDA/2.

In fifth-generation low-power CAPSENSE[™], all CAPSENSE[™] pins support the autonomous scanning mode, via the AMUXBUS, compared to the limited number of pins, which were supported by the CTRLMUX in the fifth-generation CAPSENSE[™] technology.

5.3.5.2.3 Modulator clock frequency

It is best to choose the highest allowed clock frequency for the given device because a higher modulator clock frequency leads to a higher sensitivity/signal, increased accuracy, and lower noise for a given $C_{\rm M}$ to digital count conversion as Equation 66 and Equation 67 indicates. Also, a higher value of $F_{\rm MOD}/F_{\rm TX}$ ensures lower width of Flat-spots in $C_{\rm M}$ to raw count conversion.

5.3.5.2.4 Initialization sub-conversions

As part of initialization, C_{MOD} s need to be charged at the required voltage (VDDA/2). There are three phases in initialization – C_{MOD} initialization, C_{MOD} short, and initialization sub-conversions. During the C_{MOD} initialization phase, C_{MOD1} is pulled to GND and C_{MOD2} is pulled to VDDA. During the C_{MOD} short phase, both capacitors are tied together so the charge is shared to produce a voltage close to VDDA/2 on both. After the two phases, the scanning is started but rawcount is discarded for a specific number of init sub-conversions.


Select the number of init sub-conversions based on Equation 71.



Equation 71 Number of init sub-conversions

Where,

 C_{MOD} = Modulator capacitor

V_{OS} = Comparator offset voltage (3 mV of PSOC[™] 4100S Max device)

Note: Use Vos = 4 mV for Automotive grade (E-grade) devices

 $C_{\rm M}$ = Sensor mutual-capacitance

Base% = Baseline compensation percentage

Bal% = Rawcount calibration percentage

 C_{ref} = Reference capacitance = RefCDACCode * C_{lsb}

RefCDACCode = Reference CDAC value

 $C_{lsb} = 8.86 \text{ fF}$

Note: In the case of CSX, it is recommended not to check the "Enable coarse initialization bypass" parameter.

5.3.5.2.5 Tx clock parameters

There are two parameters that are related to the Tx clock: Sense clock source and Sense clock frequency.

Tx clock source

Select "Auto" as the clock source for the Component to automatically select the best Tx clock source between Direct and Spread Spectrum Clock (SSCx) for each widget. If the "Auto" option is not selected, then choose the clock source based on the following:

- Direct Clock signal with a fixed-clock frequency. Use this option for most cases
- Spread spectrum clock (SSCx) If you choose this option, the Tx clock signal frequency is dynamically spread over a predetermined range. Use this option for reduced EMI interference and avoiding flat-spots. However, when selecting the SSCx clock, ensure to select the Tx clock frequency, modulator clock frequency, and number of sub-conversions such that the conditions mentioned in Component datasheet/ ModusToolbox™ CAPSENSE™ configurator guide for the SSCx clock source selection are satisfied
- Pseudo Random Sequence (PRSx) Use PRSx (pseudo random sequence) modes to remove flat-spots and improve EMI/EMC radiation and susceptibility. In 5th Generation CAPSENSE[™], PRS clock introduces signal/ sensitivity loss at higher rawcount calibration percent, hence 65% rawcount calibration is recommended when PRS clock is used

When selecting SSCx, you need to select the Sense clock frequency, Modulator clock frequency, and number of sub-conversions such that the conditions mentioned in the ModusToolbox[™] CAPSENSE[™] configurator guide for SSCx clock source selection are satisfied.



PRS/SSC can be used to reduce the emissions, but it increases power consumption as it needs high Nsubs. It is recommended to set Nsubs as 1024 (or multiples of 1024) to obtain the maximum spread. If Nsubs are lesser than 1024 or non-multiples of 1024, the performance will be non-optimal.

Tx clock frequency

The Tx clock frequency determines the duration of each sub-conversion, as explained in the CAPSENSE[™] CSX-RM sensing method (fifth-generation) section. The Tx clock divider should be configured such that the pulse width of the Tx clock is long enough to allow the sensor capacitance to charge and discharge completely. This is verified by observing the charging and discharging waveforms of the sensor using an oscilloscope and an active probe. The sensors should be probed close to the electrode and not at the sense pins or the series resistor.

Refer to Figure 101 and Figure 102 for waveforms observed on the sensor/shield. Figure 101 shows proper charging when the sense clock frequency is correctly tuned. The pulse width is at least 5Tau, that is, the voltage is reaching at least 99.3% of the required voltage at the end of each phase. Figure 102 shows incomplete settling (charging/discharging). If the charging is incomplete, increase the Tx clock divider.



Figure 101

Proper charge cycle of a CSX sensor







Note: The sense clock divider should be **divisible by 2**. This ensures that both scan phases have equal durations.

Repeat this process for all the sensors and the shield. Each sensor may require a different Tx clock divider value to charge/discharge completely. But all the sensors that are in the same scan slot need to have the same Tx clock source, Tx clock divider, and number of sub-conversions. Therefore, take the largest Tx clock divider in a given scan slot and apply it to all the other sensors that share the slot.

Additionally, if you are using the SSCx clock source, ensure that you select the Tx clock frequency that meets the conditions mentioned in the Component datasheet/middleware document/ModusToolbox™ CAPSENSE™ Configurator user guide in addition to these conditions.

5.3.5.2.6 Number of sub-conversions

The number of sub-conversions decides the sensitivity of the sensor and sensor scan time. From Equation 27 for a fixed modulator clock and Tx clock, increasing the number of sub-conversions (N_{Sub}) increases the signal and SNR. However, increasing the number of sub-conversions also increases the scan time of the sensor.

Initially, set the value to a low number (for example, 20), and use the Tuner GUI to find the SNR of the sensor. If the SNR is not > 5:1 with the selected N_{Sub} , increase then N_{Sub} in steps such that the SNR requirement is met.

Note: Number of sub-conversions should be greater than or equal to 8 to allow the CDAC dithering to function optimally. When using PRS/SSC it should be multiples of 1024 for optimal performance.

5.3.5.2.7 Capacitive DACs

In the fifth-generation technology, CSX-RM supports three CDACs: Reference CDAC (C_{ref}), Fine CDAC (Cfine) and Compensation CDAC (C_{comp}), that balance C_{MOD} s as Equation 8 shows. These govern the Conversion gain and CAPSENSETM signal for capacitance-to-digital conversion. CAPSENSETM allows the following configurations of the CDACs:

• Enabling or disabling of Compensation CDACs



- Enabling or disabling of Auto-calibration for the CDACs
- Compensation CDAC divider, DAC code selection for Reference and Compensation CDACs if auto-calibration is disabled

Table 23 is only applicable for fifth-generation low power, which shows the different numbers of valid CDAC combinations that can be set in the CAPSENSE[™] Configurator.

Sr. no.	C _{ref}	C _{fine}	C _{comp}
1	Auto	Auto	Auto
2	Auto	Auto	Disabled
3	Auto	Disabled	Auto
4	Auto	Disabled	Disabled
5	Value	Value	Auto
6	Value	Value	Value
7	Value	Value	Disabled
8	Value	Disabled	Auto
9	Value	Disabled	Value
10	Value	Disabled	Disabled
11	Disabled	Auto	Auto
12	Disabled	Auto	Disabled
13	Disabled	Value	Auto
14	Disabled	Value	Value
15	Disabled	Value	Disabled

Table 23Valid CDAC configurations

Note: It is recommended to always enable auto-calibration for the CDACs. This ensures optimal tuning.

Reference CDAC (C_{ref})

The reference CDAC is used to compensate the charge transferred by the sensor mutual-capacitance (C_M) from C_{MOD} . The number of times it is switched depends on the mutual-capacitance of the sensor.

C_{ref} is calculated using the following equation:

 $C_{\rm ref}$ = Reference capacitance = RefCDACCode * $C_{\rm lsb}$

Where,

RefCDACCode = Reference CDAC value

 $C_{lsb} = 8.86 \text{fF}$

*C*_{ref} should satisfy below criteria:

RefCDACCode > 6

If the auto-calibrated RefCDACCode is less than 6, then enable fine CDAC.

The following options can be used to increase the RefCDACCode,

- Decrease the Tx clock divider. Note that the pulse width of the Tx clock should be long enough to allow the sensor capacitance to charge and discharge completely. This decreased Tx clock can be accommodated by decreasing series resistance or decreasing shield Cp
- Disable compensation



Fine Reference CDAC (C_{fine})

The fifth-generation low-power CAPSENSE[™] consists of Fine CDAC, which is a programmable CDAC used to achieve finer resolution for the Reference CDAC. Hence, enabling Cfine along with Cref increases the accuracy. It is recommended to always enable auto-calibration for Fine CDAC, to ensure optimal performance.

C_{fine} = Fine Reference CDAC = FineCDACCode * C_{lsb} FineCDACCode = Fine CDAC value

FINECDACCODE - FINE CDAC V

C_{lsb} = 2.2 nF

Compensation CDAC (C_{comp})

Enabling the compensation CDAC is called "dual CDAC" mode, and results in increased signal as explained in Conversion gain and CAPSENSE[™] signal. Enable the compensation CDAC for most cases.

The compensation capacitor is used to compensate excess mutual-capacitance from the sensor to increase the sensitivity. The number of times it is switched depends on the amount of charge the user application is trying to compensate from the sensor mutual-capacitance.

5.3.5.2.8 Compensation CDAC divider

The number of times the compensation capacitor is switched in a single sense clock is denoted by K_{comp} . Select CDAC compensation divider based on below Equation 72 such that below criteria is satisfied:

- **1.** CDAC compensation divider >= 4
- **2.** K_{comp} should be a whole number

CDAC compensation divider = $\frac{Tx \ clock \ divider}{K_{comp}}$

Equation 72 CDAC compensation divider

5.3.5.2.9 Auto-calibration

This feature enables the firmware to automatically calibrate the CDAC to achieve the required calibration target of 40%. It is recommended to enable auto-calibration for most cases. Enabling this feature will result in the following:

Fixed raw count calibration to 40% of max raw count even with part-to-part C_M variation

Decrease the effect of Flat-spots

Automatically selects the optimum gain

For proper functioning of CAPSENSETM under diverse environmental conditions, it is recommended to avoid very low or high CDAC codes. You can use CAPSENSETM tuner to confirm that the auto-calibrated CDAC values fall in this recommended range. If the CDAC values are out of the recommended range, based on Equation 66, Equation 67, and Equation 69, you may change the Calibration level or F_{mod} or F_{SW} to get the CDAC code in proper range.

5.3.5.2.10 Selecting CDAC codes

This is not the recommended approach. However, this could be used only if you want to disable autocalibration for any reason. To get the CDAC code, you may first configure CAPSENSE[™] Component with autocalibration enabled and all other hardware parameters the same as required for final tuning and read back the calibrated CDAC values using Tuner GUI. Then, re-configure the CAPSENSE[™] Component to disable autocalibration and use the obtained CDAC codes as fixed DAC codes read-back from the Tuner GUI.



5.3.5.2.11 CDAC dither

As the input capacitance is swept, the raw count should increase linearly with capacitance. However, there are regions called flat-spots where the raw count does not change linearly with input capacitance (refer to section Flat-spots for more details). Dithering, with the help of a dither CDAC, helps to reduce flat-spots. The dither CDAC adds white noise that moves the conversion point around the flat region.

It is recommended to always enable CDAC dither scale in auto-calibrated mode to ensure optimal performance. In case it is required to set the CDAC dither scale manually, see the following table for general recommended values.

Table 24 Dither Scale Recommendation for CSX sensors

Mutual Capacitance (C _m)	Scale
300 fF <= C _m < 500 fF	5
500 fF <= C _m < 1000 fF	4
1000 fF <= C _m < 2000 fF	3
C _m >= 2 pF	Follow Table 20

For details on setting dither related parameters, refer to the PSOC[™] 4: MSCLP CAPSENSE[™] low power (section '**Stage 2: Measure sensor capacitance to set CDAC Dither parameter**') code example.

5.3.5.3 Selecting CAPSENSE[™] software parameters

CAPSENSE[™] software parameters in the fifth-generation are the same as that for fourth-generation; therefore, these parameters can be selected as mentioned in the Selecting CAPSENSE[™] software parameters section.

5.3.5.4 Configuring autonomous scan

Configuring autonomous scan in CSX-RM sensing is the same as that for CSD-RM sensing; therefore, configure autonomous scan as mentioned in the Configuring autonomous scan section.

5.3.5.5 Multi-channel scanning

Multi-channel scanning in CSX-RM sensing is the same as that for CSD-RM sensing; therefore, refer to the Chapter 5.3.4.2.5 section for more details.

5.3.5.6 Button widget tuning

Button widget tuning section provides high-level steps for tuning CSX button. The CE231079 PSOC[™] 4: MSC CAPSENSE[™] CSX button tuning explains tuning of mutual-capacitance based button widgets in the Eclipse IDE for ModusToolbox[™]. For details on the Component and all related parameters, see the Component datasheet.

5.3.5.7 Touchpad widget tuning

Please refer to AN234185 PSOC[™] 4 CAPSENSE[™] Touchpad design guide for touchpad tuning guidelines.



5.3.6 Manual tuning trade-offs

When manually tuning a design, it is important to understand how the settings impact the characteristics of the capacitive sensing system. Any CAPSENSE[™] design has three major performance characteristics: reliability, power consumption, and response time.

• **Reliability** defines how CAPSENSE[™] systems behave in adverse conditions such as a noisy environment or in the presence of water. High-reliability designs will avoid triggering false touches, and ensure that all intended touches are registered in these adverse conditions

Power consumption is defined as the average power drawn by the device, which includes, scanning, processing, and low-power mode transitions as explained in Low-power design. Quicker scanning and processing of the sensors ensures that the device spends less time in a higher power state and maximizes the time it can spend in a lower power sleep state.

• **Response time** defines how much time it takes from the moment a finger touches the sensor until there is a response from the system. Because the lowest response time is limited by the scan and processing time of the sensors, it is important to properly define and follow a timing budget. A good target for total response time is below 100 ms

These performance characteristics depend on each other. The purpose of the tuning process is to find an optimal ratio that satisfies the project's specific requirements. When planning a design, it is important to note that these characteristics usually have an inverse relationship. If you take action to improve one characteristic, the others will degrade.

For example, if you want to use CAPSENSE[™] in a toy, it is more important to have a quick response time and low power consumption. In a different example, such as a "Start/Stop" button for an oven, reliability is the most important characteristic and the response time and power consumption are secondary.

Now let us consider the factors that affect reliability, power consumption, and response time. Figure 103 shows dependencies between CAPSENSE[™] characteristics, measurable parameters, and actual CAPSENSE[™] configurable parameters.



Figure 103

CAPSENSE[™] parameter relationships



5.3.6.1 Reliability

The following factors affect reliability:

- 1. Signal-to-noise ratio (SNR): SNR gives a measure of confidence in a valid touch signal. For reliable CAPSENSE[™] operation, it should be greater than 5. Manual tuning can ensure optimal SNR in specific designs
- 2. Noise immunity: It is the ability of the system to resist external or internal noise. Typical examples of external noise are ESD events, RF transmitters such as Bluetooth[®] LE, switching relays, power supply, and so on. The internal noise source could be an LED driven by PWM, or I²C, or SPI communications for example. Even designs with good SNR may suffer from poor performance because of poor noise immunity. Manual tuning allows to tune frequencies and parameters to help avoid noise interference by allowing more control over selection of different parameters

5.3.6.2 Power consumption and response time

The following factors affect the power consumption and response time:

- 1. Scan rate: Scan rate can be defined as the frequency at which you scan the sensor. Scan rate decides the minimal possible time from the finger touch until it is reported. The maximum scan rate will be limited by the Sensor scan
- 2. Scan time: It is the time taken to scan and process a particular sensor. It affects power consumption as indicated in Low-power design and scan rate as indicated above. Manual tuning can achieve specific scan durations while maintaining a minimum SNR
- 3. Firmware touch delay: This can be caused by the Debounce procedure or use of Raw Data Noise Filters depending on the CAPSENSE[™] component version you are using). Both affect scan time by adding to the processing time of a sensor and delay the touch reporting until a certain number of samples in a row show the touch signal. In both cases response rate is reduced, but reliability is usually improved

5.3.7 Tuning debug FAQs

This section lists the general debugging questions on CAPSENSE[™] Component tuning. Jump to the question you have, for quick information on possible causes and solutions for your debugging topic.

5.3.7.1 The tuner does not communicate with the device

Cause 1: Your device is not programmed.

Solution 1: Make sure to Program your device with your latest project updates before launching the tuner.

Cause 2: The tuner configuration setting does not match the SCB Component setting.

Solution 2: Open the EzI2C slave component configuration window, that is, the Configure 'SCB_P4' dialog and verify that the settings match the configuration of the Tuner Communication Setup dialog. See the CAPSENSE[™] Component datasheet for details on tuner usage.

Cause 3: Your I2C pins are not configured correctly.

Solution 3: Open the *.cydwr* file in Workspace Explorer and ensure the pin assignment matches what is physically connected on the board.

Cause 4: You did not include the CAPSENSE[™] TunerStart API or another required tuner code.

Solution 4: Add the tuner code listed in CAPSENSE[™] Component datasheet to your main.c and reprogram the device.



5.3.7.2 I am unable to update parameters on my device through the tuner

Cause 1: Your communications settings on the device are incorrect.

Solution 1: Review and make sure the settings in the UART/EZI2C configurator dialog and Tuner Communication Setup dialog match. Make sure that the sub-address size is equal.

5.3.7.3 I can connect to the device but I do not see any raw counts

Cause 1: You did not add the tuner code to your project.

Solution 1: Review the Tuner GUI section and add the tuner code to your main.c and reprogram the device.

5.3.7.4 Difference counts only change slightly (10 to 20 counts) when a finger is placed on the sensor

Cause 1: The gain of your system is too low.

Solution 1: Review the Tuner GUI section of this document.

Cause 2: Your sensor parasitic capacitance is very high.

Solution 2: To confirm this issue, use the Built-in Self-Test (BIST) APIs documented in the Component datasheet. These functions allow you to read out an estimate of the sensor parasitic capacitance. You can also confirm this reading independently with an LCR meter.

If your hardware has an option to enable Driven shield signal and shield electrode, use this option in the advanced settings of the CAPSENSETM Component configuration window. A driven shield around the sensors helps reduces the parasitic capacitance. When you enable this option, you may want to enable driving the shield to unused sensors by also changing the "Inactive Sensor connection" setting to "shield" in the advanced settings. If after enabling the shield, your C_P remains greater than the supported range of parasitic capacitance by the PSOCTM device, review your board layout to reduce C_P further, by following the PCB layout guidelines, and/or contact Technical support to review your layout. See Component datasheet/middleware document for more details on the supported range of C_P

Cause 3: Your overlay may be too thick.

Solution 3: Review your Overlay thickness with respect to your Overlay thickness.

Cause 4: Raw counts may be too close to saturation and hence, saturating when sensor is touched.

Solution 4: Tune IDAC to ensure that raw counts are tuned to ~85 percent of the max raw count for a given sensor according to the Modulation and compensation IDACs section.

5.3.7.5 After tuning the system, I see large amount of radiated noise during testing

Cause 1: The sense clock frequency is causing radiated noise in your system.

Solution 1: Reduce the sense clock frequency or enable PRS for your sensor based on Electromagnetic compatibility (EMC) considerations section. If it is already enabled, see theElectromagnetic compatibility (EMC) considerations section.

Cause 2: Large shield electrode may be contributing to a large radiated noise.

Solution 2: Reduce the size of shield electrode based on Layout guidelines for liquid tolerance.



5.3.7.6 My scan time no longer meets system requirements after manual tuning

Cause: The noise and C_P of your system are high, which requires more scan time and filtering to achieve reliable operation.

Solution: C_P needs to be reduced. First, enable the Driven shield signal and shield electrode in the advanced settings of the CAPSENSETM Component configuration window and ensure gain is set as high as possible by reviewing the PCB layout guidelines. If your system still cannot meet final requirements, you may need to change your board layout to reduce C_P further, review the PCB layout guidelines for the same.

5.3.7.7 I am unable to calibrate my system to 85 percent

Cause 1: Your sensor may have a short to ground.

Solution: First, use a multimeter to check if there is a short between your sensor and ground. If it is present, review your schematic and layout for errors.

Cause 2: Your sensor C_P may be too high or too low.

Solution: If your hardware has an option to enable Driven shield signal and shield electrode, use this option in the advanced settings of the CAPSENSE[™] Component configuration window. A driven shield around the sensors helps reduces the parasitic capacitance. If you do not have a hardware option to use shield or if after enabling the shield, yourC_P remains greater than the device supported C_P, contact Technical support to review your layout or for further application-specific guidance.

If you suspect the capacitance to be low compared to the minimum supported parasitic capacitance by the device, add a footprint of the capacitor to a pin. In the final design, if the C_P is identified to be lower than the supported range, place an additional compensation capacitor to increase the sensor C_P to the supported range by dynamically connecting it to the sensor while scanning. See the Component datasheet/middleware document to understand how to gang the sensors to an external compensation capacitor connected to a pin to increase the C_P whenever required.





Figure 104 Gang the sensors to the external compensation capacitor

5.3.7.8 My slider centroid response is non-linear

Cause: Layout may not meet hardware design guidelines to ensure proper linearity.

Solution: Check the C_P of the sensors using the built-in self-test option in the General tab of the CAPSENSE[™] configuration window and update the layout according to the Slider design section. See the Component datasheet/middleware document section for details on BIST API.

5.3.7.9 My slider segments have a large variation of CP

Cause: Your layout design caused your sensors to have an unbalanced C_{P} .

Solution: Your layout needs to be updated. Review Slider design and update your layout as required. If this is not immediately possible, you should re-tune every sensor to have a similar response. This will be a long iterative process and the preferred method is to update the hardware, if possible.

5.3.7.10 Raw counts show a level-shift or increased noise when GPIOs are toggled

Cause 1: The sensor traces are routed parallel to the toggling GPIOs on your PCB.

Solution: Your layout needs to be updated. Review Trace routing and update your layout as required. If the layout cannot be modified at the current stage, you could evaluate the use of firmware filters to reduce the peak-to-peak noise and hence improve SNR.

Cause 2: A large amount of current is being sinked through the GPIOs.

Solution: Limit the amount of DC current sink through the GPIOs when CAPSENSE[™] sensors are being scanned. See Schematic rule checklist. If the current sink through GPIOs is firmware-controlled, and the raw count-level-



shift caused by current sink has a large difference compared to the touch signal, you could implement firmware techniques like resetting or re-initializing the CAPSENSE[™] baseline whenever the current sink is enabled through the GPIOs. The baseline of the CAPSENSE[™] sensor could be reset by using the CapSense_InitializeWidgetBaseline() API function as shown below:

CapSense_InitializeWidgetBaseline(CapSense_CSD_BUTTON_WDGT_ID);



Figure 105 Resetting baseline using firmware technique

Cause 3: You did not follow the guidelines mentioned in Sensor pin selection section.

Solution: Follow the recommendations in Sensor pin selection section. In addition, for PSOC[™] 6 family of devices, follow these guidelines on drive mode strength, switching frequency and slew rate selection, and so on:

• Reduce the drive strength of the switching GPIOs. Table 25 lists the available drive strength options for the GPIOs. Figure 106 shows an example on how to select the drive strength of the GPIOs using the Device configurator in the ModusToolbox[™] project

Drive strength	Drive current in mA
Full	8
$\frac{1}{2}$	4

(table continues...)



Table 25 (continued) brive strength for GF105				
Drive strength	Drive current in mA			
$\frac{1}{4}$	2			
$\frac{1}{8}$	1			

Table 25(continued) Drive strength for GPIOs

- Decrease the switching frequency of the GPIO being toggled
- Use GPIO slew rate as SLOW mode (note that this limits the toggling frequency to 1.5 MHz). See Table 43 for more details
- Use PRS as the Sense clock source.
- If possible, reduce VDDA to lower than 2.7 V
- Try to restrict GPIO switching to intervals between CAPSENSE[™] scans



Figure 106 Selecting drive strength for GPIOs

5.3.7.11 I am getting a low SNR

Cause 1: Sensor is not tuned properly.

Solution: Follow the tuning guidelines in CAPSENSE[™] performance tuning.

Cause 2: CAPSENSE[™] and other peripherals are not properly assigned to the recommended pin.

Solution: See Sensor pin selection and Raw counts show a level-shift or increased noise when GPIOs are toggled for more details.

Cause 3: HFCLK source may be causing higher noise for a PSOC[™] 6 device.

Solution: For the best performance of CAPSENSE[™] in PSOC[™] 6 family of devices, use HFCLK derived from the IMO/ECO+PLL clock source. This clock source provides the best SNR performance. Figure 107 shows how to



change the clock settings using the System tab in the Device configurator for a ModusToolbox[™] project. See AN221774 - Getting started with PSOC[™] 6 MCU for more details on changing the device clock.



Figure 107 Changing clock settings in device configurator

5.3.7.12 I am observing a low CM for my CSX button

Cause: The mutual capacitance between the Tx and Rx electrode should be higher than approximately 750 fF for proper IDAC calibration.

Solution: It is recommended to have two free pins in your device with footprint to add extra Capacitance if C_M of the button turn out to be low. We could then increase the sensor C_M to the supported range by dynamically connecting external capacitor to the CSX sensor while scanning as shown in the below figure, where Pin1 is ganged to the Tx pin and Pin2 is ganged to the Rx pin of the sensor respectively. This will help in mitigating low C_M risk if it is found during testing phase. See Component datasheet/middleware document to understand how to gang the sensor.

Figure 108 shows the addition of the external capacitor as a button widget in the CAPSENSE[™] component and assigning dedicated pins to the Tx and Rx electrode. Figure 109 shows the ganging of the sensor to the external capacitor by assigning Selected pins to both sensor pin and external capacitor pin, this must be done for both Rx and Tx electrode. There is no need to scan the external capacitor while scanning of the widgets, thus we can selectively scan widgets using the APIs CapSense_SetupWidget() and CapSense_Scan() provided by the CAPSENSE[™] component.









Figure 109 Assigning dedicated pins to the external capacitors

PSOC[™] 4 and PSOC[™] 6 MCU CAPSENSE[™] design guide



5 CAPSENSE[™] performance tuning

ame:	CapSense					
Basic	Advanced	Gestures	Built-in			٩
General	CSD Settings	CSX Settings	Widget Details	Scan Order		
Widget	/Sensor list:		Widget/Senso	r parameters:		
	External_cap External_cap Sensor_1 (CSX) Sensor_1_R Sensor_2 (CSX) Sensor_2 (CSX) Sensor_2_R Sensor_2_To	xO xO	IDAC valu Sensor C Selected p	Connections / Gar	Auto-calibrated aging Dedicated pin. Exter Dedicated pin External_cap_Rx0 External_cap_Tx Sensor_1_Tx Sensor_2_Rx0 Sensor_2_Tx	
			(CSX sensing).	ns pin for the sensor (CS The available option r or reuse one or mor	s ar	

Figure 110 Gaining the external capacitor and sensor pin



6 Gesture in CAPSENSE[™]

6.1 Touch gesture support

The CAPSENSE[™] Component in PSOC[™] 4 and PSOC[™] 6 MCU supports the gesture detection feature for button, sliders and touchpad widgets. It allows to identify different predefined gestures based on touch patterns on button, sliders and touchpad widget.

Note: The gesture detection feature is available for selected device part numbers. If you intend to use the gesture feature of the component, ensure that you select the device that supports this feature.

6.2 Gesture groups

Gestures are divided into several groups: Click, one-finger scroll, two-finger scroll, two-finger zoom, one-finger edge swipe, one-finger flick, and one-finger rotate.

Table 26 lists the gestures supported by various widgets. See Component datasheet/middleware document for more details on how these gestures are defined and the parameter that to be configured in the CAPSENSE[™] configurator to detect these gestures.

Widget type	Gesture groups								
	Click	One-finger scroll	Two-finger scroll	One-finger flick	One-finger edge swipe	Two-finger zoom	One-finger rotate		
Button	\checkmark	_	-	-	-	-	-		
Linear slider	-	\checkmark	-	\checkmark	-	-	-		
Radial slider	\checkmark	-	-	-	-	-	-		
Matrix buttons		-	-	-	-	_	-		
Touchpad	\checkmark	_	-	\checkmark	-	-	\checkmark		
Proximity		-	_	-	-	_	-		

Table 26 Gesture supported by different CAPSENSE[™] widgets

6.3 One-finger gesture implementation

Implementing gesture detection involves following steps:

- **1.** Tuning the widget
- 2. Selecting predefined gesture
- **3.** Firmware implementation with timestamp
- 4. Tuning gesture parameters

6.3.1 Tuning the widget

Tune the CAPSENSE[™] hardware and software parameters for the widget. Generally, in a gesture application, because of the speed and orientation of the finger movement changes, the finger may make a very little contact with the widget. This could be confirmed by viewing the centroid data in the Tuner GUI when the gesture is being performed. If the sensitivity is good enough, you will get the data without any break. If you observe any break in the centroid data, increase the sensitivity until the data for the gesture is complete and appear without any break.



Ensure that you get a SNR above 5:1 for the slight finger contact that you may want to detect. Also, ensure that you have a linear centroid response with respect to the finger position on the slider or touchpad. Tune the sensors using guidelines in section Slider widget tuning tuning for achieving the same

6.3.2 Selecting predefined gesture

First, enable Gestures in the Gesture tab in CAPSENSE[™] Component. All gesture-related configuration parameters appear after enabling gestures; these parameters are systematically arranged by widgets/gesture groups as Table 26 shows. According to the application requirement, you can enable and disable gestures by selecting the specific checkbox. Do the following to enable gestures and configure the corresponding parameters.

- Select the widget for which gesture feature must be enabled in the Widget pane. If you have multiple widgets in the project, the PSOC[™] Creator allows gesture recognition only one widget. However, in ModusToolbox[™], gesture recognition can be enabled on more than one widget
- Select the desired gestures in Gestures pane. User has an option to select multiple gestures. In
 PSOC[™] Creator, you cannot enable scroll gesture and flick gesture at the same time. This is applicable for
 both sliders and touchpad. However, in ModusToolbox[™], you can enable more than one gesture according
 to the application requirement
- Configure all parameters in the Parameter pane. When a gesture is selected, the right pane of the window dispays the parameters of the selected gesture group. See the Component datasheet/middleware document

lame: CapSense_1					_
Basic Advanced Ges	tures ADC Built-in			4	
Enable gestures			Two-finger settling time (ms	s): 3	+
LinearSlider() (CSD) Click gestures The group consists of all click-re touchdown, lift off, one/two-finger single/dou	ble click gestures, etc.	Minimum interval Maximum interval Dne-finger minim	a displacement ement for the second click between touches (ms) between touches (ms) um touch duration (ms) um touch duration (ms)	30 20 10 1000 10 1000	
One-finger Touchdown			displacement s the maximum displacement	nt	

Figure 111 Configuring gestures in CAPSENSE[™] component



6.3.3 Firmware implementation with timestamp

See the code example PSOC[™] 4 CAPSENSE[™] Touchpad Gestures to understand how to implement timestamp for gesture recognition. Because each gesture has a pattern of touch that changes with time, a reference timestamp is needed for properly getting the touch data with respect to time. This time stamp represents the sampling rate for the gesture recognition algorithm. Both the centroid positions and their respective timestamp are used by the gesture decoding API to determine different predefined gesture patterns that are applicable for the widget.

First, tune the widget using the procedure described in Tuning the widget and determine the time interval between two successive CAPSENSE[™] scans in the firmware. Update the timestamp exactly with this duration. The way to accurately determine it is to toggle a GPIO in the firmware after the CAPSENSE[™] scan is complete and find the time duration using an oscilloscope.

6.3.4 Tuning gesture parameters

This section describes how to set gesture parameters for sliders; the same procedure could be extended to the gesture groups supported by touchpads. CAPSENSE[™] sliders support Click, One-finger Scroll, and One-finger flick gesture features. See the Component datasheet/middleware document.

6.3.4.1 Using tuner GUI for tuning gesture parameters

You can use the **Gesture View** in Tuner GUI for tuning the gesture parameters and visualize and analyze the performance of the gesture detected in the end system.

Ensure the following while using Tuner GUI for gestures:

- 1. For tuning gesture parameters in runtime, Tuner GUI must be used with EZI2C. Use Synchronized communication mode for visualizing the detected gestures in runtime. For more details on using the Tuner GUI, see the Component datasheet/middleware document and the PSOC[™] 4 CAPSENSE[™] touchpad gestures code example. All the parameters for the gestures that are available in the CAPSENSE[™] configurator are available in Tuner GUI, where you can directly edit these values for tuning.
- 2. As Figure 112 shows, the Gesture View tab is organized into different panes as follows:

Gesture Event History pane shows detected gestures and their positions on the widget.

Detected Gesture pane indicates the detected gesture. If the delay checkbox is enabled, a gesture picture is displayed for the specified time-interval; if delay is disabled, the last reported gesture picture is displayed until a new gesture is reported.

Cypress[®] **Icon** in the Tuner GUI moves according to the scroll gesture. It indicates how well the parameter of the scroll gesture is tuned. This dynamic feature gives performance feedback for further fine-tuning gesture parameters.





Figure 112 Tuner GUI for gestures

3. Determining the event duration using Tuner GUI. A general equation to determine the event duration is given by Equation 73.



Equation 73 Gesture duration

Where,

No. of Samples = Number of samples the gesture event occurred. This data could be obtained from the Graph View in the Tuner GUI.

 T_{sample} = Time interval between two samples.

$$T_{sample} = \frac{1}{\text{Re}fresh\,rate}$$





Figure 113 Determining the Gesture parameters using Tuner GUI

6.3.4.2 Click

There are two type of click gestures: single-click and double-click. Table 27 lists the parameters to be configured for the Click **gesture** in both PSOC[™] Creator and in ModusToolbox[™]. See Component datasheet/ middleware document. Table 28 provides the recommended values of the gesture parameter for the Click gesture.

Table 27Click gesture parameters

Gesture	PSOC [™] Creator	ModusToolbox™
Single-click	One finger minimum touch duration	Minimum click timeout
	One finger maximum touch duration	Maximum click timeout
	Maximum position displacement	Maximum click distance
Double-click	Minimum interval between touches	Minimum second click interval
	Maximum interval between touches	Maximum second click interval
	Maximum displacement for the second click	Maximum second click distance

Table 28Recommended values for click gestures

Parameters	Typical values	
Maximum position displacement	20% of maximum position of the slider	
Maximum position displacement for the second click	20% of maximum position of the slider	
(table continues)		



Table 20

Table 28 (continued) Recommended values for click gestures				
Parameters	Typical values			
Minimum interval between touches (ms)	60			
Maximum interval between touches (ms)	400			
One finger minimum touch duration (ms)	20			
One finger maximum touch duration (ms)	400			

(continued) Recommended values for click gestur

6.3.4.2.1 Single click

A single click is defined as a touch-down event followed by a lift-off. Figure 114 shows the spatial and timing condition that must be satisfied for a valid single-click event.



Figure 114 Single-click gesture

From Figure 114, at time T1, the finger touched down on the slider; at time T2, the finger is lifted off from the slider. For a valid single click, the touch-down duration should be between the "One finger minimum touch duration" and "one-finger maximum touch duration" and the relative position of the liftoff from the initial position of touch should be less than the "Maximum position displacement" parameter.

The duration of each single-click event can be determined by using Equation 73 by finding the number of samples for the single click in the **Graph** view of Tuner GUI and the refresh rate as shown in Figure 113. From the single-click event duration, fix the parameters "One-finger minimum touch duration" and "One-finger maximum touch duration". The maximum position displacement parameter can be determined by observing the maximum variation in the centroid position using the Tuner GUI as shown in Figure 113. The recommended value is 20 percent of the maximum centroid position of the slider as mentioned in Table 27.



6.3.4.2.2 Double click

A double click is two single-clicks event occurring one after another with the second click occurring between the minimum and maximum time interval between the two touches. In addition, the relative position of the second click from the initial position of touchdown event should be less than the maximum position displacement for the second click. Figure 115 shows the spatial and timing conditions that must be satisfied for a valid double-click event.



Figure 115 Double-click gesture

From Figure 115, at time T1, the finger touched down on the slider for the first click; at time T2, the finger is lifted off from the slider. At T3, the finger touched down on the slider for the second click; at T4, the finger is lifted off from the slider. For a valid double click, each click should satisfy the condition of single click, and the second click should occur between Minimum and Maximum interval between touch parameters.

Using the **Graph** view in the Tuner GUI, observe the double-click touch data. Determine the parameter of single click as mentioned in the Single click section. Determine the duration between the two touches using the Graph view in the Tuner GUI and set the value of the minimum and maximum intervals between touch parameters. A typical captured data for the double-click event is shown in Figure 113.

6.3.4.3 Scroll

There are two different scroll gestures that can be detected on sliders: One-finger scroll and One-finger Inertial scroll. See Component datasheet/middleware document. Table 29 shows the parameters to be configured for the scroll gesture.

Note: One-finger Inertial Scroll gesture is not supported in ModusToolbox[™].



Table 29 One finger scroll parameters				
Gesture	PSOC[™] Creator	ModusToolbox™		
One-finger scroll	Position threshold N	Minimum scroll distance		
	Scroll step	-		
	Debounce	Scroll debounce		
One-finger inertial scroll	Position inertial threshold	NA		
	Count level]		

6.3.4.3.1 One-finger scroll

A One-finger Scroll gesture is a combination of a touchdown followed by a displacement in specific direction. The change in position between two consecutive scans must exceed the Position Threshold value given in the configurator after tuning. See Component datasheet/middleware document.

Follow these steps to set the scroll gesture parameter values as shown in Table 29.

- Determine the number of samples of the scroll gesture from the Graph view (Centroid position) in Tuner GUI
- 2. By using Equation 73 determine the duration of the complete scroll
- **3.** Determine the change in centroid position for the complete scroll using the Tuner GUI
- **4.** Determine Position Threshold Equation 74. Each gesture is scanned at a sample rate that is set in the timestamp in the application code. The position threshold is given by the change in the centroid position for the duration that is set in the timestamp

Position Threshold = $\frac{Change in Centroid position}{Total duration of scroll} \times Duration of timestamp$

Equation 74 Equation to determine position threshold

- 5. In PSOC[™] Creator, set four different position thresholds and their scroll count values in the configurator, which are determined by varying the speed of the scroll gesture. Now, change the speed of scroll and repeat the steps 1 4 and set these position threshold values. In ModusToolbox[™] has only one parameter: Minimum Scroll distance; determine its value in the same way you determined the position threshold
- 6. Read the scroll step from the CAPSENSE[™] data structure and use it to control the speed and smoothness of the scroll gesture. The scroll step depends on the position threshold. This scroll step is used in the application code to control the actual variable value to be changed with respect to scroll.

Note: The scroll step parameter is not available in ModusToolbox[™].

7. Set the maximum slider position as ten times the dimension of the slider as a general rule. If you set scrollDistanceMin=10, everything below a 1-mm movement will not detect the scroll gesture. Everything above this number might detect a gesture

Observe the **Cypress**[®] icon in the Tuner GUI (see Figure 112) to get a feedback on how well the tuning has been done for the scroll gesture in the given hardware. You can also print the variable that must be controlled by scroll through UART to visualize how the value is changing with respect to scroll. This could be used as a visual feedback. The position threshold parameters and the corresponding step counts should be tuned until the variation in the variable value with respect to scroll meet the requirement of the end user application.



6.3.4.3.2 One-finger inertial scroll

The one-finger Inertial scroll gesture is defined as a touchdown event followed by a minimum displacement in a specific direction, and then a liftoff. The movement of scroll will automatically stop when it reaches the end value of the variable. See Component datasheet/middleware document.

The gesture parameter is provided in Table 29. The position inertial threshold parameter is given by the minimum change in centroid position that is required before a liftoff; its value can also be determined by steps in the One-finger scroll section. The count value parameter defines the momentum of scroll; it can take two possible values: low or high. Choose the count value according to the end application requirement.

6.3.4.4 One-finger flick

A flick gesture is a touchdown event followed by a high-speed displacement and a liftoff event (see Component datasheet/middleware document). The flick gesture is similar to the One-finger Inertial Scroll; the only difference is that it requires a high-speed displacement followed by a liftoff event within the maximum sample interval defined in the configurator. You can determine the position threshold and the maximum sample interval by following the same procedure in One-finger scroll section and by using Equation 73.

Gesture	PSOC [™] Creator	ModusToolbox™
One Finger Flick Gesture	Position threshold	Minimum flick distance
	Maximum sample interval	Maximum flick timeout

Table 30One-finger flick gesture parameters

6.3.5 Two-finger gesture implementation

Two-finger gestures such as Two-finger Scroll and Two-finger Zoom are supported in the touchpad widget. You must enable this feature in the **Widget Details** tab of the Touchpad Widget. The procedure for tuning the parameters is the same as mentioned in the One-finger gesture implementation section (see Component datasheet/middleware document). Figure 116 shows how to enable two-finger touch gestures in the configurator, select the centroid type as **5 x 5 Centroid**, and set the two-finger detection as **True**.



the second s			
Basic Advanced Gestures B	ult-in		4 Þ
eneral CSD Settings CSX Settings	lidget Details Scan Order		
Widget/Sensor list:	Widget/Sensor parameters:		
B-∭ LinearSlider0 (CSD)	Position movement threshold	3	^
LinearSlider0_Sns0	Position slow movement threshold	7	
LinearSlider0_Sns1	Position fast movement threshold	12	
LinearSilder0_Sns2	IIR coefficient maximum limit	60	
- LinearSlider0_Sns3	IIR coefficient minimum limit	1	
LinearSlider0_Sns4	IIR coefficient divisor	64	
LinearSlider0 Sns5	Ballistic Multiplier Parameters		
E-W Touchpad0 (CSD)	Acceleration coefficient	9	
 Touchpad0_Col0 	Speed coefficient	2	
Touchpad0_Col1	Divisor value	4	
Touchpad0_Col2	X-axis speed threshold	3	
Touchpad0_Col3	Y-axis speed threshold	4	
 Touchpad0_Col4 	V Centroid Parameters		
Touchpad0_Col5	Centroid type	5x5 Centroid	
Touchpad0_Row0	Cross-coupling position threshold	5	
Touchpad0_Row1	Edge correction	True	
Touchpad0_Row2	Virtual sensor threshold	100	
- Touchpad0_Row3	Peruitimate threshold	100	
Touchpad0_Row4	Two finger detection	True	~
Touchpad0_Row5			~
	Two finger detection		
	Enables detection of the second finger on CS	SD touchnad	

Figure 116 Enabling two-finger touch gestures in the CAPSENSE[™] component

6.3.6 Advanced filters for gestures

Advanced filtering features for gestures such as Ballistic multiplier, Adaptive IIR filter, and the Edge correction feature are available to improve gesture recognition and the user experience.

See Component datasheet/middleware document.



7 Design considerations

This chapter explains the firmware and hardware design considerations for CAPSENSE[™].

7.1 Firmware

The CAPSENSE[™] component provides multiple application programming interfaces to simplify firmware development. The CAPSENSE[™] Component datasheet provides a detailed list and explanation of the available APIs. You can use the CAPSENSE[™] Example projects provided in PSOC[™] Creator or ModusToolbox[™] to learn schematic entry and firmware development. See Chapter 4 for more details.

The CAPSENSE[™] scan is non-blocking in nature. The CPU intervention is not required between the start and the end of a CAPSENSE[™] scan. Therefore, you can use CPU to perform other tasks while a CAPSENSE[™] scan is in progress. However, note that CAPSENSE[™] is a high-sensitive analog system. Therefore, sudden changes in the device current may increase the noise present in the raw counts. If you are using widgets that require high



sensitivity such as proximity sensors, or buttons with thick overlay, you should use a blocking scan. Example firmware for a non-blocking scan is shown below.

```
/* Enable global interrupts */
CyGlobalIntEnable;
/* Start EZI2C component */
 EZI2C_Start();
/*
 * Set up communication data buffer to CapSense data structure to be
 * exposed to I2C master at primary slave address request.
*/
 EZI2C_EzI2CSetBuffer1(sizeof(CapSense_dsRam),
 sizeof(CapSense_dsRam),
 (uint8 *)&CapSense_dsRam);
/* Initialize CapSense component */
CapSense Start();
/* Scan all widgets */
 CapSense_ScanAllWidgets();
 for(;;)
  {
   /* Do this only when a scan is done */
    if(CapSense_NOT_BUSY == CapSense_IsBusy())
     { /* Process all widgets */
       CapSense ProcessAllWidgets();
       /* Scan result verification */
       if (CapSense_IsAnyWidgetActive())
        {
          /* Add any required functionality
             based on scanning result */
        }
        /* Include Tuner */
        CapSense RunTuner();
        /* Start next scan */
        CapSense_ScanAllWidgets();
      }
      /* CPU Sleep */
      CySysPmSleep();
  }
}
```

You should avoid interrupted code, power mode transitions, and switching ON/OFF peripherals while a highsensitivity CAPSENSE[™] scan is in progress. However, if you are not using high-sensitivity widgets, you can use CPU to perform other tasks. You can also use low-power mode of PSOC[™] to reduce the average power consumption of the CAPSENSE[™] system, as explained in the next section. Monitoring and verifying the raw counts and SNR using the Tuner GUI is recommended if you are using a non-blocking code.

If you want to develop firmware using the ModusToolbox[™] software, see the references in the ModusToolbox[™] section of this document.



7.1.1 Low-power design

PSOC[™] low-power modes allow you to reduce overall power consumption while retaining essential functionality. See AN234231 - Achieving lowest-power capacitive sensing with PSOC[™] 4000T and AN86233 - PSOC[™] 4 MCU low-power modes and power reduction techniques, for a basic knowledge of PSOC[™] 4 low-power modes. See AN219528 - PSOC[™] 6 MCU low-power modes and power reduction techniques, for PSOC[™] 6's low-power modes, and AN210998 - PSOC[™] 4 low-power CAPSENSE[™] design, for designing a low-power CAPSENSE[™] application.

The CPU intervention is not required between the start and the end of a CAPSENSE[™] scan. If the firmware does not have any additional task other than waiting for the scan to finish, you can put the device to Sleep mode after initiating a scan to save power. When the CSD hardware completes the scan, it generates an interrupt to return the device to the Active mode.

There are different firmware and hardware techniques to reduce the power consumption of the CAPSENSE™ system.

- 1. If you use APIs that scan multiple widgets together, the device returns to Active mode after finishing the scan of a single widget. Therefore, you should scan each widget individually for reducing the power consumption in the design. See the CAPSENSE[™] Component datasheet
- 2. You can use the Deep-Sleep mode of PSOC[™] to considerably reduce the power consumption of a CAPSENSE[™] design. However, the CAPSENSE[™] hardware is disabled in the Deep-Sleep mode. Therefore, the device must wake up frequently to scan for touches. You can use the watchdog timer (WDT) in PSOC[™] to wake up the device from the Deep-Sleep mode at frequent intervals. Increasing the frequency of the scans improves the response of the CAPSENSE[™] system, but it also increases the average power consumption
- **3.** As the number of sensors in the design increases, the device has to spend more time in the Active mode to scan all sensors. This, in turn, increases the average power consumption. For saving power in a design with multiple sensors, you should include a separate proximity loop that surrounds all the sensor. When the device wakes up from the Deep-Sleep mode, only scan this proximity sensor. If the proximity sensor is active, the device must stay in the Active mode and scan other sensors. If the proximity sensor is inactive, the device can return to the Deep-Sleep mode. Figure 117 illustrates this process





Figure 117 Low-power CAPSENSE[™] Design

- 1. The CAPSENSE[™] component can reduce power consumption by reducing the execution time of scanning by ganging sensors together and managing scanning at the application level. In this case, all the sensors in the design are "ganged" that is, simultaneously connected to the AMUX bus to form a virtual sensor. See the code example PSOC[™] 4 low power ganged sensor and AN92239 Proximity sensing with CAPSENSE[™] for details on ganged sensor implementation. A ganged sensor has different tuning parameters because its properties are different compared to considering the sensors individually. Therefore, it should be considered as a single CSD button and tuned separately; see Manual tuning. The ganged sensor is periodically scanned by using a watchdog timer (WDT); if the ganged sensor reports a touch event, enable the scanning of the actual widgets that need to be scanned. This is helpful in CAPSENSE[™] designs that requires Wake on Touch modes. The procedure is similar to what is explained in Figure 117. You can achieve very low system current while maintaining a good touch response, by properly tuning CAPSENSE[™] and the wakeup interval. This technique could also be used with the CSX touchpad widget
- 2. If high-speed peripherals such as system timers and I²C are required, you can put the CPU to sleep mode instead of going to deep sleep mode
- **3.** You can also add a shield hatch in the design, as explained in Driven shield signal and shield electrode to reduce the parasitic capacitance and therefore, the scan time. The scan time and power consumption is directly related; thus, the power consumption is reduced by lowering the scan time
- **Note**: In PSOC[™] 4000 devices, it is not recommended to enter Sleep mode if a CAPSENSE[™] scan is in progress.



7.1.2 Synchronized scanning

In Fifth-Generation Low-Power CAPSENSE[™] (MSCLP), the sensor scanning can be controlled using the External Frame Start feature. This allows scanning to be triggered by a pulse on the External Frame Start pin (ext_frm_start). This feature is available in PSOC[™] 4000T and PSOC[™] 4100T Plus.

This feature can be used to synchronize the scanning of multiple devices with MSCLP on-board or to synchronize with external periodic noise sources, such as LCDs.

External frame start pulse guidelines

Mentioned below are the characteristics of the External Frame Start signal for the proper operation of the external frame start feature.

1. Scan trigger: A scan will happen only when an external frame start signal is received after a scan_all_slots has been called in the application.



- 2. Pulse Type: A clean rectangle wave
- **3. Pulse Period:** The period of pulse that is interval between two subsequent pulses should not be lesser than the frame duration + MSC ISR duration + Processing duration



Figure 119 Pulse period

4. Minimum Pulse Width: The pulse should not be shorter than 2 ILO cycles





Figure 120 Minimum pulse width

5. Max Pulse Width: Should not be longer than scanning frame duration

	\checkmark	×
External Frame start		
Scan	Scan ISR Process	Scan ISR Process

Figure 121 Max pulse width

6. Sync interval (interval between the calling scan_all_slots() and the pulse): Should be longer or equal 2 ILO cycles.

Scan	
C C	Scan
ILO Clock	
External Frame st	art
Application	Scan_all_slots()

Conditioning the external frame start pulse

With the help of external frame start feature in MSCLP, scans can be synchronized with an LCD sync signal. If the external frame start signal does not comply with the guidelines mentioned in the **External Frame Start Pulse Guidelines** section, the signals will need to be conditioned. One way to condition the sync signal is using the TCPWM hardware present in the device. It receives the LCD sync signal (e.g., 60 Hz square wave) and generates the external_frame_start signal, with the appropriate width, as output.





Figure 123 Using TCPWM to generate conditioned pulse

The TCPWM is configured as a single shot timer. The timer gets triggered by an external input pulse. This external input pulse is the LCD sync signal, and the output from the TCPWM is fed to the ext_frm_start pin of the MSCLP.

Three GPIOs and 1 TCPWM are used in this approach,

- **1.** External Trigger input for the TCPWM
- 2. TCPWM line output
- **3.** MSCLP ext_frm_strt pin

The output from the TCPWM needs to be wired and connected to the input of the ext_frm_strt pin.

7.2 Sensor construction

A capacitive sensor can be constructed using different materials depending on the application requirement. In a typical sensor construction, a conductive pad, or surface that senses a touch is connected to the pin of the PSOC[™] using a conductive trace or link. This whole arrangement is placed below a non-conductive overlay material and the user interacts on top of the overlay.



Figure 124 shows the most common CAPSENSE[™] sensor construction.

Figure 124 CAPSENSE[™] sensor construction

The copper pads etched on the surface of the PCB act as CAPSENSE[™] sensors. A nonconductive overlay serves as the touch surface. The overlay also protects the sensor from the environment and prevents direct finger contact. A ground hatch surrounding the sensor pad isolates the sensor from other sensors and PCB traces.

If liquid tolerance is required, you should use a shield hatch instead of the ground hatch. In this case, drive the hatch with a shield signal instead of connecting it to ground. See Liquid tolerance section for details.



The simplest CAPSENSE[™] PCB design is a two-layer board with sensor pads and hatched ground plane on the top, and the electrical components on the bottom. Figure 125 shows an exploded view of the CAPSENSE[™] hardware.



Figure 125 CAPSENSE[™] hardware Sensor construction using springs as sensors

Sensors may also be constructed by using materials other than copper, such as indium tin oxide (ITO) or printed ink on substrates such as glass or a flex PCB. In some cases, springs can also be used as CAPSENSE[™] sensors as Figure 126 shows, to create elevated sensors that allow overlay to be placed at an elevated distance from the PCB. See Getting started with CAPSENSE[™] design guide for PCB design considerations specific to spring sensors and other non-copper sensors such as ITO and printed ink.



Figure 126Sensor construction using springs as sensors

7.3 Overlay selection

7.3.1 Overlay material

The overlay is an important part of CAPSENSE[™] hardware as it determines the magnitude of finger capacitance. The finger capacitance is directly proportional to the relative permittivity of the overlay material. See Finger capacitance for details.

Table 31 shows the relative permittivity of some common overlay materials. Materials with relative permittivity between 2.0 and 8.0 are well suited for CAPSENSE[™] overlay.



Table 31 Relative permittivity of overlay materials	
ε _r	
1.0	
4.6 - 4.9	
7.6 - 8.0	
6.0	
3.2	
2.9 – 3.0	
2.8	
2.4 - 4.1	
1.2 – 2.5	
2.5 - 6.0	

In capacitive touch sensing, the finger and the sensor behave as the two plates of a capacitance, with the overlay forming the dielectric material. Hence, in case of multiple overlays, it makes two capacitors in series. Thus, the effective dielectric constant is as shown below for two overlays of dielectric constant of $\varepsilon 1$ and $\varepsilon 2$ and thickness of d1 and d2.

F	$\varepsilon 1 * d1 + \varepsilon 2 * d2$
$E_{overall} =$	d1 + d2

Equation 75 Effective Dielectric constant for multiple overlays

Note: Conductive materials interfere with the electric field pattern. Therefore, you should not use conductive materials for overlay. You should also avoid using conductive paints on the overlay.

7.3.2 Overlay thickness

Finger capacitance is inversely proportional to the overlay thickness. Therefore, a thin overlay gives more signal than a thick overlay. See Finger capacitance for details.

Table 32 lists the recommended maximum thickness of acrylic overlay for different CAPSENSE[™] widgets.

Table 32	Maximum thickness of acrylic overlay
----------	--------------------------------------

Widget	Maximum thickness (mm) – 4th Generation CAPSENSE™	Maximum thickness (mm) – 5th Generation CAPSENSE™
Button	5	18
Slider	5 ¹⁾	18
Touchpad	0.5	3

1) For a 5 mm acrylic overlay, the SmartSense Component requires a minimum of 9 mm finger diameter for slider operation. If the finger diameter is less than 9 mm, Manual Tuning should be used.

Because Finger capacitance also depends on the dielectric constant of the overlay, the dielectric constant also plays a role in the guideline for the maximum thickness of the overlay. Common glass has a dielectric constant of approximately $\varepsilon_r = 8$, while acrylic has approximately $\varepsilon_r = 2.5$. The ratio of $\varepsilon_r/2.5$ is an estimate of the overlay



thickness relative to plastic for the same level of sensitivity. Using this rule of thumb, a common glass overlay can be about three times as thick as a plastic overlay while maintaining the same level of sensitivity.

In addition, avoid using very thin or no overlay. It is important to have a minimum overlay thickness in a CAPSENSE[™] design for the following reasons:

- 1. An overlay provides protection from the environmental condition, prevents direct finger contact, and gives ESD protection. The overlay thickness should be small enough to give a good signal, and decided based on the button size and the strength to withstand ESD. See AN64846 Getting started with the CAPSENSE[™]
- 2. For the CSD button, if there is no overlay the buttons will be over sensitive
- **3.** For sliders, if there is no overlay, the raw count may saturate for the slider segments and may cause non-linear centroid response for slider. See Slider design
- **4.** For the CSX sensor, it is recommended to have a minimum overlay thickness of 0.5 mm. If it is violated, sudden decrease in raw count is observed when a finger is placed on a sensor or a water drop falls on the Tx and Rx electrodes. See Effect of grounding

7.3.3 Overlay adhesives

The overlay must have a good mechanical contact with the PCB. Use a non-conductive adhesive film for bonding the overlay and the PCB. This film increases the sensitivity of the system by eliminating the air gap between the overlay and the sensor pads. Recommendation for the Adhesive to be used are mentioned below:

1. Adhesive selection:

a. 3M™ Acrylic Adhesive 200 MP is typically recommended for its superior adhesion, high shear strength, and transparency. These properties make it a top choice for bonding applications where a reliable, transparent, and uniform bond line is essential.

2. Surface compatibility:

- **a.** For overlays with minimal surface irregularities, such as acrylic and glass, a thinner adhesive layer (approximately 60 microns) is recommended. This ensures a smooth, uniform bond without visible air gaps.
- **b.** If the surfaces have minor irregularities, such as 3D printed enclosures or milled plastics, a slightly thicker adhesive layer (around 130 microns) can be used to accommodate the unevenness and to prevent air gaps, ensuring a more reliable and durable bond.

3. Temperature and environmental considerations:

- **a.** These adhesives perform well in commercial-grade applications, maintaining functionality and adhesion under typical usage conditions .
- **b.** It is vital to assess the shear strength of these adhesives at higher temperatures. Especially in automotive applications where exposure to higher temperatures (either continuous or short term) is common.

A few additional points to consider:

- **1. Mechanical load durability:** Ensure that the adhesive can withstand various mechanical loads, including shear and peel stresses, to verify the bond's reliability under real-world conditions.
- 2. Automotive standards compliance: Ensure that the adhesive is compatible with the thermal and environmental demands, typical of automotive applications, covering temperature ranges, humidity levels, and exposure to chemicals.
- **3. CAPSENSE[™] system compatibility:** For CAPSENSE[™]systems, consider the adhesive's electrical insulation properties and ensure that it does not interfere with the capacitive sensing performance. Conduct appropriate testing to verify the sensor's performance before and after adhesive application.


7.4 PCB layout guidelines

PCB layout guidelines help you to design a CAPSENSE[™] system with good sensitivity and high Signal-to-noise ratio (SNR).

7.4.1 Sensor CP

In a CAPSENSETM system design, the C_P of the sensor must be within the supported range of the device. You can find the supported C_P range in the Component datasheet/middleware document. The main components of C_P are trace capacitance, sensor pad capacitance, and pin capacitance of the device. The pin capacitance is device-dependent (see the Device datasheet), so you can only design your sensor and trace capacitance to be able to meet the C_P criteria in the datasheet. The relationship between C_P and the PCB layout features is not simple. C_P increases with an increase in the sensor pad size and trace length and width, and with a decrease in the gap between the sensor pad and the ground hatch.

There are many ways to decrease the C_P :

- Decrease the trace length and width as much as possible. Reducing the trace length increases noise immunity
- Drive the hatch with a shield signal. See Driven shield signal and shield electrode

Reducing the sensor pad size is not recommended because it also reduces the finger capacitance. In some special cases, such as small sensor pad and very small trace length due to placement of the sensor pad close to the device, there is a possibility of the sensor C_P to be lower than the supported minimum C_P by the device. In that case, add a footprint of the capacitor across the sensor or any unused pin. If the C_P is identified to be lower than the supported range, place a 4.7 pF capacitor across the sensor or on the unused pin and gang the capacitor during the CAPSENSETM scan, refer to the FAQ I am unable to calibrate my system to 85 percent for more details. This will increase the C_P of the sensor to the supported range.

If the sensor C_P is very high due to long traces or because of a nearby ground, use the mutual-capacitance sensing method so that the sensitivity is not degraded because of the high C_P value. The sensitivity of the CAPSENSE[™] sensor in a mutual-capacitance sensing method is independent of the sensor C_P.

7.4.2 Board layers

Most applications use a two-layer board with the sensor pads and the hatched ground planes on the top side and all other components on the bottom side. PCBs that are more complex use four layers.

- FR4-based PCB designs perform well with board thickness ranging from 0.020 inches (0.5 mm) to 0.063 inches (1.6 mm).
- Flex circuits work well with CAPSENSE[™] too. You can use flex circuits for curved surfaces. All PCB guidelines in this document also apply to flex. You should use flex circuits with thickness 0.01 inches (0.25 mm) or higher for CAPSENSE[™]. The high breakdown voltage of the Kapton[®] material (290 kV/mm) used in flex circuits provides built in ESD protection for the CAPSENSE[™] sensors

7.4.3 Button design

7.4.3.1 Self-capacitance button design

The self-capacitance button has a single electrode and can have different shapes and size as recommended below.

Shape: You should use circular sensor pads for CAPSENSE[™] buttons. Rectangular shapes with rounded corners are also acceptable. However, you should avoid sharp corners (<90°) since they concentrate electric fields. Figure 127 shows recommended button shapes.





Figure 127 Recommended button shapes

Size: Button diameter should be 5 mm to 15 mm, with 10 mm suitable for most applications. A larger diameter is appropriate for thicker overlays.

Spacing: The width of the gap between the sensor pad and the ground hatch should be equal to the overlay thickness, and range from 0.5 mm to 2 mm. For example, if the overlay thickness is 1 mm, you should use a 1 mm gap. However, for a 3 mm overlay, you should use a 2 mm gap.

Select the spacing between two adjacent buttons such that when touching a button, the finger is not near the gap between the other button and the ground hatch, to prevent false touch detection on the adjacent buttons, as Figure 128 shows.





7.4.3.2 Mutual-capacitance button design

Mutual capacitance sensing measures the change in capacitive coupling between two electrodes. The sensor pattern should be designed in such a way that the finger disturbs the electric field between the Tx and Rx electrodes to a maximum extent. There are standard button patterns that could be used for the mutual capacitance button design and their parameters could be modified based on the application requirement. Fishbone pattern is one of the mutual capacitance patterns which give better performance in terms of SNR.

7.4.3.2.1 Fishbone pattern

Prongs or fishbone are standard shapes for mutual-capacitance buttons. The Tx forms a box or ring around the button for shielding Rx from noise. There are interlaced Tx and Rx prongs inside the border to form the electric



field. Figure 129 shows an example of a two-prong fishbone sensor structure with top and bottom view with hatched ground. The gap between the outer wall of the Tx electrode and the coplanar hatch ground should be greater than the air-gap of Tx and Rx electrodes. The reference plane (PCB bottom layer) of the Fishbone structure should have void region as shown in Figure 129.





Table 33 lists the suggested fishbone button design parameters for some commonly used sensor sizes and overlay like glass and acrylic. As explained in section Sensor size, the recommended button size is to keep the button X and Y dimension close to the sum of expected user finger size and overlay thickness. However, the table lists multiple button sizes that you can chose from if you have constraints on available space on board or if you would like to have a bigger button for your application for ease of user interaction etc.

Also, note that for a given button size, the achievable SNR decreases with increased overlay thickness. Thus, if you plan to use thick overlays (approx. > 1 mm acrylic or 2 mm glass) ensure to avoid compromising on button size due to board space because that will further limit the button SNR performance. Ensure to use bigger buttons (>= biggest expected finger size) for such thick overlays. And also, for small buttons better to have thin overlays for getting good SNR.

	A:		1		1	
Number of Rx-prongs	Air gap between Tx and Rx in mm	Tx width in mm	Rx width in mm	X-wall wdth in mm	Y-wall width in mm	Y prong in mm
3	0.35	0.48	0.48	0.24	0.24	0.2
3	0.75	0.92	0.92	0.46	0.46	0.2
3	0.5	1.17	1.17	0.58	0.58	0.2
2	0.9	1.60	1.60	0.80	0.80	0.2
2	1.3	1.70	1.70	0.85	0.85	0.2
2	1.1	2.15	2.15	1.08	1.08	0.2
2	1.5	1.75	1.75	0.88	0.88	0.2
2 2 2 2		0.9 1.3 1.1 1.5	0.9 1.60 1.3 1.70 1.1 2.15 1.5 1.75	0.9 1.60 1.60 1.3 1.70 1.70 1.1 2.15 2.15 1.5 1.75 1.75	0.9 1.60 1.60 0.80 1.3 1.70 1.70 0.85 1.1 2.15 2.15 1.08 1.5 1.75 1.75 0.88	0.9 1.60 1.60 0.80 0.80 1.3 1.70 1.70 0.85 0.85 1.1 2.15 2.15 1.08 1.08 1.5 1.75 1.75 0.88 0.88

Table 33Dimension of Fishbone buttons (all units in mm)

(table continues...)



Table 33	(conti	(continued) Dimension of Fishbone buttons (all units in mm)													
Button size (X-size, Y- size) (mm)	Number of Rx-prongs	Air gap between Tx and Rx in mm	Tx width in mm	Rx width in mm	X-wall wdth in mm	Y-wall width in mm	Y prong in mm								
15, 15	2	1.7	2.05	2.05	1.03	1.03	0.2								
17, 17	2	2.3	1.95	1.95	0.98	0.98	0.2								
20, 13	2	1.8	3.20	3.20	1.60	1.60	0.2								
25, 13	2	2	4.25	4.25	2.13	2.13	0.2								

Table 33(continued) Dimension of Fishbone buttons (all units in mm)

The above button design parameters in Table 33 ensure a good SNR performance if you follow the schematics and layout guidelines in this chapter.

7.4.3.2.2 Button design for arbitrary shapes and dimensions

Figure 130 shows the different orientation of Rx prongs in the Fish bone pattern, in Button A the Rx prong is perpendicular to the side of the button with larger dimension and in Button B the Rx prongs is parallel to the side of the button with larger dimension. Orientation of Rx prongs like in Button A results in optimized button pattern compared to Button B. Thus, it is always recommended to have Rx prongs perpendicular to the side of the button with larger dimension. Thus if you need a 10x13 mm button, then simply use the 13x10 mm button from Table 32 and rotate it 90° to get 13x10 mm Noise in CAPSENSE[™] system button pattern as shown in Figure 130.





Orientation of Rx prongs

Note: In case if you expect a higher external noise in the design and for other complex cases you can contact Technical support for any assistance in the button design. Refer to the section Noise in CAPSENSE[™] system for more details about the external noise. And in the design if you expect a low C_M then follow the guidelines mentioned in the section I am observing a low CM for my CSX button for mitigating it.



13 x 10 mm button	10 x 13 mm button

Figure 131Rotating the button 90 deg to get the desired button dimension

There may be some design where you need a different button shape than the recommended rectangular, like an oval or circular shape etc. The below steps explain how to construct the button with nonstandard shape from the standard Fish bone pattern.

- First select the Fishbone pattern (Rectangular shape for oval shape and Square button for circular shape) from Table 32 to cover the desired button shape
- Then in the user interface or above the overlay print button shape with required dimension over the fishbone pattern as shown in Figure 132

Mutual capacitance buttons designed using this method have some oversensitive area or less sensitive outside the button shape as shown in the below figures, this could be mitigated by properly tuning the software thresholds of the mutual capacitance button. The below figure shows an example of a circular button made using a square fishbone pattern.





If you want a pattern that is not present in Table 32, you can obtain the button parameters by following few steps. For example, if you want a 19x19 pattern, choose the pattern that is close to the required pattern from Table 32 like 17x17, and scale the air gap between Tx and Rx with respect to the button areas. For example:

$$New_{gap} = TxRx_{gap} \times \left(\frac{ButtonArea_{desired}}{ButtonArea_{reference}}\right)$$

Where, ButtonArea=X x Y dimension of the sensor.

Compute the Tx, Rx width and Tx wall based on the assumption below and by considering the *New*_{gap} as obtained above. The obtained values of the button design parameters are shown in Table 33. Refer to the Figure 129 to understand the description of the button design parameters.

 $Tx_{width} = Rx_{width}$

mm

2.3

2.9



0.2

0.2

7 Design considerations

2

2

$$Tx_{wall} = \frac{Tx_{width}}{2}$$

Table 34	Button par	rameter for 19	X 19 buttor	n form 17 X	17 button		
Button size (X- size, Y-size) (mm)	Number of Rx-prongs	Air gap between Tx and Rx in	Tx width in mm	Rx width in mm	X-wall width in mm	Y-wall width in mm	Y prong in mm

General recommendations on Fishbone pattern parameters 7.4.3.2.3

1.95

1.85

1.95

1.85

0.98

0.93

0.98

0.93

Sensor size

17, 17

19,19

The sensor size is the XY dimension of the button, it is selected based on the board space availability, expected user finger size and overlay material and thickness. Sensor size selection also depends upon the number of required buttons on the PCB considering required button-to-button gap and space availability in the PCB. But if the space is not the constrain then choose higher button size which will result in getting a good SNR. Note that increasing the sensor size beyond a point will cause the SNR to saturate, this is because some of the electric field lines from Tx/Rx electrode do not interact with the finger as shown in Figure 133.



Figure 133 Interaction of electric filed with the finger

The SNR of the button is decreased with usage of thick overlays. Thus, the recommended minimum sensor size is finger size plus overlay thickness to achieve a good SNR even with thick overlays. For example, the minimum sensor size recommended could be 13x10 mm, considering the finger size around 10mm in diameter and 3 mm overlay thickness. As mentioned in the Button design for arbitrary shapes and dimensions Rx prongs should be perpendicular to the side with large dimension.

Button spacing

The button spacing is the gap between the Tx wall of two buttons. It helps to prevent user error by isolating the buttons from each other and reduces the cross talk. It is recommended to keep a minimum of 8 mm spacing between the buttons this will ensure a good single touch and multi touch performance.

Overlay

The overlay thickness and overlay permittivity influences the SNR of the button and immunity towards the external noise such as ESD. Refer to the Overlay selection section for more details. It is recommended to keep the overlay thickness as minimum as possible which will help in getting a higher SNR for the button and it



should be high enough to provide immunity towards ESD noise. In some cases, if the overlay thickness is more and you cannot avoid it due to mechanical design consideration. In such a case, for getting a better SNR use a mutual capacitance button with bigger size than the recommended size. Refer to the section Sensor size for selecting the minimum button dimension with respect to the overlay thickness. Using an overlay material with higher dielectric constant will also leads to higher SNR. So always use material with high dielectric constant when we use thick overlay. And also, for smaller buttons better to have thin overlays for getting good SNR.

Air gap between Tx and Rx electrode

The gap between the Tx and Rx electrode influences the mutual capacitance between the Tx and Rx electrode. Increasing the gap reduces the mutual capacitance. It is the most critical parameter in the Fishbone pattern design and the gap between the Tx and Rx electrode such that the mutual capacitance is above 750 fF.

Number of Rx-prongs

The number of Rx prongs influence the mutual capacitance between the Tx and Rx electrode, because increasing the number of Rx prongs decreases the gap between the Tx and Rx electrode for a given button size. Higher mutual capacitance implies higher electric field lines between Tx and Rx electrode. Thus, we get a higher signal when we touch the button, because the finger touch will disturb the electric field to a maximum extent. But higher C_M also increases the impact of external noise such as VDDA ripple noise. Thus, there is a tradeoff in selecting the number of Rx prongs to get a higher signal verses getting good noise immunity. The optimal number of Rx prongs is 2 for the Fishbone pattern (that is Fishbone pattern with a single Tx prong and two Rx prongs). The below figure shows the mutual capacitance button with three and one number of Rx prongs.



Figure 134 Mutual capacitance button with different number of prongs

Tx electrode and Rx electrode width

The Tx electrode and Rx electrode width influences the mutual capacitance between Tx and Rx electrode. Best signal response is achieved when Rx width/area is equal to Tx width/area in the case of less external noise in the system. The below figure shows the electric filed lines from Tx to Rx electrode with equal and unequal widths. Thus, from the below figure it is clear that having equal Tx and Rx width will eventually leads to higher change in C_M for a finger touch.

Figure 135 Effect of Tx and Rx width





In some cases, it is required to provide liquid tolerance to the mutual capacitance button as mentioned in section Liquid tolerance for mutual-capacitance sensing. To achieve that we have to use a hybrid sensing technique with both CSX and CSD sensing method. In such a case the Tx or Rx electrode whichever is scanned in CSD technique should have a significant width so that it ensures a good signal for a finger touch.

Co planar ground

Presence of coplanar ground decreases the impact of noise in the system and it also provides good ground resulting in decreased signal disparity effect. It is recommended to have as much area surrounding the sensor with hatched pattern and connected it to device ground. Also follow the recommendations as mentioned in the layout and schematics guidelines in this chapter. Ground plane reduces the coupling of electric field lines to the approaching finger, which decreases the change in mutual capacitance caused by a finger touch. It is suggested to avoid having ground plane underneath the sensor unless you expect strong coupling to a noise source present right below the sensor. Figure 129 shows the coplanar ground on the top and bottom layer of the PCB. The gap between the outer wall of the Tx electrode and the coplanar hatch ground should be greater than the air-gap of Tx and Rx electrodes.

Tx wall (X-wall and Y-wall width)

Tx wall act as a shield to the Rx electrode from noise. Wide Tx wall also reduces the effect of cross talk and the impact of Co-planar ground. It is recommended to keep the Tx wall width approximately equal to half of Tx electrode width. The below figure shows the effect of wider Tx wall, it increases the number of electric field lines reaching the finger from the Tx electrode by reducing the impact of Coplanar ground. The width of Tx wall can also be slightly increased in case Tx electrode is scanned as a CSD sensor as mentioned in sectionLiquid tolerance for mutual-capacitance sensing. An example 10x10 pattern with increased Tx wall is given in Table 34.





Figure 136 Effect of width of Tx wall

Table 35Dimension of 10x10 button with increased Tx wall (all units in mm)

Button Size (X- Size, Y-Size) (mm)	Number of Rx-Prongs	Air Gap between Tx and Rx in mm	Tx Width in mm	Rx Width in mm	X-Wall Width in mm	Y-Wall Width in mm	Y Prong in mm
10, 10	2	0.8	1.2	1.2	1.5	1.6	0.2

7.4.4 Slider design

Figure 137 shows the recommended slider pattern for a linear slider and Table 36 shows the recommended values for each of the linear slider dimensions. A detailed explanation on the recommended layout guidelines is provided in the following sections.



Table 36	Linear slider dimensions
----------	--------------------------

Parameter	Acrylic overlay thickness	Minimum	Maximum	Recommended
Width of the segment (W)	1 mm	2 mm	-	8 mm ¹⁾
	3 mm	4 mm	-	
	4 mm	6 mm	-	

(table continues...)

(continued) Linear slider dimensions



7 Design considerations

Table 26

Table 36 (continued) Linear Studer dimensions									
Parameter	Acrylic overlay thickness	Minimum	Maximum	Recommended					
Height of the segment (H)	-	7 mm ²⁾	15 mm	12 mm					
Air gap between segments (A)	-	0.5 mm	2 mm	0.5 mm					
Air gap between the hatch and the slider (A _{HS})	-	0.5 mm	2 mm	Equal to overlay thickness					

 1)
 The recommended slider-segment width is based on an average human finger diameter of 9 mm. See section Slider-segment

shape, width, and Air gap for more details.

2) The minimum slider segment height of 7 mm is recommended based on a minimum human finger diameter of 7 mm. Slider height may be kept lower than 7 mm if the overlay thickness and CAPSENSE[™] tuning is such that an Signal-to-noise ratio (SNR) (SNR) ≥ 5:1 is achieved when the finger is placed in the middle of any segment.

7.4.4.1 Slider-segment shape, width, and Air gap

A linear response of the reported finger position (that is, the centroid position) versus the actual finger position on a slider requires that the slider design is such that whenever a finger is placed anywhere between the middle of the segment SLD0 and middle of segment SLDn-1, other than the exact middle of slider segments, exactly two sensors report a valid signal ¹⁰. If a finger is placed at the exact middle of any slider segment, the adjacent sensors should report a difference count = noise threshold. Therefore, it is recommended that you use a double-chevron shape as Figure 137 shows. This shape helps in achieving a centroid response close to the ideal response, as Figure 138 and Figure 139 show. For the same reason, the slider-segment width and air gap (dimensions "W" and "A" respectively, as marked in Figure 137) should follow the relationship mentioned in Equation 48.



Figure 138 Ideal slider segment signals and centroid response

¹⁰ Here, a valid signal means that the difference count of the given slider segment is greater than or equal to the noise threshold value.





Figure 139 Ideal slider signals

W+2A = finger diameter

Equation 76 Segment width and air gap relation with the finger diameter

Typically, an average human finger diameter is approximately 9 mm. Based on this average finger diameter and Equation 76, the recommended slider-segment-width and air-gap is 8 mm and 0.5 mm respectively.

If the sum of *slider-segment width* and 2 * *air-gap* is lesser than *finger diameter*, as required according to Equation 76, the centroid response will be non-linear. This is because, in this case, a finger placed on the slider will add capacitance, and hence valid signal to more than two slider-segments at some given position, as Figure 140 shows. Thus, calculated centroid position in Equation 77 will be non-linear as Figure 141 shows.





Figure 140 Finger causes valid signal on more than two segments when slider segment width is lower than recommended

centroid position =
$$\left(\frac{S_{x+1} - S_{x-1}}{S_{x+1} + S_x + S_{x-1}} + x\right) \times \frac{\text{Resolution}}{(n-1)}$$

Equation 77 Centroid algorithm used by CAPSENSE[™] component in PSOC[™] Creator

Where,

Resolution = API resolution set in the CAPSENSE[™] component customizer

n = Number of sensor elements in the CAPSENSE[™] component customizer

x = Index of element which gives maximum signal

Si = Different counts (with subtracted noise threshold value) of the slider segment







Note that even though a *slider-segment-width* value of less than *finger diameter – 2 * air-gap* provides a nonlinear centroid response, as Figure 141 shows; it may still be used in an end application where the linearity of reported centroid versus actual finger position does not play a significant role. However, a minimum value of slider-segment-width must be maintained, based on overlay thickness, such that, at any position on the effective slider length, at least one slider-segment provides a Signal-to-noise ratio (SNR) of \ge 5:1 (that is signal greater than or equal to the finger threshold parameter) at that position. If the slider-segment width is too low, a finger may not be able to couple enough capacitance, and therefore, none of the slider-segments will have a 5:1 SNR, resulting in a reported centroid value of 0xFFFF¹¹ in PSOCTM Creator as Figure 142 shows, and 0x0000¹² in ModusToolboxTM.



Figure 142 Incorrect centroid reported when slider-segment-width is too low

The minimum value of slider-segment width for certain overlay thickness values for an acrylic overlay are provided in Table 36. For thickness values of acrylic overlays, which are not specified in Table 36, Figure 143 may be used to estimate the minimum slider-segment width. Very thin overlay or no overlay may cause a nonlinear centroid response due to saturation of raw count or due to high finger capacitance; centroid position may be detected before touching the slider. In these conditions, the CAPSENSE[™] centroid algorithm will not be able to correctly estimate the finger position on the slider using Equation 77. It is recommended to have the overlay thickness for the CSD sensor as mentioned in Table 35.

¹¹ The CAPSENSE[™] Component in PSOC[™] Creator reports a centroid of 0xFFFF when there is no finger detected on the slider, or when none of the slider segments reports a difference count value greater than the Finger Threshold parameter.

¹² The CAPSENSE[™] middleware in ModusToolbox[™] reports a centroid of 0x0000 when there is no finger detected on the slider, or when none of the slider segments reports a difference count value greater than the Finger Threshold parameter.





Figure 143 Minimum slider-segment width with respect to overlay thickness for an acrylic overlay

If the *slider-segment-width* + 2 * *air-gap* is higher than the *finger diameter* value as required in Equation 76, the centroid response will have flat-spots; that is, if the finger is moved towards the middle of any segment, the reported centroid position will remain constant as Figure 144 shows. This is because, as Figure 145 shows, when the finger is placed in the middle of a slider segment, it will add a valid signal only to that segment even if the finger is moved a little towards adjacent segments.



Figure 144 Flat-spots (nonresponsive centroid) when slider-segment width is higher than recommended







Note that if the value of *slider-segment-width* + 2 * *air-gap* is higher than the *finger diameter*, it may be possible to increase and adjust the sensitivity of all slider segments such that even if the finger is placed in the middle of a slider segment, adjacent sensors report a difference count value equal to the noise threshold value (see Figure 138); however, this will result in the hover effect – the slider may report a centroid position even if the finger is hovering above the slider and not touching the slider.

7.4.4.2 Dummy segments at the ends of a slider

In a CAPSENSE[™] design, when one segment is scanned, adjacent segments are connected to either ground or to the driven-shield signal based on the option specified in the "Inactive sensor connection" parameter in the CAPSENSE[™] CSD Component. For a linear centroid response, the slider requires all the segments to have the same sensitivity, that is, the increase in the raw count (signal) when a finger is placed on the slider segment should be the same for all segments. To maintain a uniform signal level from all slider segments, it is recommended that you physically connect the two segments at both ends of a slider to either ground or driven shield signal. The connection to ground or to the driven-shield signal depends on the value specified in the "Inactive sensor connection" parameter. Therefore, if your application requires an 'n' segment slider, it is recommended that you create n+2 physical segments, as Figure 137 shows.

If it is not possible to have two segments at both ends of a slider due to space constraints, you can implement these segments in the top hatch fill, as Figure 146 shows. Also, if the total available space is still constrained, the width of these segments may be kept lesser than the width of segments SLD0 through SLDn-1, or these dummy segments may even be removed.

If the two segments at the both ends of a slider are connected to the top hatch fill, you should connect the top hatch fill to the signal specified in the "Inactive sensor connection" parameter. If liquid tolerance is required for the slider, the hatch fill around the slider, the last two segments, and the inactive slider segments should be connected to the driven-shield signal. See the Effect of liquid droplets and liquid stream on a self-capacitance sensor section for more details.





Figure 146 Linear slider pattern when first and last segments are connected to top hatch fill

7.4.4.3 Deciding slider dimensions

Slider dimensions for a given design can be chosen based on following considerations:

- **1.** Decide the required length of the slider (L) based on application requirements. This is same as the "effective slider length" as Figure 137 shows.
- 2. Decide the height of the segment based on the available space on the board. Use the maximum allowed segment height (15 mm) if the board space permits; if not, use a lesser height but ensure that the height is greater than the minimum specified in Table 36.
- The slider-segment width and the air gap between slider segments should be as recommended in Table
 36. The recommended slider-segment-width and air-gap for an average finger diameter of 9 mm is 8 mm and 0.5 mm respectively.
- **4.** For a given slider length L, calculate the number of segments required by using the following formula:

Number of segments = $\frac{slider \, length}{slider \, segment \, width + \, airgap} + 1$

Equation 78 Number of segments required for a slider

Note: A minimum of two slider segments are required to implement a slider.

If the available number of CAPSENSE[™] pins is slightly less than the number of segments calculated for a certain application, you may increase the segment width to achieve the required slider length with the available number of pins. For example, a 10.2 cm slider requires 13 segments. However, if only 10 pins are available, the segment width may be increased to 10.6 cm. This will either result in a nonlinear response as Figure 144 shows, or a hover effect; however, this layout may be used if the end application does not need a high linearity.

Note: The PCB length is higher than the required slider length as Figure 137 shows. PCB length can be related to the slider length as shown in Equation 79.

PCB length = Slider length + 3 \times slider segment width + 2 \times air gap

Equation 79 Relationship between minimum PCB length and slider length

If the available PCB area is less than that required per this equation, you can remove the dummy segments. In this case, the minimum PCB length required will be as shown in Equation 80.



PCB length = *Slider length* + *Slider segment width*

Equation 80 Relationship between minimum PCB length and slider length

7.4.4.4 Routing slider segment trace

A slider has many segments, each of which is connected separately to the CAPSENSE^m input pin of the device. Each segment is separately scanned and the centroid algorithm is applied finally on the signal values of all the segments to calculate the centroid position. The SmartSense algorithm implements a specific tuning method for sliders to avoid nonlinearity in the centroid that could occur due to the difference of C_P in the segments. However, the following layout conditions need to be met for the slider to work:

- **1.** *C*_P of any segment should always be within the supported range of *C*_P as mentioned in the Component datasheet
- 2. *C*_P of the slider segment should be as close as possible. However, in the practical scenario C_P of each slider segment might vary because of differences in trace routing for each segment. The maximum allowed variation in the segment parasitic capacitance is 44% maximum *C*_P of the slider segment for an 85% IDAC calibration level. If the variation in *C*_P is beyond this limit then it may cause a change in the sensitivity among the slider segments leading to a non-linear slider response

Implement the following layout design rules to meet a good slider design with linear response.

- Design the shape of all segments to be as uniform as possible
- Ensure that the length and the width of the traces connecting the segments to the device are same for all the segments if possible
- Maintain the same air gap between the sensors or traces to ground plane or hatch fill

7.4.4.5 Slider design with LEDs

In some applications, it may be required to display the finger position by driving LEDs. You can either place the LEDs just above the slider segments or drill a hole in the middle of a slider segment for LED backlighting, as Figure 147 shows. When a hole is drilled for placing an LED, the effective area of the slider segment reduces. To achieve an SNR > 5:1, you need to have a slider segment with a width larger than the LED hole size. See Table 36 for the minimum slider width required to achieve an SNR > 5:1 for a given overlay thickness. Follow the guidelines provided in the Crosstalk solutions section to route the LED traces.



Figure 147 Slider design with LED backlighting



7.4.5 Sensor and device placement

Follow these guidelines while placing the sensor and the device in your PCB design:

- Minimize the trace length from the device pins to the sensor pad
- Mount series resistors within 10 mm of the device pins to reduce RF interference and provide ESD protection. See Series resistors on CAPSENSE[™] pins for details
- Mount the device and the other components on the bottom layer of the PCB
- Avoid connectors between the sensor and the device pins because connectors increase C_P and noise pickup
- Button to Button distance (edge to edge) must be greater than 8 mm. If keys have less than 8 mm between them, there will be cross talk between the keys. Also, from a usability standpoint, it increases the risk of the user touching two keys at the same time. Key to key distance must be greater than 8 mm
- Spacing from a touch line to any metal should be greater than 5 mm. This includes the metal chassis, decorative chrome trim, screws, and so on
- Isolate or provide physical separation between CAPSENSE[™] components and their signals from noisy subsystems such as transformers. A CAPSENSE[™] system in general is sensitive to external noise

7.4.6 Trace length and width

Use short and narrow PCB traces to minimize the parasitic capacitance of the sensor. The maximum recommended trace length is 12 inches (300 mm) for a standard PCB and 2 inches (50 mm) for flex circuits. The maximum recommended trace width is 7 mil (0.18 mm). You should surround the CAPSENSE[™] traces with a hatched ground or hatched shield with trace-to-hatch clearance of 10 mil to 20 mil (0.25 mm to 0.51 mm).

7.4.7 Trace routing

You should route the sensor traces on the bottom layer of the PCB, so that the finger does not interact with the traces. Do not route traces directly under any sensor pad unless the trace is connected to that sensor.

Do not run capacitive sensing traces closer than 0.25 mm to switching signals or communication lines. Increasing the distance between the sensing traces and other signals increases the noise immunity. If it is necessary to cross communication lines with sensor pins, make sure that the intersection is at right angles, as Figure 148 shows.





Figure 148 Routing of sensor and communication lines

If, due to spacing constraints, sensor traces run in parallel with high-speed traces such as I²C communication lines or Bluetooth[®] LE antenna traces, it is recommended to place a ground trace between the sensor trace and the high-speed trace as shown in Figure 149. This guideline also applies to the cross talk caused by CAPSENSE[™] sensor trace with precision analog trace such as traces from temperature sensor to the PSOC[™] device. The thickness of the ground trace can be 7 mils and the spacing from sensor trace to ground trace should be equal to minimum of 10 mils to reduce the C_P of the CAPSENSE[™] sensor.



Figure 149 Reducing cross talk between high-speed switching trace and CAPSENSE[™] trace

If a ground trace cannot be placed in between the switching trace and the CAPSENSE[™] trace, the 3W rule can be followed to reduce the cross talk between the traces. The 3W rule states that "to reduce cross talk from



adjacent traces, a minimum spacing of two trace widths should be maintained from edge to edge" as shown in Figure 150.



Figure 150 3W trace spacing to minimize cross talk

- Do not run Tx and Rx lines parallel to each other. The trace routing should be separated as much as possible
- If the layout constraints require Tx and Rx run parallel for short distances, the space between Tx and Rx should be greater than the distance between Tx and Rx inside the key (2 times the Tx-Rx key spacing is preferred) or add ground between them
- Keep as much clearance around Rx as possible to prevent noise on the touch keys. It is critical to follow this guideline for spacing to power traces and LED lines (high speed switching, power). Ground should also follow this rule, but it is less critical. Ground will provide noise protection but will reduce key sensitivity
- For a given set of sensors, the number of Rx lines must be less than or equal to Tx lines. Rx lines are susceptible to noise, whereas Tx lines are relatively less susceptible

7.4.8 Crosstalk solutions

A common backlighting technique for panels is an LED mounted under the sensor pad so that it is visible through a hole in the middle of the sensor pad. When the LED is switched ON or OFF, voltage transitions on the LED trace can create crosstalk in the capacitive sensor input, creating noisy sensor data. To prevent this crosstalk, isolate CAPSENSE[™] and the LED traces from one another as Trace routing section explains.

You can also reduce crosstalk by removing the rapid transitions in the LED drive voltage, by using a filter as Figure 151 shows. Design the filter based on the required LED response speed.





Figure 151 Reducing crosstalk

A guard trace is a ground trace running close to or above/below a TX/Rx line of a mutual-capacitance button. Guard traces can be used to protect sensor traces from noise if the layout does not allow for a ground hatch. Similar to ground hatch, guard traces add parasitic capacitance and reduce button sensitivity. Guard traces are usually needed on a case-by-case basis. Typical situations where guard traces have been used in the past include:

- Reduce cross talk
- Protect from noise of high-speed lines (I2C, SPI, UART) and toggling LED traces
- Border around the HMI or around an LCD

7.4.9 Vias

Use the minimum number of vias possible to route CAPSENSE[™] signals, to minimize parasitic capacitance. Place the vias on the edge of the sensor pad to reduce trace length, as Figure 152 shows.







7.4.10 Ground plane

When designing the ground plane, follow these guidelines:

- Ground surrounding the sensors should be in a hatch pattern. If you are using ground or driven-shield planes in both top and bottom layers of the PCB, you should use a 25 percent hatching on the top layer (7-mil line, 45-mil spacing), and 17 percent on the bottom layer (7 mil line, 70 mil spacing)
- For the other parts of the board not related to CAPSENSE[™], solid ground should be present as much as possible
- The ground planes on different layers should be stitched together as much as possible, depending on the PCB manufacturing costs. Higher amount of stitching results in lower ground inductance, and brings the chip ground closer to the supply ground. This is important especially when there is high current sinking through the ground, such as when the radio is operational
- Every ground plane used for CAPSENSE[™] should be star-connected to a central point, and this central point should be the sole return path to the supply ground. Specifically:
 - The hatch ground for all sensors must terminate at the central point
 - The ground plane for C_{MOD}, C_{INTX} must terminate at the central point
 - The ground plane for C_{SH TANK} must terminate at the central point

Figure 153 explains the star connection. The central point for different families is mentioned in Table 37.



Figure 153 Star connection for Ground

Table 37Central point for star connection

Family	Central point
PSOC [™] 4000	VSS pin
PSOC [™] 4100/4100M	VSS pin
PSOC [™] 4200/4200M/4200L/PSOC [™] 4-S/PSOC [™] 4100PS	VSS pin
(table continues)	

Application note

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7 Design considerations

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Table 37	(continued) Central point for star conr	nection
Family		Central point
PSOC [™] 4100-BL		E-pad
PSOC [™] 4200-BL		E-pad

 All the ground planes for CAPSENSE[™] should have an inductance of less than 0.2 nH from the central point. To achieve this, place the C_{MOD}, C_{INTx}, and C_{SH_TANK} capacitor pads close to the chip, and keep their ground planes thick enough

7.4.10.1 Using packages without E-pad

When not using the E-pad, the VSS pin should be the central point and the sole return path to the supply ground. High-level layout diagrams of the top and bottom layers of a board when using a chip without the E-pad are shown in Figure 154 and Figure 155.



Figure 154

PCB top layer layout using a chip without E-pad





Figure 155 PCB bottom layer layout using a chip without E-pad

7.4.10.2 Using packages with E-pad

If you are using packages with E-pad, the following guidelines must be followed:

- The E-pad must be the central point and the sole return path to the supply ground
- The E-pad must have vias underneath to connect to the next layers for additional grounding. Generally unfilled vias are used in a design for cost purposes, but silver-epoxy filled vias are recommended for the best performance as they result in the lowest inductance in the ground path

7.4.10.3 Using PSOC[™] 4 Bluetooth[®] LE devices

In the case of PSOC[™] 4 Bluetooth[®] LE devices in the QFN package (with E-pad):

- The general guidelines of ground plane (discussed above) apply
- The E-pad usage guidelines of Using packages with E-pad apply
- The VSSA pin should be connected to the E-pad below the chip itself
- The vias underneath the E-pad are recommended to be 5x5 vias of 10-mil size

High-level layout diagrams of the top and bottom layers of a board when using PSOC[™] 4 Bluetooth[®] LE chips are shown in Figure 156 and Figure 157.



E-pad the board Stitching to the ground on the next layer	Stitching to the ground		•	•	•	•	•	•	•	•	•	•	•	•	•	•	•	Vias u E-pad		der	th	e	•	•	•				Gro		d f	iU 1	fo	r.
			•			•		•	•	•	•	•	•	•	•	•	•										ne	00	art	-			*	
		•	•			•	•	•	•	•	•	•	•	•	•	•	•	•• •	•	•	•												•	
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						•			۰	•	۰	۰		٠	•	•			•	•			•		•	•	٠	•	•		•	•	•	1
					•			۰		•	۰	۰	•	۰	•	۰		1			٠	٠	۰	٠	•	•	•		•	٠	۰	•	•	
			•			•		•		۰	۰	٠	•	•	٠	۰		*****			۰		٠	٠	•	٠	٠	•	•	•	•	۰	•	11
					•					•					٠	•		*****			٠	۰	٠	٠	•		٠	•	•	•	۰	۰	0	
										•	•				•													•	٠		•		•	
		•	•								•		•			•								•	•		٠	۰	۰	۰	•	٠		18
												•	•								•		•		۰		٠	•	٠	۰	٠	۰	0	
															•										•		٠	•		•				1
													•									•	•					•		•	• -	-	θ	19
			-	XX	•0	2.6		•		888	100			2222		887			888					222			9382			82			988	2
		•													С	ap	Sei	nse Butt	on	IS									C. M. A. A.	ホススク	oui	nd		
							888								XXX					888					Ha	atc	hG	iro	une	d fi	H)			8
Hatch Ground fill	Hatch Ground fill	88		O(X)	VVV											VVV										$\sim \sim \sim$	VVV		$\sim \sim \sim \sim$	XXX	000			
Hatch Ground fill for Sensors			888	880				XXXX				COOX	2000	0000						XXX		XXXX	$\lambda \lambda D$		40	- C			XXQXX			000		

Figure 156 PCB top layer layout with PSOC[™] 4Bluetooth[®] LE (with E-pad)





Figure 157 PCB bottom layer layout with PSOC[™] 4 Bluetooth[®] LE (with E-pad)

7.4.11 Power supply layout recommendations

CAPSENSE[™] is a high-sensitivity analog system. Therefore, a poor PCB layout introduces noise in highsensitivity sensor configurations such as proximity sensors and buttons with thick overlays (>1 mm). To achieve low noise in a high-sensitivity CAPSENSE[™] design, the PCB layout should have decoupling capacitors on the power lines, as listed in Table 38.

Power line	Decoupling capacitors	Corresponding ground terminal	Applicable device family
VDD	0.1 μF and 1 μF	VSS	PSOC [™] 4000
VDDIO	0.1 μF and 1 μF	VSS	PSOC [™] 4000, PSOC [™] 6 MCU
VDDD	0.1 μF and 1 μF	VSS	PSOC [™] 4100, PSOC [™] 4200, PSOC [™] 6 MCU
	$0.1\mu\text{F}$ and $1\mu\text{F}$	VSSD	PSOC [™] 4100-BL, PSOC [™] 4200-BL, PSOC [™] 4200L, PSOC [™] S- series, PSOC [™] 4100S Plus, PSOC [™] 4100S Max
	See device datasheet	VSSD	PSOC [™] 4000T, PSOC [™] 4100T Plus

Table 38Decoupling capacitors on power lines

(table continues...)



Table 38	(continued) Decoupling capacitors on power lines				
Power line	Decoupling capacitors	Corresponding ground terminal	Applicable device family		
VDDA ¹⁾	0.1 μF and 1 μF (Battery powered supply)	VSSA	PSOC [™] 4100, PSOC [™] 4200, PSOC [™] 4100-BL, PSOC [™] 4200- BL, PSOC [™] 4200L, PSOC [™] 4S-Series, PSOC [™] 4100S Plus, PSOC [™] 4100PS, PSOC [™] 6 MCU		
	0.1 μF and 10 μF (Mains Powered supply)	VSSA	PSOC [™] 4S-series, PSOC [™] 4100S Plus, PSOC [™] 4100PS		
VDDR	0.1 μF and 1 μF	VSSD	PSOC [™] 4100-BL, PSOC [™] 4200-BL, PSOC [™] 6 MCU with Bluetooth [®] LE Connectivity		
VCCD	See device datasheet	VSS (PSOC [™] 4000) or VSSD (all others)	All device families		

The V_{DDA} pin on PSOC[™] 4 S-Series, PSOC[™] 4100S Plus, and PSOC[™] 4100PS family requires different values of bulk capacitor 1) depending on the power supply source. If the device is battery powered, it is recommended to use 0.1 µF and 1 µF capacitors in parallel and if the device is mains powered, it is recommended to use 0.1 µF and 10 µF in parallel. This is to improve the power supply rejection ratio of reference generator (REFGEN) used in the CAPSENSE[™] block.

The decoupling capacitors and C_{MOD} capacitor must be placed as close to the chip as possible to keep ground impedance and supply trace length as low as possible.

For further details on bypass capacitors, see the Power section in the Device datasheet.

7.4.12 Layout guidelines for liquid tolerance

As explained in the Liquid tolerance section, by implementing a shield electrode and a guard sensor, a liquidtolerant [™] system can be implemented. If there are multiple CSD blocks in the device, each CSD block should have a dedicated shield electrode. This section shows how to implement a shield electrode and a guard sensor.

7.4.12.1 Layout guidelines for shield electrode

The area of the shield electrode depends on the size of the liquid droplet and the area available on the board for implementing the shield electrode. The shield electrode should surround the sensor pads and traces, and spread no further than 1 cm from these features. Spreading the shield electrode beyond 1 cm has negligible effect on system performance.

Also, having a large shield electrode may increase radiated emissions. If the board area is very large, the area outside the 1-cm shield electrode should be left empty, as Figure 158 shows. The board design should focus on reducing the coupling capacitance between the liquid droplet and ground. Thus, for improved liquid tolerance, there should not be any hatch fill or a trace connected to ground in the top and bottom layers of the PCB.

When there is a grounded hatch fill or a trace then, when a liquid droplet falls on the touch surface, it may cause sensor false triggers. Even if there is a shield electrode between the sensor and ground, the effect of the shield electrode will be totally masked out and sensors may false trigger.

In some applications, there may not be sufficient area available on the PCB for shield electrode implementation. In such cases, the shield electrode can spread less than 1 cm; the minimum area for shield electrode can be the area remaining on the board after implementing the sensor.

In some applications, the capacitance of the shield electrode will be very high; you can reduce it with the following techniques:



- Using multiple shield electrode instead of single shield electrode: If there is a single hatch pattern with a higher C_P, split the hatch pattern into multiple hatch patterns and drive it with the shield signal to decrease the shield C_P. This will also allow the use of a higher range of sense clock frequencies for the sensors which will improve the sensitivity of the CAPSENSE[™] system. In a complex layout design, this approach will make trace routing simple
- Connecting multiple shield pins to the same electrode: If splitting the shield electrode in the layout is not feasible, connect multiple shield pins to the same electrode. This will make all the series resistance of the sensor pins in parallel and reduce the effective time constant of the shield electrode, which will allow using a higher range of sense clock frequencies for sensors, which will improve the sensitivity of the CAPSENSE[™] system



Figure 158 Shield electrode placement when sensor trace Is routed in top and bottom layer

Follow these guidelines to implement the shield electrode in two-layer and four-layer PCBs: Two-layer PCB:

- Top layer: Hatch fill with 7 mil trace and 45 mil grid (25 percent fill). Hatch fill should be connected to the driven-shield signal
- Bottom layer: Hatch fill with 7 mil trace and 70 mil grid (17 percent fill). Hatch fill should be connected to the driven-shield signal

Four (or more)-layer PCB:

- Top layer: Hatch fill with 7 mil trace and 45 mil grid (25 percent fill). Hatch fill should be connected to the driven-shield signal
- Layer-2: Hatch fill with 7 mil trace and 70 mil grid (17 percent fill). Hatch fill should be connected to the driven-shield signal
- Layer-3: V_{DD} Plane
- Bottom layer: Hatch fill with 7 mil trace and 70 mil grid (17 percent fill). Hatch fill should be connected to ground

The recommended air gap between the sensor and the shield electrode is 1 mm.



7.4.12.2 Layout guidelines for guard sensor

As explained in the Guard sensor section, the guard sensor is a copper trace that surrounds all sensors, as Figure 159 shows.



Figure 159 PCB layout with shield electrode and guard sensor

The guard sensor should be triggered only when there is a liquid stream on the touch surface. Ensure that the shield electrode pattern surrounds the guard sensor to prevent it from turning on due to liquid droplets. The guard sensor should be placed such that it meets the following conditions:

- It should be the first sensor to turn on when there is a liquid stream on the touch surface. To accomplish this, the guard sensor is usually placed such that it surrounds all sensors
- It should not be accidentally touched while pressing a button or slider sensor. Otherwise, the button sensors and slider sensor scanning will be disabled and the CAPSENSE[™] system will become nonoperational until the guard sensor is turned off. To ensure the guard sensor is not accidentally triggered, place the guard sensor at a distance greater than 1 cm from the sensors

Follow these guidelines to implement the guard sensor:

- The guard sensor should be in the shape of a rectangle with curved edges and should surround all the sensors
- The recommended thickness for a guard sensor is 2 mm
- The recommended clearance between the guard sensor and the shield electrode is 1 mm

If there is no space on the PCB for implementing a guard sensor, the guard sensor functionality can be implemented in the firmware. For example, you can use the ON/OFF status of different sensors to detect a liquid stream depending on the use case data.

The following conditions can be used to detect a liquid stream on the touch surface:

• When there is a liquid stream, more than one button sensor will be active at a time. If your design does not require multi-touch sensing, you can detect this and reject the sensor status of all the button sensors to prevent false triggering



- In a slider, if the slider segments which are turned ON are not adjacent segments, you can reset the slider segments status or reject the slider centroid value that is calculated
- A firmware algorithm to detect the false touch due to water drop from the use case data can be made to improve the false touch rejection capability sensors

7.4.12.3 Liquid tolerance with ground ring

In some applications, it is required to have a ground ring (solid trace or a hatch fill) around the periphery of the board for improved ESD performance, as shown in Figure 160. The ground ring is used to redirect the ESD as explained inRedirect. Having a ground ring around the board may result in sensor false triggers when liquid droplets fall in between the sensor and the ground sensor. Therefore, it is recommended not to have any ground in the top layer. If the design must have a ground ring in the top layer, use a ground ring with the minimum thickness (8 mils).



Figure 160 CAPSENSE[™] design with ground ring for improved ESD performance

7.4.13 Schematic rule checklist

Table 39 provides the checklist to verify your CAPSENSE[™] schematic.

No.	Category	Recommendations/Remarks
1	C _{MOD}	2.2 nF. X7R or NP0 capacitors can be used for C _{MOD} . X7R type C _{MOD} will experience very large raw count variation and probably saturation in applications where the temperature range is well above ambient (that is, > 50C). Hence, it is recommended to select the C _{MOD} capacitor type according to the expected operating temperature range. See Table 40 for pin selection.
2	C _{SH_TANK} ¹⁾	 10 nF if shield electrode is used; NA otherwise. See Driven shield signal and shield electrode and CAPSENSE[™] CSD shielding for details on shield electrode and use of C_{SH_TANK} respectively. See Table 40 for pin selection.
3	$C_{\rm INTA}/C_{\rm INTB}^{2)}$	470 pF. See Table 40 for pin selection.

Table 39Schematic rule checklist

(table continues...)



No.	Category	Recommendations/Remarks				
4	Series resistance on input lines	560 Ω for self-capacitance and 2 k Ω for mutual-capacitance. See Series resistors on CAPSENSE TM pins for details.				
5	Sensor pin selection	If possible, avoid pins that are close to the GPIOs carrying switching/ communication signals. Physically separate DC loads such as LEDs and I ² C pins from the CAPSENSE [™] pins by a full port wherever possible. See Sensor pin selection section for more details.				
6	GPIO source/sink current	Ensure that the total sink current through GPIOs is not greater than 40 mA when the CAPSENSE™ block is scanning the sensors.				
7	Series resistance on shield lines	560 Ω recommended on shield lines.				
8	Recommended	PSOC [™] 4100T Plus, the recommended ports are 0, 1, 3, 4, 5, 6.				
	CAPSENSE [™] PORT	PSOC [™] 4100S Max, the recommended ports are :				
		Channel 0: 3, 4, 6,10, 11, 12 and Channel 1: 0, 5, 7, 8, 9.				
		See AMUX Splitter switch noise for more details.				

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External capacitors pin selection 7.4.13.1

As explained in the CAPSENSE[™] fundamentals section, CAPSENSE[™] requires the following external capacitors for reliable operation - C_{MOD} (capacitive sigma-delta (CSD) sensing method), C_{TANK} (only when Shield is implemented), and C_{INTX} (CSX sensing method). Starting from PSOC[™] Creator 3.3 SP2, the number of pins that can support C_{MOD} and C_{SH_TANK} is increased to improve design flexibility. Table 40 lists the recommended pins for C_{MOD}, C_{INTX}, and C_{SH_TANK} capacitors for PSOC[™] Creator 3.3 SP2 or later versions.

Note: For PSOC[™] 4100/PSOC[™] 4200, if you select a pin other than P4[2] for C_{MOD}, P4[2] will not be available for any other function. For example, if you try routing C_{MOD} to P2[0] in PSOC[™] Creator for a PSOC[™] 4200 device, it uses both P2[0] and P4[2].

Table 40 Recommended pins for external capacitors					
Device	C _{MOD} (or C _{MOD1} for fifth- generation CAPSENSE™)	C _{SH_TANK} (or C _{MOD2} for fifth- generation CAPSENSE [™])			
PSOC [™] 4000	P0[4]	P0[2]			
PSOC [™] 4100/PSOC [™] 4200	P4[2]	P4[3]			
PSOC [™] 4200M/PSOC [™] 4200L	CSD0: P4[2]	CSD0: P4[3]			
	CSD1: P5[0]	CSD1: P5[1]			
PSOC [™] 4 Bluetooth [®] LE	P4[0]	P4[1]			
PSOC [™] 6 MCU	P7[1]	P7[2]			
PSOC [™] 4S-Series, PSOC [™] 4100S Plus	P4[2]	P4[3]			
PSOC [™] 4100PS	P5[2]	P5[3]			
(table continues)	1	l			

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Table 40 (continued) Recommended pins for external capacitors

Device	C _{MOD} (or C _{MOD1} for fifth- generation CAPSENSE™)	C _{SH_TANK} (or C _{MOD2} for fifth- generation CAPSENSE™)	
PSOC [™] 4100S Max	Channel0: P4[0]	Channel0: P4[1]	
	Channel1: P7[0]	Channel1: P7[1]	
PSOC [™] 4000T	P4[2]	P4[3]	
PSOC [™] 4100T Plus	P1[0]	P1[1]	

Table 41

Supported pins for external capacitors

Device	C _{MOD} (or C _{MOD1} for fifth-generation CAPSENSE™)	for fifth-generation for fifth-generation		C _{INT B}	
PSOC [™] 4000	Port0[0:7], Port1 [0:7]P2[0]	Port0 [0:7], Port1 [0:7]P2[0]	P0[4]	P0[2]	
PSOC [™] 4100 Port0 [0:7], Port1 Port0 [0:7], Port1 [0:7]Port2 [0:7], Port3 [0:7]Port2 [0:7], Port3 [0:7]Port2 [0:7], Port3 [0:7]P4[2] [0:7]P4[3]			Not supported	Not supported	
PSOC [™] 4200	Port0 [0:7], Port1 [0:7]Port2 [0:7], Port3 [0:7]P4[2]	Port0 [0:7], Port1 [0:7], Port2 [0:7], Port3 [0:7]P4[3]	Port0 [0:7], Port1 [0:7]Port2 [0:7], Port3 [0:7]	Port0 [0:7], Port1 [0:7]Port2 [0:7], Port3 [0:7]	
PSOC [™] 4200M	CSD0:	CSD0:	CSD0: P4[2]	CSD0: P4[3]	
	Port0 [0:7], Port1 [0:7] Port2 [0:7], Port3 [0:7] Port4 [0:6], Port6 [0:5] Port7 [0:1]	Port0 [0:7], Port1 [0:7]Port2 [0:7], Port3 [0:7], Port4 [0:6], Port6 [0:5] Port7 [0:1]			
	CSD1: Not supported	CSD1: Not supported	CSD1: Not supported	CSD1: Not supported	
PSOC [™] 4200L	CSD0: Port0 [0:7], Port1 [0:7] Port2 [0:7], Port3 [0:7] Port4 [0:6], Port6 [0:5] Port7 [0:7], Port10 [0:7], Port11 [0:7]	CSD0: Port0 [0:7], Port1 [0:7] Port2 [0:7], Port3 [0:7] Port4 [0:6], Port6 [0:5] Port7 [0:7], Port10 [0:7] Port11 [0:7]	CSD0: P4[2]	CSD0: P4[3]	
	CSD1: Port5 [0:7], Port8 [0:7] Port9 [0:7]	CSD1: Port5 [0:7], Port8 [0:7] Port9 [0:7]	CSD1: P5[0]	CSD1: P5[1]	
PSOC [™] 4 Bluetooth [®] LE	Port0 [0:7], Port1 [0:7]Port2 [0:7], Port3 [0:7]Port4 [0:1], Port5 [0:1]Port6 [0:1]	Port0 [0:7], Port1 [0:7]Port2 [0:7], Port3 [0:7]Port4 [0:1], Port5 [0:1]Port6 [0:1]	P4[0]	P4[1]	



Device	C _{MOD} (or C _{MOD1} for fifth-generation CAPSENSE™)	C _{SH_TANK} (or C _{MOD2} for fifth-generation CAPSENSE™)	C _{INTA}	C _{INT B}
PSOC [™] 4S- Series, PSOC [™] 4100S Plus	P4[2], P4[3], P4[1]	P4[2], P4[3], P4[1]	P4[2]	P4[3]
PSOC [™] 4100PS	P5[0], P5[2], P5[3]	P5[0], P5[2], P5[3]	P5[2]	P5[3]
PSOC [™] 4100S	Channel0: P4[0], P4[2]	Channel0: P4[1], P4[3]	Not applicable	Not applicable
Max ¹⁾	Channel1: P7[0], P5[1]	Channel1: P7[1], P5[2]		
PSOC [™] 4000T	P4[2]	P4[3]	Not applicable	Not applicable
PSOC™ 4100T Plus	P1[0]	P1[1]	Not applicable	Not applicable

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Sensor pin selection 7.4.13.2

As explained in CAPSENSE[™] fundamentals, PSOC[™] supports CSD and CSX capacitive sensing methods. Each CSD sensor requires a single sensor pin and CSX sensor will require two sensor pins for Tx and Rx electrode in addition to the required external capacitors for each sensing technique.

The selection of the sensor pins should be in a way such that the CAPSENSE[™] sensor traces and communication or other toggling GPIO traces are isolated by proper port/pin assignment. The following are some recommended guidelines:

- Isolate switching signals, such as PWM, I2C communication lines, and LEDs from the sensor and sensor traces. Place them at least 4 mm apart and fill a hatched ground between the CAPSENSE™ traces and the switching signals to avoid crosstalk
- Distribute the placement of DC loads on different ports to reduce the noise in CAPSENSE[™]. It is recommended to have digital I/Os spread on different ports rather than concentrating in a single port
- While the CAPSENSE[™] block is scanning the sensor, limit the total source or sink current through GPIOs to • less than 40 mA while the CAPSENSE[™] block is scanning the sensor. Sinking a current greater than 40 mA while the CAPSENSE[™] sensor is scanning may result in excessive noise in the sensor raw count
- For a PSOC[™] 4 device it is recommended to place all the digital DC loads like LEDs, I2C/UART communication pins on the port powered by only VSSD; see the Device datasheet for determining the ports that are powered by VSSD. Placing DC loads on ports powered by VSSA will shift the VSSA up. Since CAPSENSE[™] is powered by VSSA, it will affect its performance
- For PSOC[™] 6 family of devices: •
 - Table 42 lists the ports that support CAPSENSE[™], selecting ports 5, 6, 7, and 8 for CAPSENSE[™] ensures lesser noise
 - It is recommended to place all digital switching pins such as LEDs, I²C, UART, SPI, SMIF communication pins on the ports that are powered by a different power supply domain which is not shared with the CAPSENSE[™] ports. Table 43 lists the ports, their supply domains, and recommendations for using these ports with CAPSENSE[™]. For more details, see the Errata section of the Device datasheet. A deviation from these guidelines might cause a noise due to level shift in raw count. For more details, see Raw counts show a level-shift or increased noise when GPIOs are toggled. To isolate the supply domains further, it is better to externally isolate them using ferrite beads as shown in Figure 162



Table 42 CAPSE	ENSE™ capable ports in PSOC™ 6 devices
Device	CAPSENSE™ capable ports
CY8C62x6, CY8C62x7	P0, P1, P2, P4, P5, P6, P7, P8, P9, P10, P11
CY8C63x6, CY8C63x7	P0, P1, P2, P4, P5, P6, P7, P8, P9, P10, P11
CY8C62x5	P7.0 to P7.7, P8.0 to P8.3, P9.0 to P9.3

Table 43

Recommendations of port usage with CAPSENSE[™] for PSOC[™] 6 device

Ports	Supply domain	Recommended for CAPSENSE™	Recommendations for GPIOs if used for communication, LEDs, and other high frequency functionality with CAPSENSE™
P0	VBACKUP	No*	Switching frequency < 8 MHz
P1	VDDD	No*	Switching frequency < 1 MHz, SLOW Slew Rate
P2, P3, P4	VDDIO2	No*	Switching frequency < 25 MHz
P5, P6, P7, P8	VDDIO1	Yes	Not recommended
P9, P10	VDDIOA	No*	Switching frequency < 1 MHz, SLOW Slew Rate
P11, P12, P13	VDDIO0	No*	Switching frequency < 80 MHz
P14	VDDUSB	No*	NA

Note: * If you need additional CAPSENSE[™] pins and if you must use GPIOs in ports P1, P9, and P10 as Tx electrode for CSX sensor, restrict the Tx clock frequency within 1 MHz and use SLOW slew rate. Figure 161 shows an example on how to select the **Slew Rate** of the GPIO using the Device configurator in the ModusToolbox[™] project. Note that using the ports other than the recommended ports for CAPSENSE[™] might cause higher noise in raw count.







Selecting slew rate for GPIOs



Figure 162 Externally isolated supply domains

7.4.14 Layout rule checklist

Table 44 provides the checklist to help verify your layout design.

Table 44Layout rule checklist

No.	Category		Minimum value	Maximum value	Recommendations/Remarks
1	Button	Shape	N/A	N/A	Circle or rectangular with curved edges
		Size	5 mm	15 mm	10 mm

(table continues...)



No.	Category		Minimum value	Maximum value	Recommendations/Remarks
		Clearance to ground hatch	0.5 mm	2 mm	Should be equal to overlay thickness
2	Slider	Width of segment	1.5 mm	8 mm	8 mm
		Clearance between segments	0.5 mm	2 mm	0.5 mm
		Height of segment	7 mm	15 mm	12 mm
3	Overlay	Туре	N/A	N/A	Material with high relative permittivity (except conductors) Remove any air gap between sensor board and overlay/front panel of the casing.
		Thickness for buttons	N/A	5 mm	
		Thickness for sliders	N/A	5 mm	
		Thickness for touchpads	N/A	0.5 mm	
4	Sensor traces	Width	N/A	7 mil	Use the minimum width possible with the PCB technology that you use.
		Length	N/A	300 mm for a standard (FR4) PCB 50 mm for flex PCB	Keep as low as possible.
		Clearance to ground and other traces	0.25 mm	N/A	Use maximum clearance while keeping the trace length as low as possible.
		Routing	N/A	N/A	Route on the opposite side of the sensor layer. Isolate from other traces. If any non-CAPSENSE [™] trace crosses the CAPSENSE [™] trace, ensure that intersection is orthogonal. Do not use sharp turns.
5	Via	Number of vias	1	2	At least one via is required to route the traces on the opposite side of the sensor layer.

Table 44 (continued) Layout rule checklist

(table continues...)


No.	Category		Minimum value	Maximum value	Recommendations/Remarks
		Hole size	N/A	N/A	10 mil
6	Ground	Hatch fill percentage	N/A	N/A	Use hatch ground to reduce parasitic capacitance. Typical hatching: 25% on the top layer (7 mil line, 45 mil spacing) 17% on the bottom layer (7 mil
		Discourses	N1 / A		line, 70 mil spacing)
7	Series resistor	Placement	N/A	N/A	Place the resistor within 10 mm of the PSOC [™] pin. See Figure 163 for an example placement of series resistance on board.
8	Shield electrode	Spread	N/A	1 cm	If you have PCB space, use 1-cm spread.
9	Guard sensor (for	Shape	N/A	N/A	Rectangle with curved edges
	water tolerance)	Thickness	N/A	N/A	Recommended thickness of guard trace is 2 mm and distance of guard trace to shield electrode is 1 mm.
10	0 Ground Ring(for ESD protection)	Shape	N/A	N/A	Around the board periphery with curved edges. Can be a solid trace or a hatch fill.
		Thickness	N/A	N/A	Not recommended in top layer as it can cause sensor false triggers with liquid droplets. If design mus have a Ground Ring in the top layer, use a minimum thickness ring of 8 mils.
11	C _{MOD}	Placement	N/A	N/A	Place close to the PSOC TM pin. See Figure 163 for an example placement of C_{MOD} on PCB.
12	C _{SH_TANK}	Placement	N/A	N/A	Place close to the PSOC TM pin. See Figure 163 for an example placement of $C_{SH_{TANK}}$ on board.
13	C _{INTA}	Placement	N/A	N/A	Place close to the PSOC TM pin. See Figure 163 for an example placement of C_{INTA} on the PCB.
14	C _{INTB}	Placement	N/A	N/A	Place close to the PSOC ^{M} pin. See Figure 163 for an example placement of C _{INTA} on the PCB.

Table 44 (continued) Layout rule checklist





Figure 163 Example placement for C_{MOD} , C_{INTx} , $C_{SH_{TANK}}$, and series resistance on input lines in the PSOCTM 4200M device

7.5 Noise in CAPSENSE[™] system

7.5.1 Finger injected noise

If the power supply design of the system is poor, the power and ground supplies of a device fluctuates in voltage relative to the finger ground (earth ground) in a common mode fashion. This type of noise is called common mode noise. Figure 164 illustrates the common mode noise, where both the 5 V and the 0 V output leads of the power supply remain 5 V from each other, but they move up and down together, in a "common mode" manner.

This is not a problem, until a finger touch occurs on the button. A finger touch on the button introduces a (capacitive) path to the same earth ground and it will create a path for charge flow, which is equivalent to a noise signal injected exactly at the finger touch location. This injected noise caused by the common mode noise in power supply is called finger injected noise. It is observed only during the finger touch on the button in AC powered application and it doesn't occur in battery powered application.





Figure 164 Common mode noise in the power supply

Note: When the complete system powered by AC supply is held in hand of the user, the entire system will be grounded to earth sufficiently and no significant "common-mode" noise would flow through the touching finger to earth. However, if the system is connected to the power supply and placed on a desk, a touch on the button, can introduce a problematic discharge path to ground.

7.5.1.1 Recommendations to reduce the finger injected noise

The finger injected noise could be reduced by properly following the layout and schematics guidelines described in this section. The general recommendations to reduce the finger injected noise is explained below.

1. Fill the PCB board around the button with hatched pattern and connected it to device ground. Follow the recommendations as mentioned in the section Ground plane.

Figure 165 shows the impact of ground on the finger injected noise for mutual capacitance button and it is also true for CSD sensing technique. In the left figure, the system doesn't have the hatched ground around the button and most of the injected noise through the finger pass to the Rx pin of the device through the Capacitance formed between the finger and Rx electrode. In the right figure, the system has the hatched ground around the button and thus the finger injected noise is having an alternate path to flow which results in the reduction of the noise reaching to the device Rx pin.





Figure 165 Effect of ground on finger injected noise

- 2. Better power supply design of the system could easily eliminate the common mode noise, which will in turn reduce the finger injected noise
- 3. Use software technique that are available in the CAPSENSE[™] component to combat the finger injected noise such as selecting optimal sensing clock frequency and Multi frequency scanning, and so on
- **4.** Increase the overlay thickness will reduce the finger injected noise as it will decrease the capacitance formed between the finger and Rx electrode

7.5.2 VDDA noise

The noise in the system due to unwanted voltage ripples in the VDD supply is called VDDA noise.



7.5.2.1 Recommendations to reduce the VDDA noise

The VDDA noise could be reduced by properly following the layout and schematics guidelines in this chapter. The general recommendations to reduce the VDDA noise as follows:

- 1. Use clean power supply and have VDD ripples below the limits mentioned in the device datasheet
- 2. Use filters or an LDO regulator on the VDD power lines. Fifth-gen and fifth-gen low-power CAPSENSE[™] devices are more robust towards power supply ripple compared to previous-generation CAPSENSE[™] devices. The user may not need any LDO to design with these devices if the power supply ripple is within the limits mentioned in the datasheet. However, the user is advised to validate and ensure that overall system-level performance requirements are met
- **3.** Use decoupling capacitors on the power supply pins to reduce the conducted noise from the power supply
- 4. To reduce high-frequency noise, place a ferrite bead around power supply or communication lines
- **5.** Selecting the proper supply configuration as mentioned in the Power section in the Device datasheet and using the internal regulator to the device might help in reducing the VDDA noise

7.5.3 External noise

Any noise that is injected into to the system through the routing trace lines like ESD, EMI, conducted noise are coming into the category of external noise. The recommended guidelines for reducing the impact of the external noise are discussed in this section.

7.5.3.1 ESD protection

The nonconductive overlay material used in CAPSENSE[™] provides inherent protection against ESD. Table 45 lists the thickness of various overlay materials, required to protect the CAPSENSE[™] sensors from a 12 kV discharge (according to the IEC 61000 4 2 specification).

Material	Breakdown voltage (V/mm)	Minimum overlay thickness for protection against 12 kV ESD (mm		
Air	1200 – 2800	10		
Wood – dry	3900	3		
Glass – common	7900	1.5		
Glass – Borosilicate (Pyrex [®])	13,000	0.9		
PMMA Plastic (Plexiglas [®])	13,000	0.9		
ABS	16,000	0.8		
Polycarbonate (Lexan [®])	16,000	0.8		
Formica	18,000	0.7		
FR-4	28,000	0.4		
PET Film (Mylar [®])	280,000	0.04		
Polyimide Film (Kapton [®])	290,000	0.04		

Table 45Overlay thickness for ESD protection
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If the overlay material does not provide sufficient protection (for example, ESD from other directions), you can apply other ESD counter-measures, in the following order: Prevent, Redirect, and ESD protection devices.



7.5.3.1.1 Preventing ESD discharge

Preventing the ESD discharge from reaching the PSOC[™] is the best countermeasure you can take. Make sure that all paths to PSOC[™] have a breakdown voltage greater than the maximum ESD voltage possible at the surface of the equipment. You should also maintain an appropriate distance between the PSOC[™] and possible ESD sources. In the example illustrated in Figure 166, if L1 and L2 are greater than 10 mm, the system can withstand a 12 kV ESD.





If it is not possible to maintain adequate distance, place a protective layer of nonconductive material with a high breakdown voltage between the possible ESD source and PSOC[™]. One layer of 5 mil thick Kapton[®] tape can withstand 18 kV. See Table 45 for other material dielectric strengths.

7.5.3.1.2 Redirect

If your product is densely packed, preventing the discharge event may not be possible. In such cases, you can protect the PSOC[™] from ESD by redirecting the ESD. A standard practice is to place a ground ring on the perimeter of the circuit board, as Figure 167 shows. The ground ring should connect to the chassis ground. Using a hatched ground plane around the button or slider sensor can also redirect the ESD event away from the sensor and PSOC[™].







7.5.3.1.3 ESD protection devices

You can use ESD protection devices on vulnerable traces. Select ESD protection devices with a low input capacitance to avoid reduction in CAPSENSE[™] sensitivity. Table 46 lists the recommended ESD protection devices.

ESD protection	device	Input	Leakage	Contact	Air discharge maximum ESD	
Manufacturer Part number		capacitance	current	maximum ESD limit	limit	
Littelfuse	SP723	5 pF	2 nA	8 kV	15 kV	
Vishay	VBUS05L1-DD1	0.3 pF	0.1 µA	±15 kV	±16 kV	
NXP	NUP1301	0.75 pF	30 nA	8 kV	15 kV	

Table 46ESD protection devices

7.5.3.2 Electromagnetic compatibility (EMC) considerations

EMC is related to the generation, transmission, and reception of electromagnetic energy that can affect the working of an electronic system. Electronic devices are required to comply with specific limits for emitted energy and susceptibility to external events. Several regulatory bodies worldwide set regional regulations to help ensure that electronic devices do not interfere with each other.

CMOS analog and digital circuits have very high input impedance. As a result, they are sensitive to external electric fields. Therefore, you should take adequate precautions to ensure their proper operation in the presence of radiated and conducted noise.

Computing devices are regulated in the US by the FCC under Part 15, Sub-Part B for unintentional radiators. The standards for Europe and the rest of the world are adapted from CENELEC. These are covered under CISPR standards (dual-labeled as ENxxxx standards) for emissions, and under IEC standards (also dual labeled as ENxxxx standards) for immunity and safety concerns.

The general emission specification is EN55022 for computing devices. This standard cover both radiated and conducted emissions. Medical devices in the US are not regulated by the FCC, but rather are regulated by FDA rules, which include requirements of EN55011, the European norm for medical devices. Devices that include motor controls are covered under EN55014 and lighting devices are covered under EN50015.

These specifications have essentially similar performance limitations for radiated and conducted emissions. Radiated and conducted immunity (susceptibility) performance requirements are specified by several sections of EN61000-4. Line voltage transients, ESD and some safety issues are also covered in this standard.

7.5.3.2.1 Radiated interference and emissions

While PSOC[™] 4 and PRoC Bluetooth[®] LE offer a robust CAPSENSE[™] performance, radiated electrical energy can influence system measurements and potentially influence the operation of the CAPSENSE[™] processor core. Interference enters the CAPSENSE[™] device at the PCB level through sensor traces and through other digital and analog inputs. CAPSENSE[™] devices can also contribute to electromagnetic compatibility (EMC) issues in the form of radiated emissions.

Use the following techniques to minimize the radiated interference and emissions.

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7 Design considerations

Hardware considerations

Ground Pane

In general, proper ground plane on the PCB reduces both RF emissions and interference. However, solid grounds near CAPSENSE[™] sensors or traces connecting these sensors to PSOC[™] pins increase the parasitic capacitance of the sensors. It is thus recommended to use hatched ground planes surrounding the sensor and on the bottom layer of the PCBs, below the sensors, as explained in the Ground plane section in PCB layout guidelines. Solid ground may be used below the device and other circuitry on the PCB which is farther from CAPSENSE[™] sensors and traces. A solid ground flood is not recommended within 1 cm of CAPSENSE[™] sensors or traces.

Series resistors on CAPSENSE[™] pins

Every CAPSENSE^M controller pin has some parasitic capacitance (C_P) associated with it. As Figure 168 shows, adding an external resistor forms a low-pass RC filter that attenuates the RF noise amplitude coupled to the pin. This resistance also forms a low-pass filter with the parasitic capacitance of the CAPSENSE^M sensor that significantly reduces the RF emissions.



Figure 168 RC filter

Series resistors should be placed close to the device pins so that the radiated noise picked by the traces gets filtered at the input of the device. Thus, it is recommended to place series resistors within 10 mm of the pins. For CAPSENSETM designs using copper on PCBs, the recommended series resistance for CAPSENSETM input lines is 560 Ω . Adding resistance increases the time constant of the switched-capacitor circuit that converts C_P into an equivalent resistor; see GPIO cell capacitance to current converter. If the series resistance value is larger than 560 Ω , the slower time constant of the switching circuit suppresses the emissions and interference, but limits the amount of charge that can transfer. This lowers the signal level, which in turn lowers the SNR. Smaller values are better in terms of SNR, but are less effective at blocking RF.

Series resistors on digital communication lines

Communication lines, such as I²C and SPI, also benefit from series resistance; 330 Ω is the recommended value for series resistance on communication lines. Communication lines have long traces that act as antennae similar to the CAPSENSETM traces. The recommended pull-up resistor value for I²C communication lines is 4.7 k Ω . If more than 330 Ω is placed in series on these lines, the V_{IL} and V_{IH} voltage levels may fall out of specifications. 330 Ω will not affect I²C operation as the VIL level still remains within the I²C specification limit of 0.3 V_{DD} when PSOCTM outputs a LOW.





Figure 169 Series resistors on communication lines

Trace length

Long traces can pick up more noise than short traces. Long traces also add to C_P. Minimize the trace length whenever possible.

Current loop area

Another important layout consideration is to minimize the return path for currents. This is important as the current flows in loops. Unless there is a proper return path for high-speed signals, the return current will flow through a longer return path forming a larger loop, thus leading to increased emissions and interference.

If you isolate the CAPSENSE[™] ground hatch and the ground fill around the device, the sensor-switching current may take a longer return path, as Figure 170 shows. As the CAPSENSE[™] sensors are switched at a high frequency, the return current may cause serious EMC issues. Therefore, you should use a single ground hatch, as Figure 171 shows.







Improper current loop layout



Figure 171 Proper current loop layout

RF source location

If your system has a circuit that generates RF noise, such as a switched-mode power supply (SMPS) or an inverter, you should place these circuits away from the CAPSENSE[™] interface. You should also shield such circuits to reduce the emitted RF. Figure 172 shows an example of separating the RF noise source from the CAPSENSE[™] interface.





Figure 172 Separating noise sources

Firmware considerations

The following parameters affect Radiated Emissions (RE) in a CAPSENSE[™] system:

- Device operating voltage
- Device operation frequency
- Sensor switching frequency
- Shield signal
- Sensor scan time
- Sense Clock Source Inactive sensor termination

The following sections explain the effect of each parameter.

Device operating voltage

The emission is directly proportional to the voltage levels at which switching happens. Reducing the operating voltage helps to reduce the emissions as the amplitude of the switching signal at any output pin directly depends on the operating voltage of the device.

PSOC[™] allows you to operate at lower operating voltages, thereby reducing the emissions. Figure 173 and Figure 174 show the impact of operating voltage on radiated emissions. Because IMO = 24 MHz, there is a spike at 24 MHz and the other spikes are caused by different hardware and firmware operations of the device.









Figure 174 Effect of V_{DD} on radiated emissions (30 MHz – 1 GHz)

Note: Frequency axis is in log scale.



Device operating frequency

Reducing the system clock frequency (IMO frequency) reduces radiated emissions. However, reducing the IMO frequency may not feasible in all applications because the IMO frequency impacts the CPU clock and all other system timings. Choose a suitable IMO frequency based on your application.

Sensor-switching frequency

Reducing the sensor-switching frequency (see Sense clock) also helps to reduce radiated emissions. See Figure 175 and Figure 176. Because IMO = 24 MHz, there is a spike at 24 MHz and the other spikes are caused by different hardware and firmware operations of the device.



Figure 175 Effect of sensor-switching frequency on radiated emissions (150 kHz – 30 MHz)







Note: Frequency axis is in log scale.

Pseudo random sense clock

The PSOC[™] 4 device supports PRS-based sense clock generation. A PRS is used instead of a fixed clock source to attenuate emitted noise on the CAPSENSE[™] pins by reducing the amount of EMI created by a fixed-frequency source and to increase EMI immunity from other sources and their harmonics.

Spread spectrum sense clock

In addition to the PRS-based clock generation, the PSOC[™] 4 S-Series, PSOC[™] 4100S Plus, PSOC[™] 4100PS, and PSOC[™] 6 MCU family of devices supports a unique feature called spread spectrum sense clock generation, in which the sense clock frequency is spread over a desired range. This method will help to reduce the peaks and spread out the emissions over a range of frequencies. The spread spectrum clock can be enabled by selecting the **Sense Clock Source** as **SSCn**. The range of frequency spread is decided by the length of the register. For more details on the spread spectrum clock generation in the PSOC[™] 4 S-Series, PSOC[™] 4100S Plus, and PSOC[™] 4100PS family, see the Spread spectrum clock section in the CAPSENSE[™] chapter of the respective device Technical reference manual.



lame: CapSense_1		
	ilt-in Settings Widget Details	4
Scan settings Modulator clock frequency (k Actual frequency (kHz): Sense clock source: Enable common sense clock Sense clock frequency (k Actual frequency (kHz): Inactive sensor connection:	Hz): 24000 - 24000 SSC3 - Direct Auto	Enable shield electrode Enable shield electrode for reliable operation in the presence of water droplets
Enable IDAC auto-calibra Enable compensation ID/ Datasheet	ion	OK Apply Cancel

Figure 177 Sense clock sources in PSOC[™] 4 S-Series, PSOC[™] 4100S Plus, and PSOC[™] 4100PS family

Shield signal

Shield signal

Enabling the shield signal (see Driven shield signal and shield electrode) on the hatch pattern increases the radiated emissions. Enable the driven-shield signal only for liquid-tolerant, proximity-sensing, or high-parasitic-capacitance designs. Also, if the shield must be used, ensure that the shield electrode area is limited to a width of 1 cm from the sensors, as Figure 158 shows.

Figure 178 and Figure 179 show the impact of enabling the driven-shield signal on the hatch pattern surrounding the sensors on radiated emissions.

Note: In these figures, the hatch pattern is grounded when the driven-shield signal is disabled. Because IMO = 24 MHz, there is a spike at 24 MHz and the other spikes are caused by different hardware and firmware operations of the device.





Figure 178 Effect of shield electrode on radiated emissions (150 kHz – 30 MHz)









Sensor scan time

Reducing the sensor scan time reduces the average radiated emissions. The sensor-scan time depends on the scan resolution and modulator clock divider (see Equation 9). Increasing the scan resolution or modulator clock divider increases the scan time.

Figure 180 and Figure 181 show the impact of sensor scan time on radiated emissions. Note that, here, the sensor scan time was varied by changing the scan resolution. Because IMO = 24 MHz, there is a spike at 24 MHz and the other spikes are caused by different hardware and firmware operations of the device.

Table 47	Sensor scan time

Parameter	Total scan time for five buttons			
	0.426 ms	0.106 ms		
Modulation clock divider	2	2		
Scan resolution	10 bits	8 bits		
Individual sensor scan time	0.085 ms	0.021 ms		





Effect of scan time on radiated emissions (150 kHz - 30 MHz)





Figure 181 Effect of scan time on radiated emissions (30 MHz – 1 GHz)



Sense clock source

Using PRS instead of direct clock drive as sense clock source spreads the radiated spectrum and hence reduces the average radiated emissions. See Figure 182 and Figure 183. Because IMO = 24 MHz, there is a spike at 24 MHz and the other spikes are caused by different hardware and firmware operations of the device.





Figure 182 Effect of sense clock source on radiated emissions (150 kHz – 30 MHz)









Inactive sensor termination

Connecting inactive sensors to ground reduces the radiated emission by a greater degree than connecting them to the shield. Figure 184 and Figure 185 show the impact of different inactive sensor terminations on radiated emission. Because IMO = 24 MHz, there is a spike at 24 MHz and the other spikes are caused by different hardware and firmware operations of the device.



Figure 184 Effect of inactive sensor termination on radiated emissions (150 kHz – 30 MHz)





Figure 185 Effect of inactive sensor termination on radiated emissions (30 MHz – 1 GHz)

Note: Frequency axis is in log scale.

7.5.3.2.2 Conducted RF noise

The noise current that enters the CAPSENSE[™] system through the power and communication lines is called conducted noise. You can use the following techniques to reduce the conducted RF noise.

- Use decoupling capacitors on the power supply pins to reduce the conducted noise from the power supply. See section Power supply layout recommendations and the Device datasheet for details
- Provide GND and VDD planes on the PCB to reduce current loops
- If the PSOC[™] PCB is connected to the power supply using a cable, minimize the cable length and consider using a shielded cable

To reduce high-frequency noise, place a ferrite bead around power supply or communication lines.

7.5.4 AMUX Splitter switch noise

Note: This section is specific to PSOC[™] 4100S Max, and PSOC[™] 4100T Plus devices.

For optimal performance of CAPSENSE[™], it is recommended to use the pins directly connected to the same section of the AMUXBUS as the MSCLP block. This delivers better SNR compared to pins routed through the AMUXSPLITTER switches. Using directly connected pins, helps avoid the parasitic effect of the AMUXSPLITTER switches. Refer to Table 48, for recommended ports.



Table 48 Recommended port configurations			
Device		Recommended ports	
PSOC [™] 4100T	Plus	0, 1, 3, 4, 5, 6	
PSOC [™] 4100S	Мах	Channel 0: 3, 4, 6,10, 11, 12	
		Channel 1: 0, 5, 7, 8, 9	

Refer Figure 186, which illustrates an example of a 4100T Plus device, where Port 2 pins are routed through the AMUX splitter switches.



Figure 186 Splitter switches

7.6 Effect of grounding

7.6.1 CSX method

The equivalent capacitances formed in the CSX method when a finger touches the CSX sensor is shown in Figure 187. From Figure 187, current drawn from the IDAC (IRX) has two components: I_{mt} and I_{sc} . These two components depend on the ratio of C_{bodyDG}/C_{fs} . Because the raw count depends on the amount of current drawn from IDAC, the increase and decrease of C_{bodyDG}/C_{fs} will affect the raw count of the sensor and cause a sudden change in the behavior on some conditions. To understand it better, consider two extreme conditions which cause $C_{bodyDG} >> C_{fs}$ and $C_{bodyDG} << C_{fs}$.





Figure 187 Equivalent circuit of the CSX sensor when finger is placed on the button

Where,

 $C_{\rm M}$ = Mutual capacitance between the Rx and Tx electrode

 C_{fs} = Capacitance formed between the surface of the finger and electrode

 $C_{\rm fm}$ = Virtual capacitance which reduces the mutual-capacitance C_M due to placing a finger

 C_{bodyDG} = Body capacitance relative to the device ground

 $I_{RX} = I_{mt} + I_{sc}$

Equation 81 Current drawn from IDAC in CSX method

 $I_{\rm mt}$ is due to the effective mutual-capacitance between the Tx and Rx electrode.

 $I_{\rm sc}$ = Parasitic current that flows due to the capacitance formed between the sensor and finger

7.6.1.1 CbodyDG≫Cfs

Because C_{bodyDG} >> C_{fs} , you can replace C_{bodyDG} with a ground conductor; the resulting equivalent circuit appears as shown in Figure 188. Whenever there is a finger touch, the current drawn from the IDAC is directly dependent upon the effective mutual-capacitance between the Tx and Rx. This condition is observed in a good board design.







7.6.1.2 CbodyDG≪Cfs

This condition ($C_{bodyDG} << C_{fs}$) is observed when a finger touches a CSX button with a very thin overlay or no overlay, or a finger touching the Rx and Tx electrodes directly, or a water drop being present on the Rx and Tx electrode only. Because $C_{bodyDG} << C_{fs}$, you can remove C_{bodyDG} ; the equivalent circuit for this case is as shown in Figure 189. In this condition, the capacitance introduced by the finger to the electrode C_{fs} is very high compared to the capacitance of the finger relative to the device ground C_{bodyDG} .

From Figure 189, it forms a balanced bridge circuit. Due to this, no current flows through C_{fm} , and also due to increase in C_{fs} , I_{sc} increases and thus additional current is drawn from the IDAC. This causes an unexpected behavior of decrease in the raw count.



Figure 189 Equivalent circuit of the CSX sensor when Cbody<<Cfs

For CSX sensors, design should focus on increasing the ratio of C_{bodyDG}/C_{fs} . Following are the examples for increasing the ratio of C_{bodyDG}/C_{fs} :

C_{bodyDG}/C_{fs} ratio depends on the thickness of the overlay, size of the sensor, and many other factors. By experimental data, you are recommended not to use overlay thickness below 0.5 mm for CSX sensor. See Overlay thickness



- 2. If the sensor is surrounded by hatch fill connected to ground, there is a lower chance that C_{bodyDG}<<C_{fs}. Therefore, ensure good ground in the design. Follow the best practices for the PCB layout guidelines described in this chapter
- **3.** In the design, it is recommended to isolate the trace lines of Rx and Tx electrode, external capacitors, and resistors of the CSX touch sensing system from any conducting surface or a finger touch to avoid direct interaction. Not following this recommendation may cause $C_{bodyDG} << C_{fs}$

7.6.2 CSD method

The equivalent capacitances formed in the CSD method when a finger touches the CSD sensor is shown in Figure 190. It shows that the current drawn from the IDAC directly depends on the capacitance introduced by the finger touch. I_{CP} is a fixed component and I_{CF} depends on C_F , C_{BG} , C_{GE} . From Sigma-delta converter, the raw count depends on the amount of current drawn from IDAC. To understand it better, consider two scenarios of an AC/ DC mains-powered application and a battery-powered application.



Figure 190 Equivalent circuit of the CSD sensor

 $I = I_{CP} + I_{CF}$

Equation 82 Current drawn from IDAC in CSD method

7.6.2.1 AC/DC-powered application

In an AC / DC-powered application using the mains supply, device ground is strongly coupled to earth ground. Thus, you can replace C_{GE} with a conductor and C_{BG} is usually 100 pF to 200 pF. Since C_{BG} is large when compared to C_F , you can neglect its effect. Finally, the resulting equivalent circuit is shown in Figure 191. The increase in total capacitance draws a higher current from the IDAC achieving a higher change in raw count for a finger touch. Thus, in this condition, you get a higher sensitivity, which means that you will get a higher signal for a finger touch.





Figure 191 Equivalent circuit of the CSD sensor for mains-powered application

7.6.2.2 Battery-powered application

In battery-powered portable applications, device ground and earth ground are lightly coupled, thus C_{GE} is small. The resulting equivalent circuit is shown in Figure 192. Thus, in this condition, you get a lower sensitivity; that means you will get a lower signal for a finger touch, which is due to a decrease in capacitance seen at the device.



Figure 192 Equivalent circuit of the CSD for battery-powered application

Following are the recommendations for a CSD system design in a portable application powered by a battery:



- 1. Add a large ground plane to the system. The ground plane should be away from the sensing element such that it does not increase the parasitic capacitance of the sensor. Follow the best practices for the PCB layout guidelines described in this chapter
- 2. Use a driven shield to improve the sensitivity of portable devices. Refer to the Layout guidelines for shield electrode for more details
- **3.** Reduce the thickness of the overlay material or use an overlay with better dielectric value to improve sensitivity
- **4.** Tune the CAPSENSE[™] system with powering it by a battery source



8 CAPSENSE[™] Plus

PSOC[™] 4 can perform many additional functions along with CAPSENSE[™]. The wide variety of features offered by this device allows you to integrate various system functions in a single chip, as Figure 193 shows. Such applications are known as CAPSENSE[™] Plus applications.



Figure 193 CAPSENSE[™] Plus

The additional features available in a PSOC[™] 4 device include:

- Communication: Bluetooth[®] LE, I²C, UART, SPI, CAN, and LIN
- Analog functions: ADC, comparators, and opamps
- Digital functions: PWMs, counters, timers, and UDBs
- Segment LCD drive
- Bootloaders
- Different power modes: Active, sleep, deep sleep, hibernate, and stop

While using above mentioned additional features, it is recommended to configure it in sinking mode as applicable.

For more information on PSOC[™] 4, see AN79953 - Getting started with PSOC[™] 4, or AN91267 - Getting started with PSOC[™] 4 Bluetooth[®] LE.

The flexibility of the PSOC[™] 4 and the unique PSOC[™] Creator IDE allow you to quickly make changes to your design, which accelerates time-to-market. Integrating other system functions significantly reduces overall system cost. Table 49 shows a list of example applications, where using CAPSENSE[™] Plus can result in significant cost savings.



Application	CAPSENSE™	Opamp	ADC	Comp	PWM, Counter, Timer, UDBs	Comm(Bl uetooth [°] LE, I2C, SPI, UART)	LCD drive	GPIOs
Heart rate monitor (wrist band)	User interface: buttons, linear sliders	TIA, Buffer	Heart Rate Measurement , Battery voltage measuremen t		LED Driving	Bluetooth [°] LE	Segment LCD	LED indicatio n
LED bulb	User interface: buttons, radial sliders	Amplifier	LED current measuremen t	Short circuit protectio n	LED color control (PrISM*)	Bluetooth [°] LE		LED indicatio n
Washing machine	User interface: buttons, radial sliders		Temperature sensor	Water level monitor	Buzzer, FOC** motor control	I ² C LCD display, UART network interface	Segment LCD	LED indicatio n
Water heater	User interface: buttons, linear sliders		Temperature sensor, water flux sensor	Water level monitor	Buzzer	I ² C LCD display, UART Network Interface	Segment LCD	LED indicatio n
IR remote controllers	User interface: buttons, linear and radial sliders, touchpads				Manchest er encoder			LED indicatio n
Induction cookers	User interface: buttons, linear sliders		Temperature sensor				Segment LCD	LED indicatio n
Motor control systems (table contil	User interface: buttons, linear sliders				BLDC*** and FOC motor control			LED indicatio n

(table continues...)



Table 49 (continued) Examples of CAPSENSE[™] Plus

Application	CAPSENSE™	Opamp	ADC	Comp	PWM, Counter, Timer, UDBs	Comm(Bl uetooth [°] LE, I2C, SPI, UART)	LCD drive	GPIOs
Gaming/ simulation controllers	User interface: buttons, touchpads		Reading analog joysticks			I ² C/SPI/ UART communi cation interface	Segment LCD	LED indicatio n
Thermal printers	User interface: buttons		Overheat protection, paper sensor		Stepper motor control	SPI communi cation interface		LED indicatio n

* PrISM = Precision illumination signal modulation

** FOC = Field oriented control

*** BLDC = Brushless DC motor

Figure 194 shows a general block diagram of a CAPSENSE[™] Plus application, such as an induction cooker or a microwave oven.



Figure 194CAPSENSE™ Plus system with PSOC™ 4

In this application, the 12-bit 1 Msps SAR ADC in the PSOC[™] 4 detects over-current, overvoltage, and high temperature conditions. The PWM output drives the speaker for status and alarm tones. Another PWM controls the heating element in the system. The CAPSENSE[™] buttons and slider constitute the user interface. PSOC[™] 4



can also drive a segment LCD for visual outputs. PSOC[™] 4 has a serial communication block that can connect to the main board of the system.

Figure 195 shows the application-level block diagram of a fitness tracker based on PSOC[™] 6 MCU with Bluetooth[®] LE Connectivity. The device provides a one-chip solution and includes features like activity monitoring, environment monitoring, CAPSENSE[™] for user interface, Bluetooth[®] LE connectivity, and so on. For more information on PSOC[™] 6 MCU, see AN210781 – Getting started with PSOC[™] 6 MCU with Bluetooth[®] LE connectivity.





Figure 195

Fitness tracker application with $\mathsf{PSOC}^{\texttt{M}}$ 6 MCU with Bluetooth $^{\degree}$ LE connectivity block diagram



9 Resources

9 Resources

9.1 Website

Visit the Getting started with PSOC[™] 4, Getting started with PSOC[™] 4 Bluetooth[®] LE, Getting started with PSOC[™] 6 MCU, and Getting started with PSOC[™] 6 MCU with Bluetooth[®] LE connectivity website to understand the PSOC[™] 4, PSOC[™] 6 MCU with Bluetooth[®] LE connectivity.

9.2 Device datasheet

- PSOC[™] 4 datasheet
- PSOC[™] 4 Bluetooth[®] LE datasheet
- PSOC[™] 6 MCU devices

9.3 Component datasheet/middleware document

- PSOC[™] 4 Capacitive Sensing
- PSOC[™] 6 capacitive sensing
- CAPSENSE[™] middleware library
- ModusToolbox[™] CAPSENSE[™] configurator guide

9.4 Technical reference manual

The PSOC[™] 4 Technical reference manual (TRM) and PSOC[™] 6 Technical reference manual (TRM) provide quick and easy access to information on PSOC[™] 4 and PSOC[™] 6 architecture including top-level architectural diagrams, register summaries, and timing diagrams.

9.5 Development kits

Table 9 lists Infineon[®] development kits that support PSOC[™] 4 and PSOC[™] 6 CAPSENSE[™].

9.6 PSOC[™] Creator

PSOC[™] Creator is a state-of-the-art, easy-to-use integrated development environment. See the PSOC[™] Creator home page.

9.7 ModusToolbox™

ModusToolbox[™] software suite is used for the development of PSOC[™] 4 and PSOC[™] 6 based CAPSENSE[™] applications. You can download the ModusToolbox[™] software here. The related documents are as follows:

- ModusToolbox[™] release notes
- ModusToolbox[™] install guide
- ModusToolbox[™] user guide
- ModusToolbox[™] quick start guide
- ModusToolbox[™] software training
- ModusToolbox[™] CAPSENSE[™] configurator
- ModusToolbox[™] CAPSENSE[™] tuner



9 Resources

- ModusToolbox[™] device configurator
- ModusToolbox[™] SmartIO configurator
- PSOC[™] Creator to ModusToolbox[™]
- ModusToolbox[™] command line

9.8 Application notes and design guides

[®] A large collection of application notes are available to get your design up and running fast. See PSOC[™] 4 application notes, PSOC[™] 4 Bluetooth[®] LE application notes, CAPSENSE[™] application notes and design guides. Following is the list of CAPSENSE[™] specific applications notes:

Design guide for PSOC[™] 3 and PSOC[™] 5LP devices

• PSOC[™] 3 and PSOC[™] 5LP CAPSENSE[™] design guide

Design guides for the CAPSENSE[™] Express family

- CY8CMBR3XXX CAPSENSE[™] design guide
- CY8CMBR2110 CAPSENSE[™] design guide
- CY8CMBR2016 CAPSENSE[™] design guide
- CY8CMBR2010 CAPSENSE[™] design guide
- CY8CMBR2044 CAPSENSE[™] design guide
- CAPSENSE[™] Express[™]: CY8C201XX application notes
- Design guides for PSOC[™] 1 devices
- CY8C20XX7/S design guide
- CY8C20XX6A/H CAPSENSE[™] design guide
- CY8C21X34/B CAPSENSE[™] design guide
- CY8C20X34 CAPSENSE[™] design guide

Getting started application note

- AN79953 Getting started with PSOC[™] 4
- AN210781 Getting started with PSOC[™] 6 MCU with Bluetooth[®] LE connectivity
- AN221774 Getting started with PSOC[™] 6 MCU

9.9 Design support

- Knowledge base articles Browse technical articles by product family or perform a search on CAPSENSE™ topics
- White papers Learn about advanced capacitive-touch interface topics
- Infineon developer community Connect with the technical community and exchange information
- Video library Quickly get up to speed with tutorial videos
- Quality and reliability We are committed to complete customer satisfaction. At our Quality website, you can find reliability and product qualification reports
- https://www.infineon.com/cms/en/about-infineon/company/contacts/support/– Submit your design for review by creating a support case. You need to register and login at the website to be able to contact technical support. It is recommended to use PDF prints for the schematic and Gerber files with layer information for the layout

Glossary

AMUXBUS

Analog multiplexer bus available inside PSOC[™] that helps to connect I/O pins with multiple internal analog signals.

Baseline

A value resulting from a firmware algorithm that estimates a trend in the Raw Count when there is no human finger present on the sensor. The Baseline is less sensitive to sudden changes in the Raw Count and provides a reference point for computing the Difference Count.

Button or button widget

A widget with an associated sensor that can report the active or inactive state (that is, only two states) of the sensor. For example, it can detect the touch or no-touch state of a finger on the sensor.

Capacitive sensor

A conductor and substrate, such as a copper button on a printed circuit board (PCB), which reacts to a touch or an approaching object with a change in capacitance.

CAPSENSE™

Infineon[®] Touch-sensing user interface solution. The industry's No. 1 solution in sales by 4x over No. 2.

CAPSENSE[™] Mechanical Button Replacement (MBR)

Configurable solution to upgrade mechanical buttons to capacitive buttons, requires minimal engineering effort to configure the sensor parameters and does not require firmware development. These devices include the CY8CMBR3XXX and CY8CMBR2XXX families.

CAPSENSE[™] signal

signal (CAPSENSE[™] signal)

Difference Count is also called Signal. See Difference Count.

Centroid or Centroid Position

A number indicating the finger position on a slider within the range given by the Slider Resolution. This number is calculated by the CAPSENSE[™] centroid calculation algorithm.

CMOD

Modulation capacitor (CMOD)

An external capacitor required for the operation of a CSD block in Self-Capacitance sensing mode.

Compensation IDAC

A programmable constant current source, which is used by CSD to compensate for excess sensor C_P. This IDAC is not controlled by the Sigma-Delta Modulator in the CSD block unlike the Modulation IDAC.

СР

Parasitic capacitance (CP)

Parasitic capacitance is the intrinsic capacitance of the sensor electrode contributed by PCB trace, sensor pad, vias, and air gap. It is unwanted because it reduces the sensitivity of CSD.

fineon



CSD

CAPSENSE[™] Sigma Delta

CAPSENSE[™] Sigma Delta (CSD) is a patented method of performing self-capacitance (also called self-cap) measurements for capacitive sensing applications.

In CSD mode, the sensing system measures the self-capacitance of an electrode, and a change in the self-capacitance is detected to identify the presence or absence of a finger.

CSH

Shield tank capacitor (CSH)

An optional external capacitor (C_{SH} Tank Capacitor) used to enhance the drive capability of the CSD shield, when there is a large shield layer with high parasitic capacitance.

current-output digital-to-analog converter

IDAC (current-output digital-to-analog converter)

Programmable constant current source available inside PSOC[™], used for CAPSENSE[™] and ADC operations.

Debounce

A parameter that defines the number of consecutive scan samples for which the touch should be present for it to become valid. This parameter helps to reject spurious touch signals.

A finger touch is reported only if the Difference Count is greater than Finger Threshold + Hysteresis for a consecutive Debounce number of scan samples.

Difference count

The difference between Raw Count and Baseline. If the difference is negative, or if it is below Noise Threshold, the Difference Count is always set to zero.

Driven-shield

A technique used by CSD for enabling liquid tolerance in which the Shield Electrode is driven by a signal that is equal to the sensor switching signal in phase and amplitude.

Electrode

A conductive material such as a pad or a layer on PCB, ITO, or FPCB. The electrode is connected to a port pin on a CAPSENSE[™] device and is used as a CAPSENSE[™] sensor or to drive specific signals associated with CAPSENSE[™] functionality.

Finger threshold

A parameter used with Hysteresis to determine the state of the sensor. Sensor state is reported ON if the Difference Count is higher than Finger Threshold + Hysteresis, and it is reported OFF if the Difference Count is below Finger Threshold – Hysteresis.

Ganged sensors

The method of connecting multiple sensors together and scanning them as a single sensor. Used for increasing the sensor area for proximity sensing and to reduce power consumption.

To reduce power when the system is in low-power mode, all the sensors can be ganged together and scanned as a single sensor taking less time instead of scanning all the sensors individually. When you touch any of the sensors, the system can transition into active mode where it scans all the sensors individually to detect which sensor is activated.

PSOC[™] supports sensor-ganging in firmware, that is, multiple sensors can be connected simultaneously to AMUXBUS for scanning.



Gesture

Gesture is an action, such as swiping and pinch-zoom, performed by the user. CAPSENSE[™] has a gesture detection feature that identifies the different gestures based on predefined touch patterns. In the CAPSENSE[™] Component, the Gesture feature is supported only by the Touchpad Widget.

Guard sensor

Copper trace that surrounds all the sensors on the PCB, similar to a button sensor and is used to detect a liquid stream. When the Guard Sensor is triggered, firmware can disable scanning of all other sensors to prevent false touches.

Hatch fill or hatch ground or hatched ground

While designing a PCB for capacitive sensing, a grounded copper plane should be placed surrounding the sensors for good noise immunity. But a solid ground increases the parasitic capacitance of the sensor which is not desired. Therefore, the ground should be filled in a special hatch pattern. A hatch pattern has closely-placed, crisscrossed lines looking like a mesh and the line width and the spacing between two lines determine the fill percentage. In case of liquid tolerance, this hatch fill referred as a shield electrode is driven with a shield signal instead of ground.

Hysteresis

A parameter used to prevent the sensor status output from random toggling due to system noise, used in conjunction with the Finger Threshold to determine the sensor state.

Linear slider

A widget consisting of more than one sensor arranged in a specific linear fashion to detect the physical position (in single axis) of a finger.

Liquid tolerance

The ability of a capacitive sensing system to work reliably in the presence of liquid droplets, streaming liquids or mist.

Low baseline reset

A parameter that represents the maximum number of scan samples where the Raw Count is abnormally below the Negative Noise Threshold. If the Low Baseline Reset value is exceeded, the Baseline is reset to the current Raw Count.

Manual-tuning

The manual process of setting (or tuning) the CAPSENSE[™] parameters.

Matrix buttons

A widget consisting of more than two sensors arranged in a matrix fashion, used to detect the presence or absence of a human finger (a touch) on the intersections of vertically and horizontally arranged sensors.

If M is the number of sensors on the horizontal axis and N is the number of sensors on the vertical axis, the Matrix Buttons Widget can monitor a total of M x N intersections using ONLY M + N port pins.

When using the CSD sensing method (self-capacitance), this Widget can detect a valid touch on only one intersection position at a time.

Modulation IDAC

Modulation IDAC is a programmable constant current source, whose output is controlled (ON/OFF) by the sigma-delta modulator output in a CSD block to maintain the AMUXBUS voltage at V_{REF} . The average current supplied by this IDAC is equal to the average current drawn out by the sensor capacitor.



Modulator clock

A clock source that is used to sample the modulator output from a CSD block during a sensor scan. This clock is also fed to the Raw Count counter. The scan time (excluding pre and post processing times) is given by $(2^N - 1)/M$ Modulator Clock Frequency, where N is the Scan Resolution.

MSC

Multi sense converter (MSC)

The multi sense converter is the analog to digital converter used in Fifth-Generation CAPSENSE[™] technology also known as Ratiometric sensing technology.

Mutual-capacitance

Capacitance associated with an electrode (say Tx) with respect to another electrode (say Rx) is known as mutual-capacitance.

Negative noise threshold

A threshold used to differentiate usual noise from the spurious signals appearing in negative direction. This parameter is used in conjunction with the Low Baseline Reset parameter.

Baseline is updated to track the change in the Raw Count as long as the Raw Count stays within Negative Noise Threshold, that is, the difference between Baseline and Raw count (Baseline – Raw count) is less than Negative Noise Threshold.

Scenarios that may trigger such spurious signals in a negative direction include: a finger on the sensor on power-up, removal of a metal object placed near the sensor, removing a liquid-tolerant CAPSENSE[™]-enabled product from the water; and other sudden environmental changes.

Noise threshold

A parameter used to differentiate signal from noise for a sensor. If Raw Count – Baseline is greater than Noise Threshold, it indicates a likely valid signal. If the difference is less than Noise Threshold, Raw Count contains nothing but noise.

Noise

CAPSENSE[™] noise (Noise)

The variation in the Raw Count when a sensor is in the OFF state (no touch), measured as peak-to-peak counts.

Overlay

A non-conductive material, such as plastic and glass, which covers the capacitive sensors and acts as a touchsurface. The PCB with the sensors is directly placed under the overlay or is connected through springs. The casing for a product often becomes the overlay.

Proximity sensor

A sensor that can detect the presence of nearby objects without any physical contact.

Radial slider

A widget consisting of more than one sensor arranged in a specific circular fashion to detect the physical position of a finger.

Raw count

The unprocessed digital count output of the CAPSENSE[™] hardware block that represents the physical capacitance of the sensor.

Refresh interval

The time between two consecutive scans of a sensor.

Scan resolution

Resolution (in bits) of the Raw Count produced by the CSD block.

Scan time

Time taken for completing the scan of a sensor.

Self-capacitance

The capacitance associated with an electrode with respect to circuit ground.

Sense clock

A clock source used to implement a switched-capacitor front-end for the CSD sensing method.

Sensitivity

The change in Raw Count corresponding to the change in sensor capacitance, expressed in counts/pF. Sensitivity of a sensor is dependent on the board layout, overlay properties, sensing method, and tuning parameters.

Sensor

See Capacitive sensor.

Sensor auto reset

A setting to prevent a sensor from reporting false touch status indefinitely due to system failure, or when a metal object is continuously present near the sensor.

When Sensor Auto Reset is enabled, the Baseline is always updated even if the Difference Count is greater than the Noise Threshold. This prevents the sensor from reporting the ON status for an indefinite period of time. When Sensor Auto Reset is disabled, the Baseline is updated only when the Difference Count is less than the Noise Threshold.

Sensor ganging

See Ganged sensors.

Shield electrode

Copper fill around sensors to prevent false touches due to the presence of water or other liquids. Shield Electrode is driven by the shield signal output from the CSD block. See Driven-shield.

Slider resolution

A parameter indicating the total number of finger positions to be resolved on a slider.

SmartSense[™] auto-tuning

A CAPSENSE[™] algorithm that automatically sets sensing parameters for optimal performance after the design phase and continuously compensates for system, manufacturing, and environmental changes.

SNR

Signal-to-noise ratio

The ratio of the sensor signal, when touched, to the noise signal of an untouched sensor.

Touchpad

A Widget consisting of multiple sensors arranged in a specific horizontal and vertical fashion to detect the X and Y position of a touch.

Trackpad

See Touchpad.

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Tuning

The process of finding the optimum values for various hardware and software or threshold parameters required for CAPSENSE[™] operation.

VREF

Programmable reference voltage block available inside PSOC[™] used for CAPSENSE[™] and ADC operation.

Widget

A user-interface element in the CAPSENSE[™] Component that consists of one sensor or a group of similar sensors. Button, proximity sensor, linear slider, radial slider, matrix buttons, and touchpad are the supported widgets.



Document version	Date of release	Description of changes			
2013-04-19	**	New Design Guide.			
2013-07-29	*A	Added dual IDAC support. Updated some schematics in chapter 6. Other minor changes to chapters 3, 5, and 6.			
2013-11-13	*В	Added support of CY8C4000 devices. Minor fixes throughout the document.			
2014-02-24	*C	Updated the table of device features. Changed IDAC names to sync with new PSOC [™] Creator Component terms. Added a schematic checklist. Changed screenshots to match the new Component version.			
2014-02-27	*D	Updated Table 1-1 per PSOC [™] 4000 datasheet.			
2014-03-20	*E	Added firmware design considerations to Chapter 6.			
		Added power supply layout and schematic considerations to Chapter 6. Updated the IMO range for PSOC [™] 4000			
2014-04-15	*F	Updated to support PSOC [™] 4000 and PSOC [™] Creator 3.0 SP1.			
2014-08-29	*G	Added Reference to Getting started with CAPSENSE [™] in Proximity (three- dimensional)			
		Renamed Chapter 2.5 to Liquid tolerance and re-wrote this section.			
		Updated the recommendations for Shield drive that is Csh_tank precharge and C _{MOD} precharge in Chapter 3.2.7 CAPSENSE [™] CSD shielding.			
		Added recommendation for setting "API resolution" in Chapter			
		Added guidelines on how to select value of "Sensitivity" parameter in Chapter			
		Updated recommended values of threshold and hysteresis parameters in Chapter Manual tuning trade-offs			
		Added Section Manual Tuning Slider Example.			
		Updated maximum overlay thickness value for sliders in Table 32.			
		Added guideline on maximum thickness for overlays of materials other than acrylic in Chapter 7.3.2 Overlay thickness.			
		Re-wrote Chapter Slider design.			
		Added recommendations on DC loads in Chapter 7.4.5			
		Renamed and rewrote Chapter 7.4.12 to Layout guidelines for liquid tolerance			
		Added Chapter 7.4.13.1 External capacitors pin selection.			
		Updated slider related recommendations in Layout rule Updated Electromagnetic compatibility (EMC) considerations , added extensive data on hardware and firmware considerations.			
2014-12-19	*H	Added information for the PSOC [™] 4 Bluetooth [®] LE family of devices.			
		Added information for the PRoC Bluetooth [®] LE family of devices. Updated ground and power layout guidelines in Chapter 7.4.10 and Chapter 7.4.11.			
2015-01-21	*	Added information for PSOC [™] 4200-M family of devices. Added footnote in chapter Slider.			
		Added GPIO source/sink current limit in Table 39.			
		Changed document title to PSOC [™] 4 CAPSENSE [™] Design Guide – AN85951			



Document version	Date of release	Description of changes
2015-06-02	*J	 Changed Document Title to "AN85951 – PSOC™ 4 CAPSENSE™ Design Guide". Updated Design considerations Updated Preventing ESD discharge. Updated Figure 166. Updated Redirect. Replaced "Guard Ring" with "Ground Ring".
2015-08-20	*K	Added Table 3-1. Removed chapter 3.2.1 C _{MOD} Precharge. Added chapter CAPSENSE™ in PSOC™ 4xxxM/4xxxL-Series. Updated chapter Trace routing. Added reference of AN2397. Added recommendation for modulator clock divider in chapter Manual tuning trade-offs. Added Figure 163
2015-09-16	*L	Updated Chapter 1.1. Updated 12 Figure 1. Updated Table 9, Table 37, Table 38, Table 40.
2016-01-19	*M	Updated Introduction. Moved Signal-to-noise ratio (SNR) to Chapter 2. Updated Chapters PSOC [™] 4 and PSOC [™] 6 MCU and for CAPSENSE [™] performance details. Added section to Chapter 4. Added Glossary.
2016-02-23	*N	 Added information on mutual-capacitance sensing in PSOC[™] 4 device series. Added information on CAPSENSE[™] 3.0 changes. Added following sections: Mutual-capacitance sensing CAPSENSE[™] Architecture in PSOC[™] 4 S-series Updated following sections: Introduction CAPSENSE[™] CAPSENSE[™] design and development tools CAPSENSE[™] performance tuning
2016-03-04	*0	Added PSOC [™] Analog Coprocessor references. Updated External capacitors pin selection. Updated Development kits chapter. Updated document title. Updated Copyright notice.
2016-06-14	*P	Updated IDAC sinking mode recommendation. Updated template.
2016-11-18	*Q	Updated Recommended pins for external capacitors.
2017-04-19	*R	Updated logo and copyright.



Document version	Date of release	Description of changes
2017-09-22	*S	Added references to PSOC [™] 4100S Plus throughout the document.
		Updated Chapter 1.2 CAPSENSE [™] features with PSOC [™] 4100S Plus features.
		Updated PSOC [™] 4 and PSOC [™] 6 CAPSENSE [™] development kits with CY8CKIT-149 PSOC [™] 4100S Plus prototyping kit.
		Updated Chapter 9.8 Application notes and design guides with specific list of CAPSENSE™ Application Notes
2018-01-18	*T	Changed document title
		Added references to PSOC [™] 6 MCU features throughout the document
		Updated CAPSENSE [™] generations in PSOC [™] 4 and PSOC [™] 6 CAPSENSE [™] generations in PSOC [™] 4 and PSOC [™] 6 with generalized architecture block diagram for CSD sensing.
		Added Gesture in CAPSENSE [™] Gesture in CAPSENSE [™] . Updated Table 9 and Table 41.
2018-02-28	*U	Added references to PSOC [™] 4100PS throughout the document.
2018-11-08	*V	Updated the entire document with references to CY8C62x8 and CY8C62xA devices.
		Updated the entire document with references to ModusToolbox™.
		Updated Table 9 with the information of PSOC [™] 6 kits.
		Updated chapter Mutual-capacitance button design with the information of additional mutual cap key.
		Removed all references to PRoC Bluetooth [®] LE devices.
2019-04-11	*W	Updated SmartSense and Manual tuning with respect to the latest component.
		Removed details on different shield drive mode from CAPSENSE [™] CSD
		Updated CAPSENSE [™] CSX sensing
		 Updated figures in PSOC[™] Creator
		• SmartSense, and Gesture in CAPSENSE [™] with respect to the latest component
		Removed a table in External capacitors pin selection chapter
		Updated Table 3
2020-01-07	*X	Added Liquid tolerance for Mutual Capacitance Sensing section
		Removed Mutual Capacitance Button Design section
		Updated Table 3-2 and Table 3-3
		Updated CAPSENSE [™] CSX Sensing Method
		Added ModusToolBox [™] section in Chapter 4
		Updated SmartSense and Manual Tuning section with respect to the latest component.
		Updated Slider Tuning Guidelines section
		Added Tuning Shield Electrode section
		Updated Gesture chapter with gesture tuning guidelines
		Updated the Low Power design section
		Updated Sensor and Device placement section
		Updated Slider Design section
		Added Effect of Grounding in CSX method and Effect of Grounding in CSD method section



Document version	Date of release	Description of changes
2020-03-18	*Y	Updated Sensor pin selection and chapters.
2020-10-08	*Z	Added CAPSENSE [™] configurator CAPSENSE [™] configurator. Moved Tuning Shield Electrode section under Chapter 5.3.2 CSD sensing
		method (third- and fourth-generation). Added Chapter 5.3.7.12 I am observing a low CM for my CSX button.
		Added Chapter 7.4.3.2 Mutual-capacitance button design.
		Added additional layout guidelines in Chapter 7.4.5 Sensor and device placement.
		Added additional trace routing guidelines in Chapter 7.4.7 Trace routing.
		Added additional guard trace guidelines in Crosstalk Crosstalk .
		Added new Chapter 7.5 Noise in CAPSENSE [™] system.
		Added a single line description on self cap buttons in Self-capacitance button Self-capacitance button .
		Moved ESD and Electromagnetic compatibility (EMC) considerations under Chapter 7.5.3 External noise.
		Moved Effect of grounding on CSX method and effect of grounding on CSD method under Effect of grounding.
2021-10-01	AA	Updated to IFX template.
		Updated CAPSENSE [™] features with new Fifth-Generation CAPSENSE [™] block and PSOC [™] 4100S Max features.
		Update Table 2.
		Added new section CAPSENSE [™] CSD-RM sensing method (fifth-generation) and CAPSENSE [™] CSX-RM sensing method (fifth-generation).
		Added new section for features Autonomous scanning and Usage of multiple channels.
		Removed "5.3.2.4 Button widget example" and replaced with Button widget tuning.
		Added new chapter 5.3.2.6 "Touchpad widget tuning".
		Added new section for Fifth-generation CAPSENSE [™] sensing method - CSD-RM sensing method (fifth-generation and fifth-generation low-power) and CSX-RM sensing method (fifth-generation and fifth-generation low-power).
		Updated Table 32, Table 40, and Table 41. Updated Copyright information.
2022-07-21	AB	Template update
2022-12-20	AC	In the Table 2, in the Feature column, updated "Noise floor (pk-pk)" to "Noise floor (rms)".
2023-08-04	AD	Updated link references
		Deleted CSD Finger Detection Criteria
		Deleted CSX Finger Detection Criteria
		Added Synchronized scanning section
		Added CIC2 section
		Added the section title Advantages of fifth generation and fifth generation low- power



Document version	Date of release	Description of changes
2023-09-27	AE	Updated CIC2 section
		Updated Using SmartSense to determine hardware parameters section
		Updated Table 11
		Updated Table 17
		Updated Sense clock source
2024-02-08	AF	Fixed broken links.
		Removed "5.3.2.6 Touchpad widget tuning".
		Removed "5.3.3.5 Touchpad widget tuning".
		Removed "5.3.5.7 Touchpad widget tuning".
2024-03-20	AG	Information about CIC2 is updated in Chapter 3.
		Updated measuring method for sense clock divider and added information about Cfine and CDAC configuration in Chapter 5.
		Updated LDO recommendation information in Recommendations to reduce the VDDA noise section.
2025-04-04	AH	Information about MPSC-D is added in PSOC [™] 4 and PSOC [™] 6 MCU CAPSENSE [™] .
		Updated overlay recommendation information in Overlay selection.
		Updated recommendation for AMUX Splitter switch noise in Noise in CAPSENSE [™] system.
		Updated MPSC-D (Multi-phase self-cap differential), Advantages, Limitations of MPSC-D, and Implementation of MPSC-D.
		Added Capacitive DACs scaling.
		Updated Table 9 and Table 39.



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Edition 2025-04-04 Published by Infineon Technologies AG 81726 Munich, Germany

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Document reference IFX-jaz1649247577419

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